

TAS6511-Q1 - 50W, 2MHz Digital Input 1-Channel Automotive Heatsink-Free Class-D Audio Amplifier with Current Sense and Real-time Load Diagnostics

1 Features

- AEC-Q100 qualified for automotive applications
 - Temperature grade 1: –40°C to +125°C, T_A
- General operation
 - 4.5V to 19V supply voltage, 40V load dump
 - Support for 1.8V and 3.3V I/O's
 - I²C control with 8 address options
 - <0.5W idle power loss at 14.4V, <5uA max PVDD shutdown loss
- Output current sensing via I²S or TDM
 - No need for external circuitry
- Real-time load diagnostics
 - Monitor output conditions while playing audio
 - Open load, Shorted load, Short-to-power, Short-to-ground detection
- Integrated DSP processing
 - Thermal monitoring and foldback
 - PVDD monitoring and foldback
 - Clip detection
 - Low Latency Path, >70% reduced signal delay at 48kHz
- DC and AC Standby load diagnostics
- Audio inputs
 - I²S and TDM support up to TDM16
 - Input sample rates: 16, 32, 44.1, 48, 96, 192kHz
- Audio outputs
 - 384kHz to 2MHz configurable output switching frequency
 - Up to 7A channel output current
 - 30W (14.4V, 4Ω, 10% THD+N)
 - 50W (14.4V, 2Ω, 10% THD+N)
- Audio Performance
 - THD+N <0.02% (4Ω, 1W, 1kHz)
 - 108dB SNR
 - Output noise: 41μV_{RMS} at 14.4V, A-weighting
- Protection
 - Output short protection
 - Speaker Guard™ Pro power limiter
 - Configurable overtemperature warning and shutdown
 - I²C temperature and supply voltage readout
 - DC offset, undervoltage and overvoltage
- Easily meet CISPR25-L5 EMC specification
 - Advanced spread-spectrum

- [Automotive head unit](#)
- [Telematics control unit](#)
- [Automotive cluster display](#)

3 Description

The TAS6511-Q1 is a mono-channel, digital-input, Class-D audio amplifier that supports 2MHz switching frequency enabling a cost and size-optimized single-channel audio amplifier design. The device operates from 4.5V to 19V and delivers up to 30W (14.4V, 4Ω, 10% THD+N) and up to 50W (14.4V, 2Ω, 10% THD+N). The device integrates DC and AC load diagnostics to determine the status of the connected load before enabling the output stage. Additionally, the device can monitor the output load condition while in PLAY mode with or without audio using real-time load diagnostics which operates independently from the host and audio input.

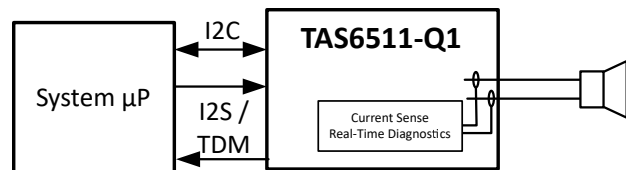
TAS6511-Q1 can monitor the output current, PVDD voltage, and temperature of the device and can report this data through TDM or I²S. The integrated DSP of the TAS6511-Q1 enables advanced protection features such as PVDD foldback, thermal foldback, and Speaker Guard™ Pro power limiter. The DSP also enables an additional low-latency signal path, providing up to 70% faster signal processing at 48kHz for time-sensitive Active Noise Cancellation (ANC) and Road Noise Cancellation (RNC) applications.

The device is available in a small pad-down TSSOP package, enabling a heatsink-free audio amplifier design.

Packaging Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
TAS6511-Q1	HTSSOP (28)	6.4mm × 9.7mm

- (1) For more information, see Mechanical, Packaging, and Orderable Information.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Diagram

2 Applications

- [Acoustic vehicle alerting system \(AVAS\)](#)
- [Emergency call \(eCall\)](#)



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4 Pin Configuration and Functions

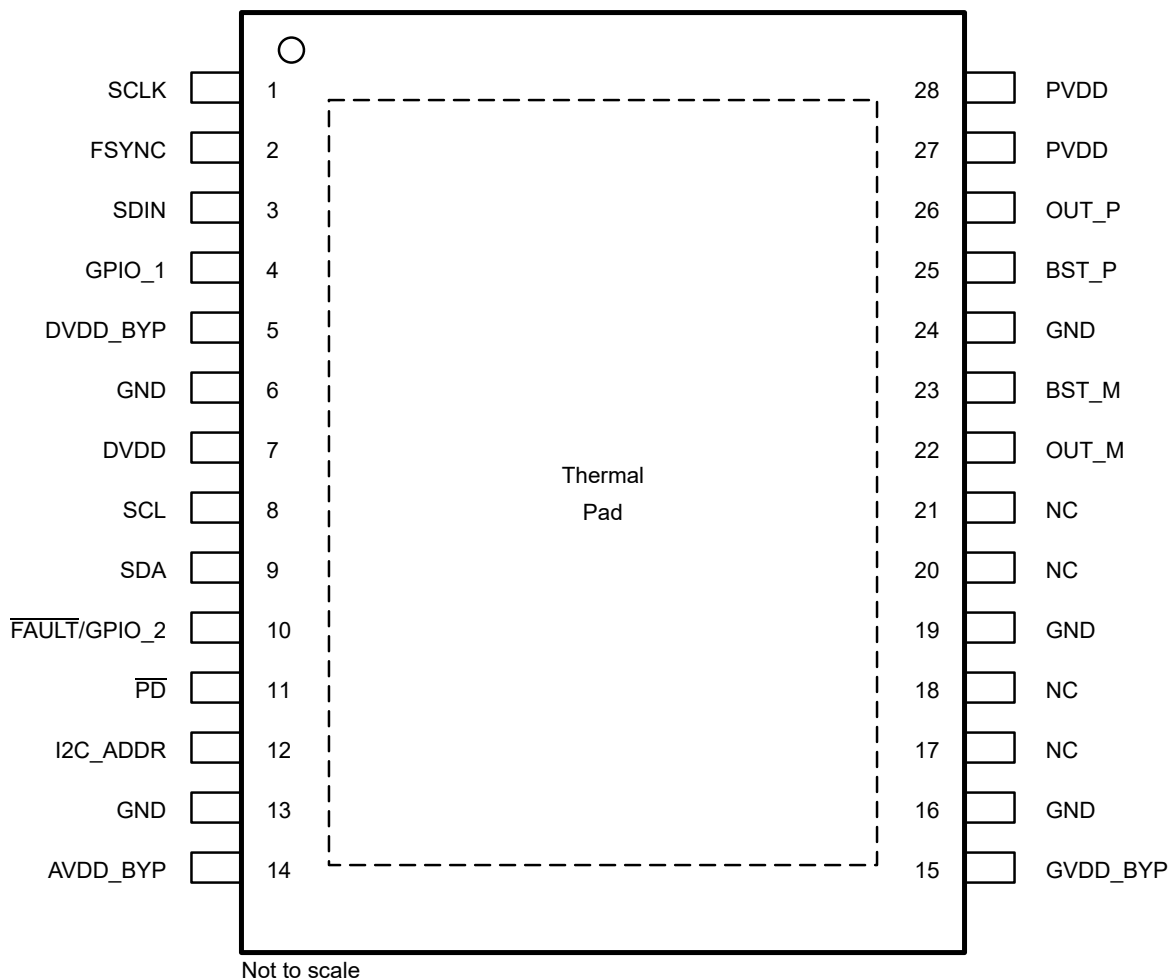


Figure 4-1. PWP (HTSSOP) Package, 28-Pin with exposed Thermal Pad Down, Top View

Table 4-1. Pin Functions- PWP Package

PIN		TYPE ¹	DESCRIPTION
NAME	NO.		
AVDD_BYP	14	PWR	5V Analog supply voltage regulator bypass
BST_M	23	PWR	Bootstrap capacitor connection pins for high-side gate driver
BST_P	25	PWR	Bootstrap capacitor connection pins for high-side gate driver
DVDD	7	PWR	DVDD supply input
DVDD_BYP	5	PWR	1.5V Digital core supply bypass, derived internally from DVDD input
FAULT/ GPIO_2	10	DI/O	Configurable general purpose IO, function set by register programming. Set as $\overline{\text{FAULT}}$ by default. Reports a fault (active low, open drain)
FSYNC	2	DI	Audio frame clock input
GND	6, 13, 16, 19, 24	GND	Ground
GPIO_1	4	DI/O	General purpose IO, function set by register programming
GVDD_BYP	15	PWR	5V Gate drive voltage regulator bypass
I2C_ADDR	12	DI	I ² C address pin
NC	17, 18, 20, 21	NC	No internal connection
OUT_M	22	NO	Negative output for the channel

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Table 4-1. Pin Functions- PWP Package (continued)

PIN		TYPE ¹	DESCRIPTION
NAME	NO.		
OUT_P	26	PO	Positive output for the channel
$\overline{\text{PD}}$	11	DI	Shuts down the device for minimal power draw (active low), 110k Ω internal pull-down resistor
PVDD	27, 28	PWR	PVDD voltage input (can be connected to battery)
SCL	8	DI	I ² C clock input
SCLK	1	DI	Audio input serial clock
SDA	9	DI/O	I ² C data input and output
SDIN	3	DI	TDM or I ² S data input
Thermal Pad	-	GND	Provides electrical and thermal connection for the device. Must be connected to GND.

1. DI = digital input, DO = digital output, DI/O = digital input/output, GND = ground, NC = no connect, NO = negative output, PO = positive output, PWR = power

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
PVDD	DC supply-voltage range relative to GND		-0.3	30	V
V _{MAX}	Transient supply voltage: PVDD	t ≤ 400 ms exposure	-1	40	V
V _{RAMP}	Supply-voltage ramp rate PVDD			40	V/ms
DVDD	DC supply voltage range relative to GND		-0.3	3.9	V
I _{MAX}	Maximum current per pin - PVDD, GND			±5	A
	Maximum current per pin - OUT_P, OUT_M			±7	A
I _{MAX_PULSED}	Pulsed supply current per pin - PVDD, GND	t < 1 ms		±12	A
	Pulsed supply current per pin - OUT_P, OUT_M			±16.5	A
V _{LOGIC}	Input voltage for logic pins - SCL, SDA, FAULT, $\overline{\text{PD}}$, GPIOx		-0.3	DVDD + 0.5	V
V _{GND}	Maximum voltage between GND pins			±0.3	
T _J	Maximum operating junction temperature range		-55	175	°C
T _{stg}	Storage temperature range		-55	150	

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±4000	V
		Charged-device model (CDM), per AEC Q100-011	±1500	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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5.3 Recommended Operating Conditions

			MIN	TYP	MAX	UNIT
PVDD	Output FET Supply Voltage Range	Relative to GND	4.5	14.4	19	V
DVDD	DC Logic supply	Relative to GND	1.62		3.6	V
T _A	Ambient temperature		–40		125	°C
T _J	Junction temperature	An adequate thermal design is required	–40		175	
R _L	Nominal speaker load impedance	BTL Mode	PVDD/ (I _{LIM})	4		Ω
R _{PU_I2C}	I ² C pullup resistance on SDA and SCL pins		1	4.7	10	kΩ
C _{Bypass}	External capacitance on bypass pins	DVDD_BYP		1		μF
C _{A_GVDD}	Combined external capacitance on bypass pins	GVDD_BYP, AVDD_BYP		1.1		μF
L _O	Output filter inductance	Minimum output filter inductance at I _{SD} current levels. Applies to short to ground or short to power protection.	1			μH

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TAS6511-Q1 ⁽²⁾	UNIT
		PWP(HTSSOP)	
		28 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	29.7	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	25.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	9.1	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.6	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	9.1	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	2.4	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report, SPRA953.

(2) JEDEC standard 4 layer PCB.

5.5 Electrical Characteristics

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{ V}$, $DVDD = 1.8\text{ V}$, $R_L = 4\ \Omega$, $P_{out} = 1\text{ W/ch}$, $f_{out} = 1\text{ kHz}$, $F_{SW} = 2.048\text{ MHz}$, BD Modulation, AES17 Filter, reconstruction filter inductor used: $3.3\mu\text{H-VCTA32252T-3R3MS6}$ in 4Ω , $VCMV053T-3R3MN22M$ in 2Ω configuration and $1\mu\text{F}$, default I²C settings, see application diagram

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OPERATING CURRENT						
I _{DVDD}	DVDD supply current	Playing, -60 dB Signal		8	12	mA
I _{PVDD_IDLE}	PVDD idle current	Playing, no audio input, F _{SW} = 2.048 MHz		35	45	
	PVDD idle current	Playing, no audio input, F _{SW} = 384 kHz		26		
I _{PVDD_Shutdown}	PVDD shutdown current	\overline{PD} active, DVDD = 0 V		2	5	μA
I _{DVDD_Shutdown}	DVDD shutdown current	\overline{PD} active, DVDD = 1.8 V		0.5	1	
I _{DVDD_Shutdown}	DVDD shutdown current	\overline{PD} active, DVDD = 3.3 V		1	2	
OUTPUT POWER						
P _O	Output power	4Ω, PVDD=14.4V, THD+N=1%, T _C =75°C	21	23		W
P _O	Output power	4Ω, PVDD=14.4V, THD+N=1%		24		W
P _O	Output power	4Ω, PVDD=14.4V, THD+N=10%, T _C =75°C	26	28		W
P _O	Output power	4Ω, PVDD=14.4V, THD+N=10%		30		W
P _O	Output power	2Ω, PVDD=14.4V, THD+N=1%, T _C =75°C	38	40		W
P _O	Output power	2Ω, PVDD=14.4V, THD+N=10%, T _C =75°C	42	50		W
EFF _p	Power efficiency	25 W output power R _L = 4 Ω, PVDD = 14.4 V, T _C = 25°C; (includes output filter losses)		90		%
PWM OUTPUT STAGE						
R _{DS(on)}	FET drain-to-source resistance	25°C, Not including bond wire and package resistance		35		mΩ
AUDIO PERFORMANCE						
V _n	Output noise voltage	Zero input, A-weighting, Gain = 21V/FS		46		μV
		Zero input, A-weighting, Gain = 15V/FS		41		
		Zero input, A-weighting, Gain = 7.5V/FS		35		
		Zero input, A-weighting, Gain = 3.75V/FS		33		
G	Gain	Peak output voltage at full scale digital input		21		V/FS
THD+N	Total harmonic distortion + noise	R _L = 4 Ω 1W Output Power		0.02		%
		R _L = 4 Ω 1W Output Power 20Hz to 20kHz		0.06		%
G _{VAR}	Device gain variation			0.5		dB
F _{BW}	Frequency response	20Hz to 20kHz, without LC filter impact or integrated compensation		0.5		dB
F _{BW}	Frequency response	20Hz to 40kHz, without LC filter impact or integrated compensation		2		
PSRR	Power-supply rejection ratio	PVDD = 14.4 Vdc + 1 V _{RMS} , f = 1 kHz		80		dB
G _{MUTE}	Output attenuation	Assert MUTE and compare to amp playing 1W audio into 4 Ω		120		dB
LINE OUTPUT PERFORMANCE						
V _{n_Lineout}	Line Out Output noise voltage	Zero input, A-weighting, Gain set to reach full amplitude		46		μV
THD+N _{LINEOUT}	Line output total harmonic distortion + noise	VO = 2 VRMS , channel set to Line output mode		0.018		%
DIGITAL INPUT PINS						
V _{IH}	Input logic level high		70	30		%DVDD
V _{IL}	Input logic level low					
I _{IH}	Input logic current	V _I = DVDD			15	μA
I _{IL}		V _I = 0			-15	
DIGITAL OUTPUT PINS						
V _{OH}	Output voltage for logic level high	I = ±1 mA	90	10		%DVDD
V _{OL}	Output voltage for logic level low					
V _{OH}	Output voltage for logic level high	DVDD = 3.3 V, I = ±2 mA	90	10		%DVDD
V _{OL}	Output voltage for logic level low					
BYPASS VOLTAGES						
V _{DVDD_BYP}	Digital bypass pins voltage			1.5		V

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Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{ V}$, $DVDD = 1.8\text{ V}$, $R_L = 4\ \Omega$, $P_{\text{out}} = 1\text{ W/ch}$, $f_{\text{out}} = 1\text{ kHz}$, $F_{\text{sw}} = 2.048\text{ MHz}$, BD Modulation, AES17 Filter, reconstruction filter inductor used: $3.3\mu\text{H-VCTA32252T-3R3MS6}$ in 4Ω , VCMV053T-3R3MN22M in 2Ω configuration and $1\mu\text{F}$, default $I^2\text{C}$ settings, see application diagram

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OVERVOLTAGE (OV) PROTECTION						
PVDD _{OV_SET}	PVDD overvoltage shutdown set		20.3		22.8	V
PVDD _{OV_HYS}	PVDD overvoltage recovery hysteresis			0.9		V
UNDERVOLTAGE (UV) PROTECTION						
PVDD _{UV_SET}	PVDD undervoltage shutdown set		3.5		4.4	V
PVDD _{UV_HYS}	PVDD undervoltage recovery hysteresis			0.3		V
DVDD _{UV_SET}	DVDD undervoltage shutdown set		1.4		1.59	V
DVDD _{UV_HYS}	DVDD undervoltage recovery hysteresis			0.1		V
POWER-ON RESET (POR)						
V _{POR_SET}	DVDD power on reset set	Increasing DVDD	0.9		1.51	V
V _{POR_HYS}	DVDD power on reset recovery hysteresis			0.25		V
V _{POR_OFF}	DVDD power off threshold	Decreasing DVDD	0.8		1.3	V
OVERTEMPERATURE (OT) PROTECTION and Temperature Sensing						
OTSD	Over-temperature shutdown			170		°C
OT _{HYS}	Over-temperature recovery hysteresis			13		°C
LOAD OVER CURRENT PROTECTION						
I _{LIM}	Overcurrent cycle-by-cycle limit	OC Level 1	3.0	3.6		A
		OC Level 2	3.9	4.4		
		OC Level 3	5.5	6.3		
		OC Level 4	6.5	7.3		
I _{SD}	Overcurrent shutdown	OC Level 1, Any short to supply or ground		7.9	8.5	A
I _{SD}	Overcurrent shutdown	OC Level 2, Any short to supply or ground		8.8	9.5	
I _{SD}	Overcurrent shutdown	OC Level 3, Any short to supply or ground		11.3	12.5	
I _{SD}	Overcurrent shutdown	OC Level 4, Any short to supply or ground		14	15	
CLICK AND POP						
V _{CP}	Output click and pop voltage	ITU-R 2k filter, Hi-Z to PLAY, PLAY to Hi-Z		2.5		mV
DC OFFSET						
V _{OFFSET}	Output offset voltage	T _C = 50°C		4	7	mV
DC DETECT						
DC _{FAULT}	Output DC fault protection		1	1.6	2	V
LOAD DIAGNOSTICS						
S2P	Maximum resistance to detect a short from OUT pin(s) to PVDD		2000			Ω
S2G	Maximum resistance to detect a short from OUT pin(s) to ground		200			
SL	Shorted load detection tolerance			±0.5		
OL	Minimum impedance detected as open load			58		
T _{DC_DIAG}	DC diagnostic time	no faults		155		ms
LO	Line output				20	kΩ
T _{Lineout_DIAG}	Line output diagnostic time			50		ms
AC _{IMP}	AC impedance accuracy	f = 18.75 kHz, R _L = 4 Ω, Impedance at output pins		±0.75		Ω
T _{AC_DIAG}	AC diagnostic time	f = 18.75 kHz		54		ms
f _{AC}	AC diagnostic test frequency	Default		18.75		kHz

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{ V}$, $DVDD = 1.8\text{ V}$, $R_L = 4\ \Omega$, $P_{out} = 1\text{ W/ch}$, $f_{out} = 1\text{ kHz}$, $F_{SW} = 2.048\text{ MHz}$, BD Modulation, AES17 Filter, reconstruction filter inductor used: $3.3\mu\text{H-VCTA32252T-3R3MS6}$ in $4\ \Omega$, $VCMV053T-3R3MN22M$ in $2\ \Omega$ configuration and $1\mu\text{F}$, default $I^2\text{C}$ settings, see application diagram

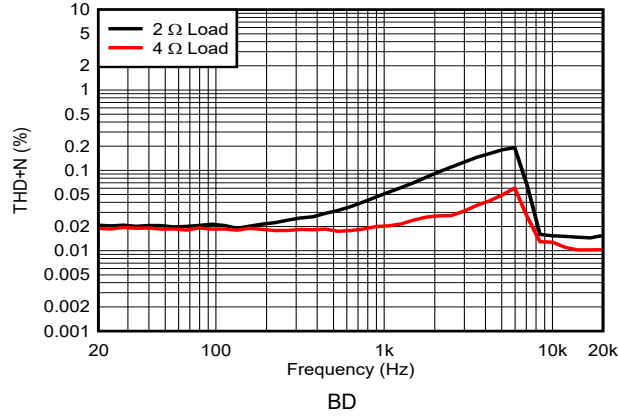
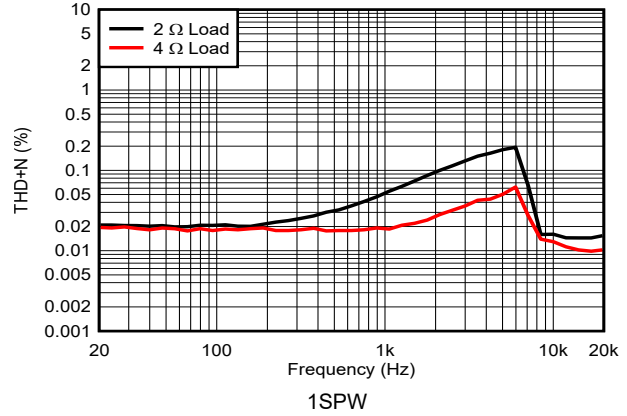
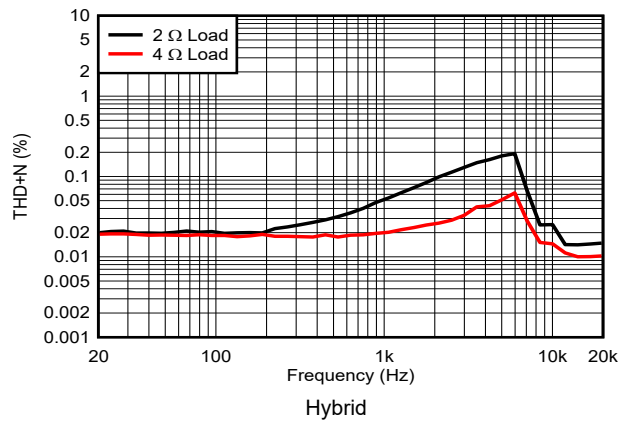
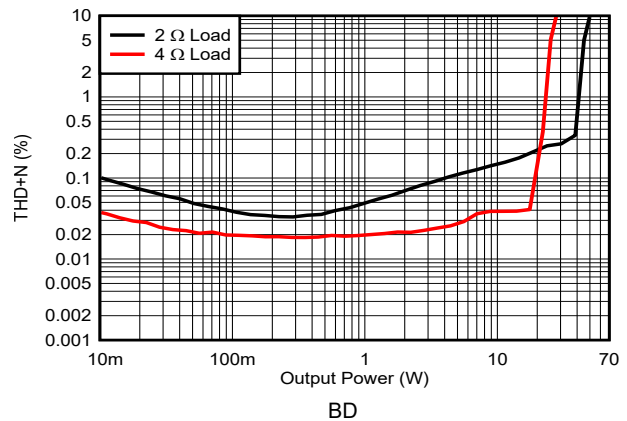
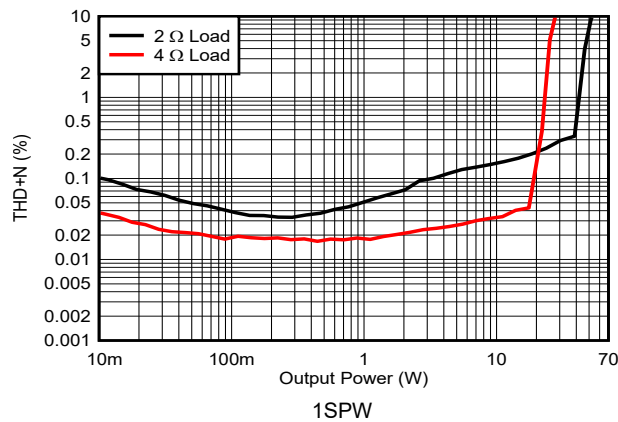
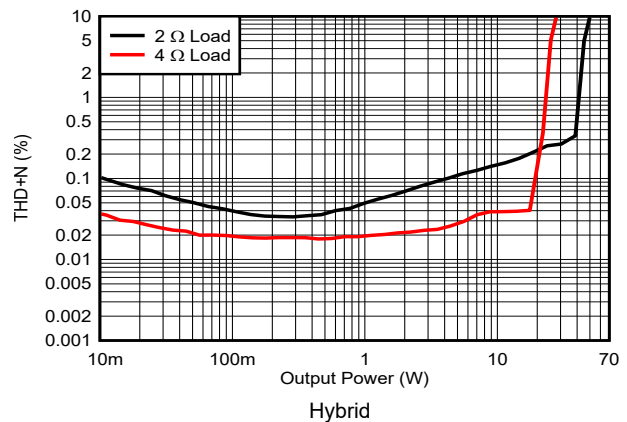
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{SNS_Acc}	Current Sense Accuracy	$f_{out} = 20\text{ Hz to }20\text{ kHz}$		± 10		%
				± 7		
	Current Sense Accuracy	Across Temp, -40°C to 125°C Ambient		± 10		
		$f_{out} = 20\text{ Hz to }20\text{ kHz}$ Across Temp, -40°C to 125°C Ambient		± 10		
I_{SNS_Error}	Current-sense gain error over temperature	-40°C to 125°C , $4\ \Omega$, using a 6 Hz , -36 dB pilot tone		± 10		
THD+N	Total harmonic distortion + noise			2		
SNR	Signal-To-Noise Ratio	Un-Weighted, Relative to 0 dBFS		60		dB
DNR	Dynamic Range	Un-Weighted, Relative to 0 dBFS		63		
I_{SNS_Lat}	Current Sense Latency	Sample time from signal output till the measured current is reported back on TDM		104		μs
Z_{Load_Drift}	$V_{Predict}$ over Current Sense	Max output swing vs Max out minus 60 dB		10		%
I²C ADDRESS PIN						
t_{I2C_ADDR}	Time delay needed for $I^2\text{C}$ address set-up			300		μs
I²C CONTROL PORT						
t_{BUS}	Bus free time between start and stop conditions		1.3			μs
t_{h1}	Hold Time, SCL to SDA		0			ns
t_{h2}	Hold Time, start condition to SCL		0.6			μs
t_{START}	$I^2\text{C}$ Startup Time After DVDD Power On Reset				12	ms
t_{RISE}	Rise Time, SCL and SDA				300	ns
t_{FALL}	Fall Time, SCL and SDA				300	ns
t_{SU1}	Setup, SDA to SCL		100			ns
t_{SU2}	Setup, SCL to Start Condition		0.6			μs
t_{SU3}	Setup, SCL to Stop Condition		0.6			μs
$t_{W(H)}$	Required Pulse Duration SCL "High"		0.6			μs
$t_{W(L)}$	Required Pulse Duration SCL "Low"		1.3			μs
SERIAL AUDIO PORT						
D_{SCLK}	Allowable input clock duty cycle		45%	50%	55%	
f_s	Supported input sample rates		16		192	kHz
f_{SCLK}	Supported SCLK frequencies		32		512	xFS
f_{SCLK_Max}	Maximum frequency				24.576	MHz
t_{SCY}	SCLK pulse cycle time		40			ns
t_{SCL}	SCLK pulse-width LOW		18			ns
t_{SCH}	SCLK pulse-width HIGH		18			ns
t_{SF}	SCLK rising edge to FSYNC edge		8			ns
t_{FS}	FSYNC edge to SCLK rising edge		8			ns
t_{DS}	DATA set-up time		8			ns
C_i	Input capacitance, pins SCLK, FSYNC, SDIN_1, SDOOUT_1, GPIO_x				10	pF
t_{DH}	DATA hold time		8			ns
$T_{AudioLA}$	Audio path latency from input to output	FSYNC = 44.1 kHz or 48 kHz		438		μs
		FSYNC = 96 kHz		219		
		FSYNC = 192 kHz		110		
$T_{LLP}LA$	Low latency path latency from input to output	FSYNC = 44.1 kHz or 48 kHz		104		μs
		FSYNC = 96 kHz		73		

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5.6 Typical Characteristics (2MHz)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 2.048\text{MHz}$, 300k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

**Figure 5-1. THD+N vs Frequency****Figure 5-2. THD+N vs Frequency****Figure 5-3. THD+N vs Frequency****Figure 5-4. THD+N vs Output Power****Figure 5-5. THD+N vs Output Power****Figure 5-6. THD+N vs Output Power**

5.6 Typical Characteristics (2MHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 2.048\text{MHz}$, 300k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

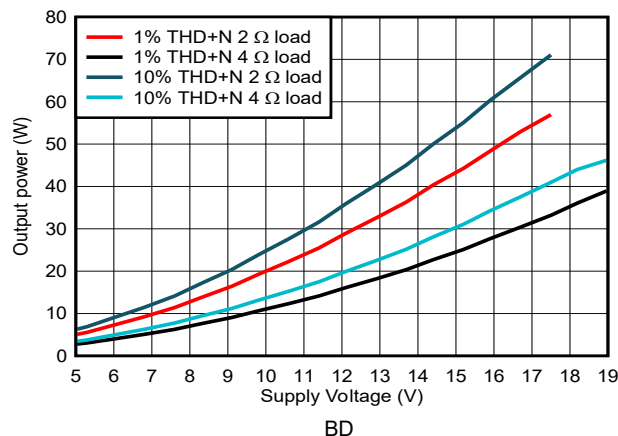


Figure 5-7. Output Power vs Supply Voltage

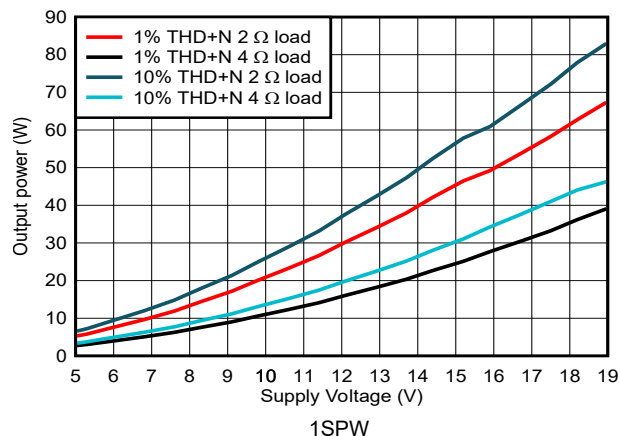


Figure 5-8. Output Power vs Supply Voltage

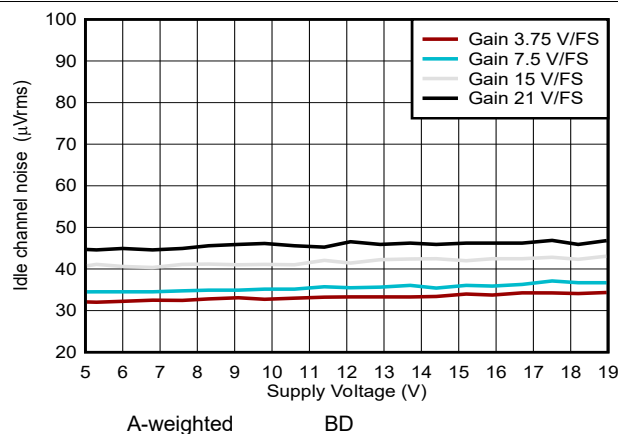


Figure 5-9. Noise vs Supply Voltage

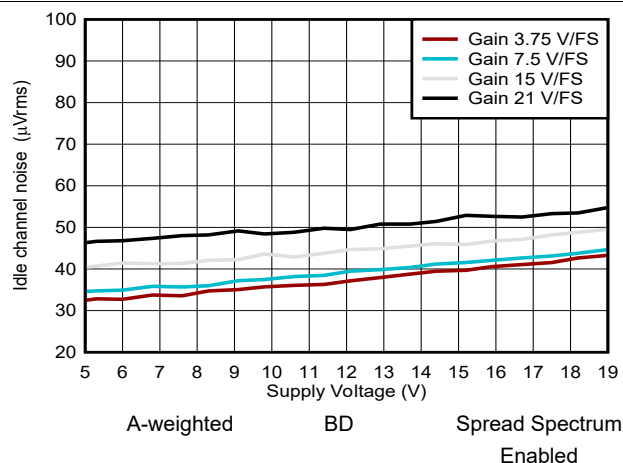


Figure 5-10. Noise vs Supply Voltage

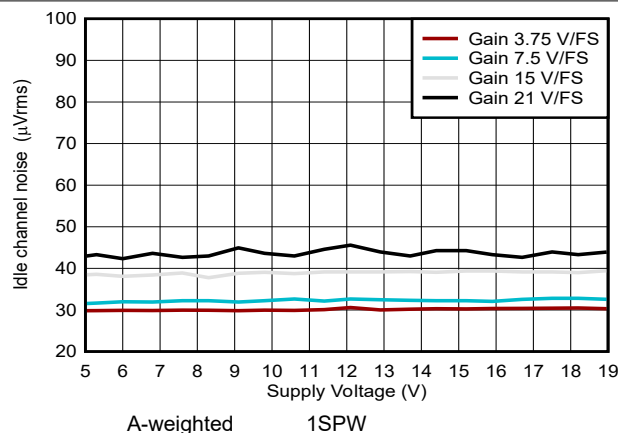


Figure 5-11. Noise vs Supply Voltage

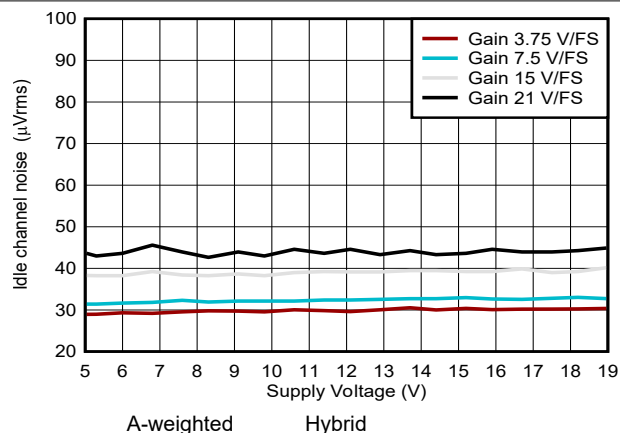


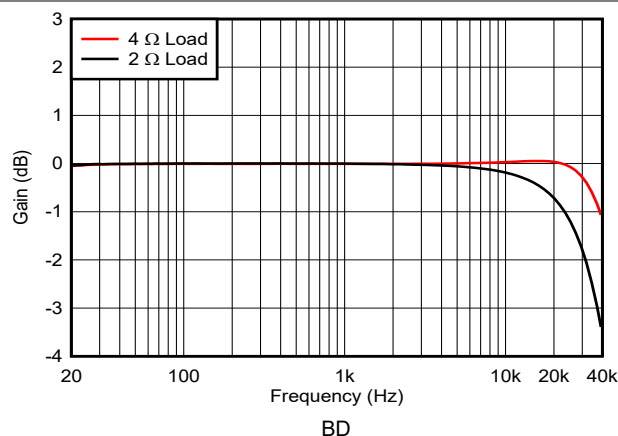
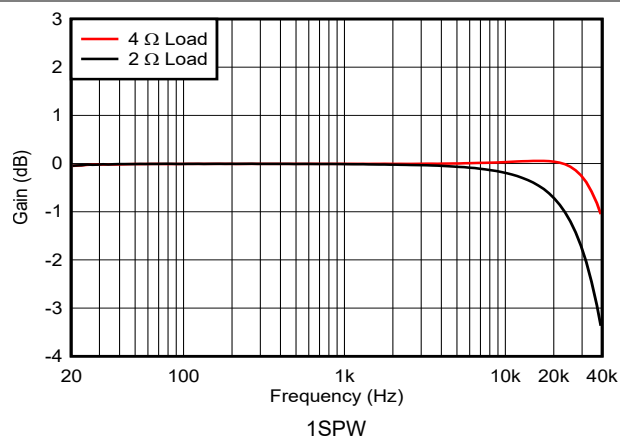
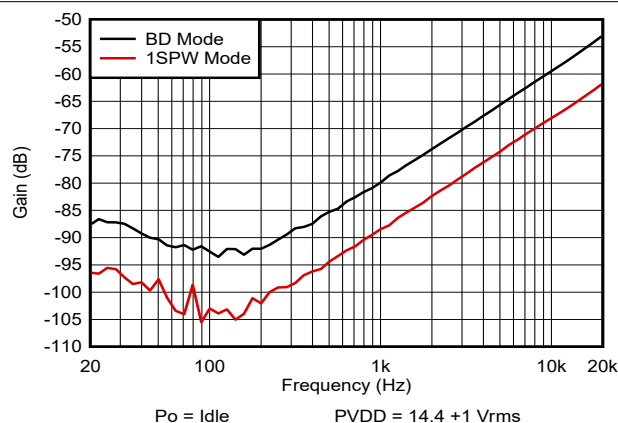
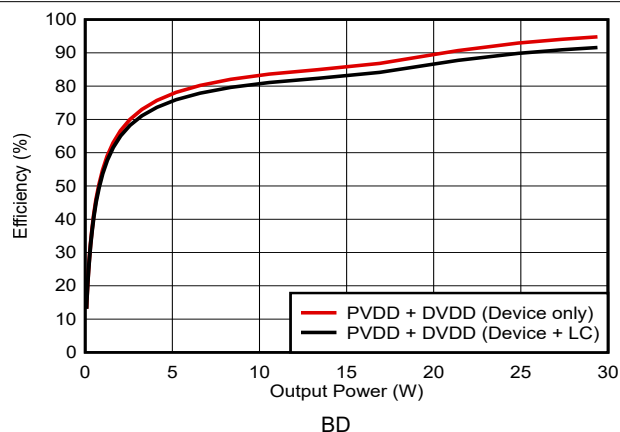
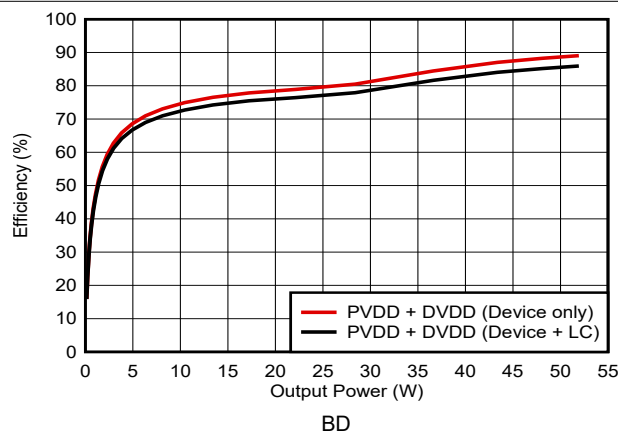
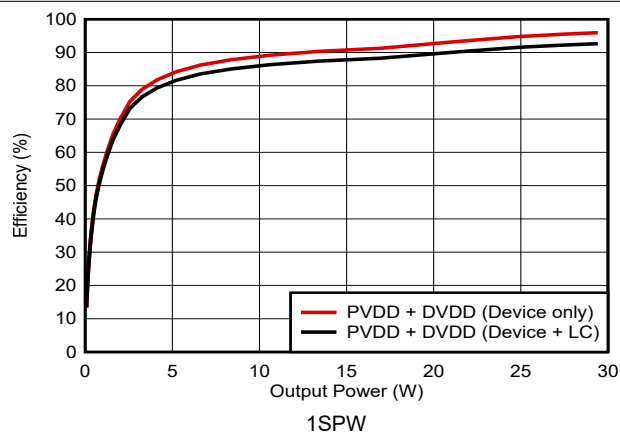
Figure 5-12. Noise vs Supply Voltage

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5.6 Typical Characteristics (2MHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 2.048\text{MHz}$, 300k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

**Figure 5-13. Frequency Response****Figure 5-14. Frequency Response****Figure 5-15. PVDD PSRR vs Frequency****Figure 5-16. Efficiency vs Output Power - 4 Ω** **Figure 5-17. Efficiency vs Output Power - 2 Ω** **Figure 5-18. Efficiency vs Output Power - 4 Ω**

5.6 Typical Characteristics (2MHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 2.048\text{MHz}$, 300k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

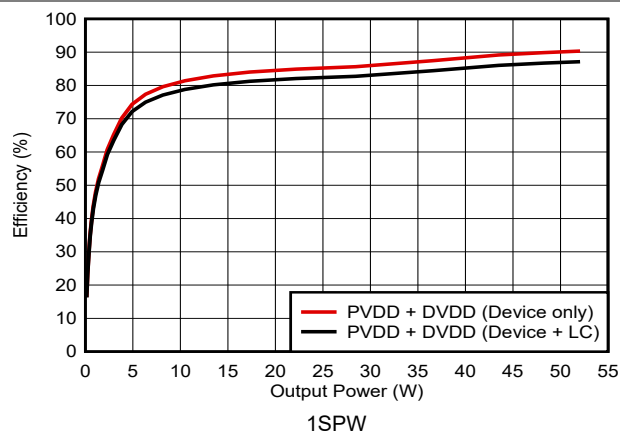


Figure 5-19. Efficiency vs Output Power - 2 Ω

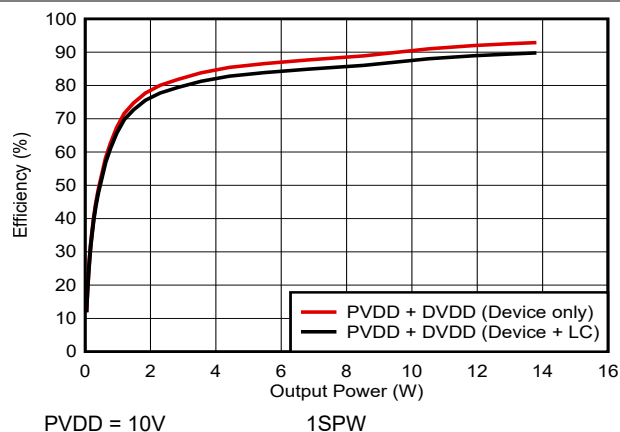


Figure 5-20. Efficiency vs Output Power - 4 Ω , PVDD = 10V

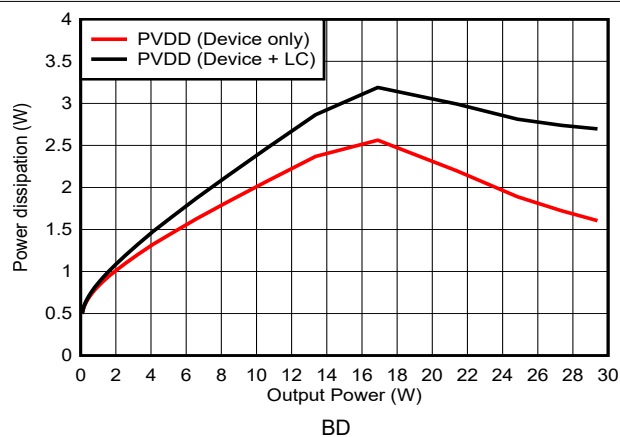


Figure 5-21. Power Dissipation vs Output Power - 4 Ω

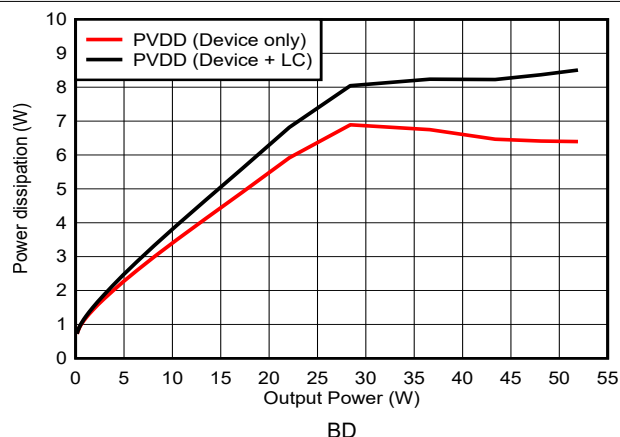


Figure 5-22. Power Dissipation vs Output Power - 2 Ω

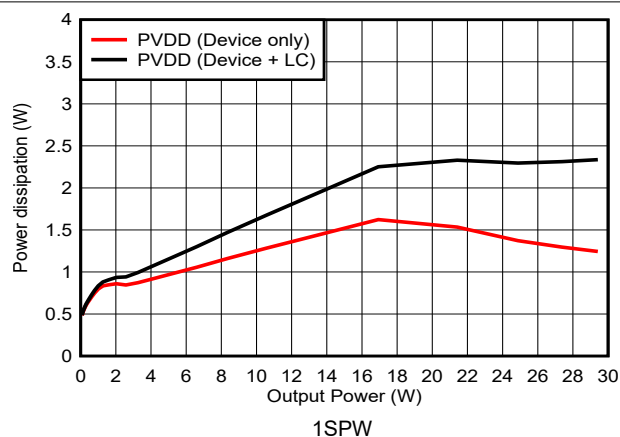


Figure 5-23. Power Dissipation vs Output Power - 4 Ω

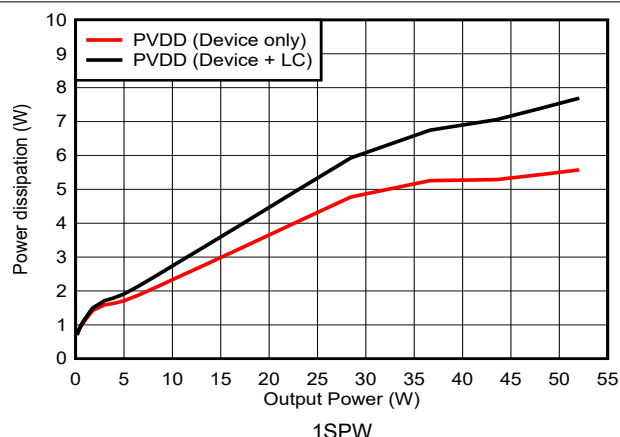


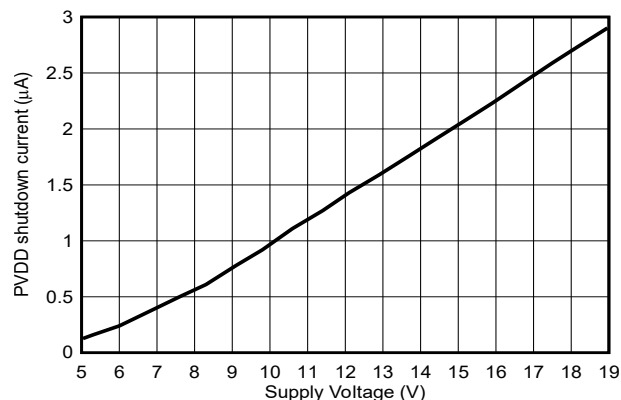
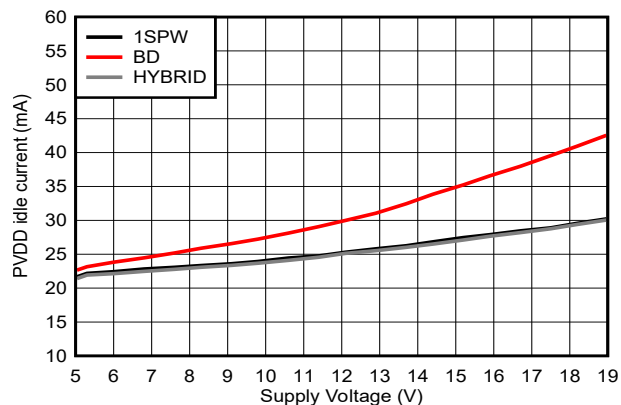
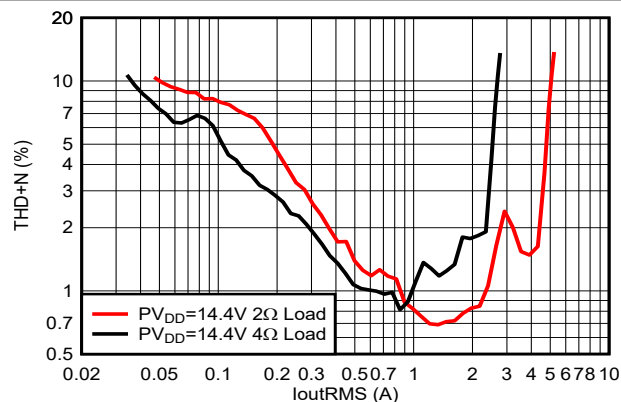
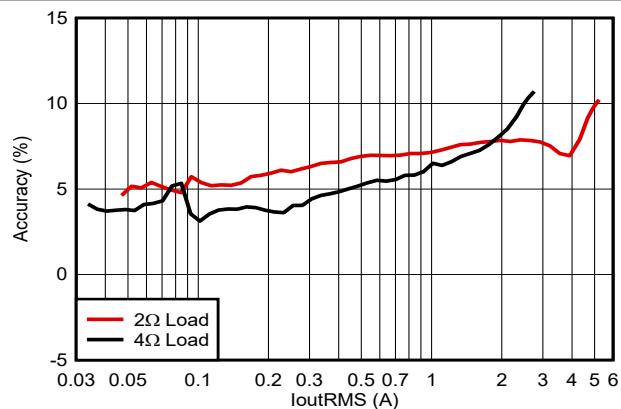
Figure 5-24. Power Dissipation vs Output Power - 2 Ω

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5.6 Typical Characteristics (2MHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 2.048\text{MHz}$, 300k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

**Figure 5-25. Shutdown Current vs Supply Voltage****Figure 5-26. 46 PVDD Idle Current vs Supply Voltage****Figure 5-27. Current Sense THD+N vs Current****Figure 5-28. Current Sense Accuracy vs Current**

5.7 Typical Characteristics (384kHz)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 384\text{kHz}$, 900k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

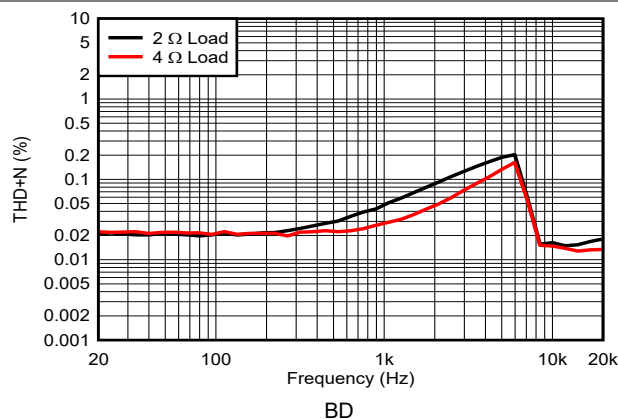


Figure 5-29. THD+N vs Frequency

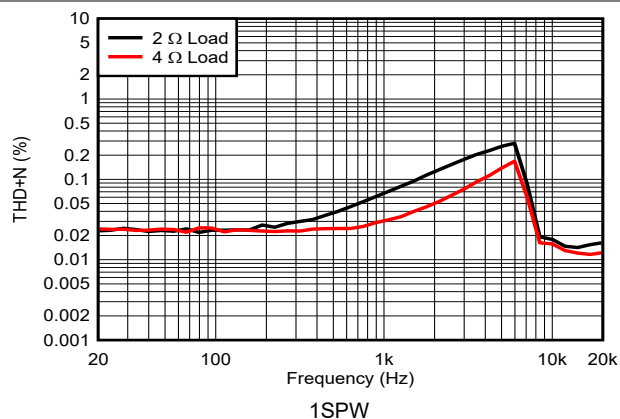


Figure 5-30. THD+N vs Frequency

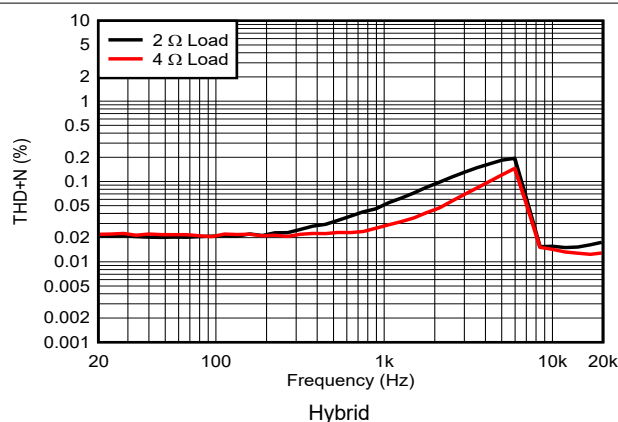


Figure 5-31. THD+N vs Frequency

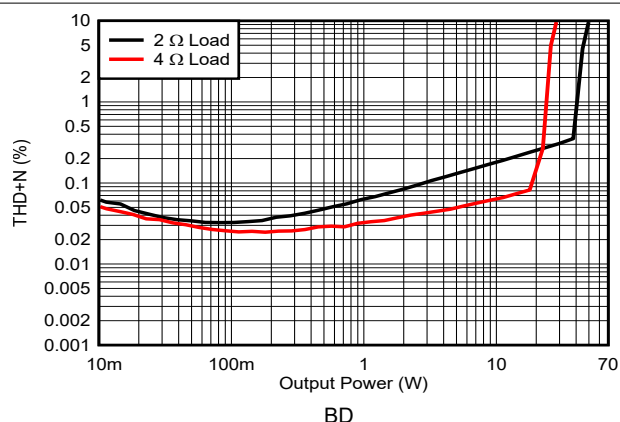


Figure 5-32. THD+N vs Output Power

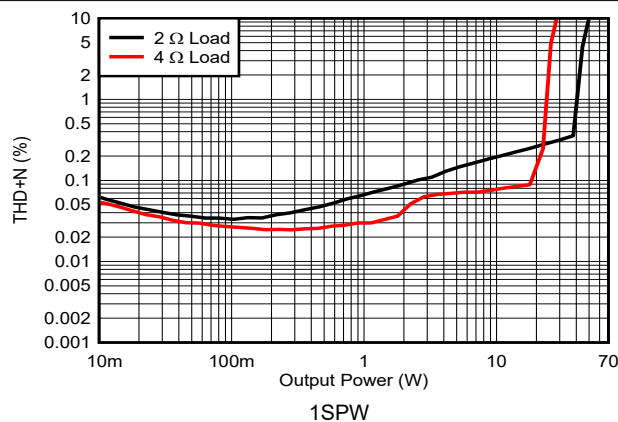


Figure 5-33. THD+N vs Output Power

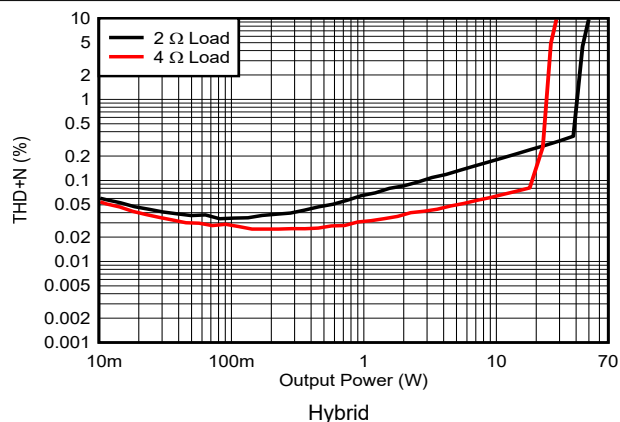


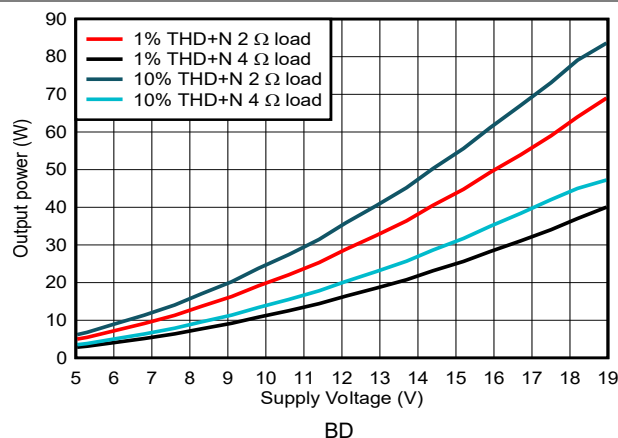
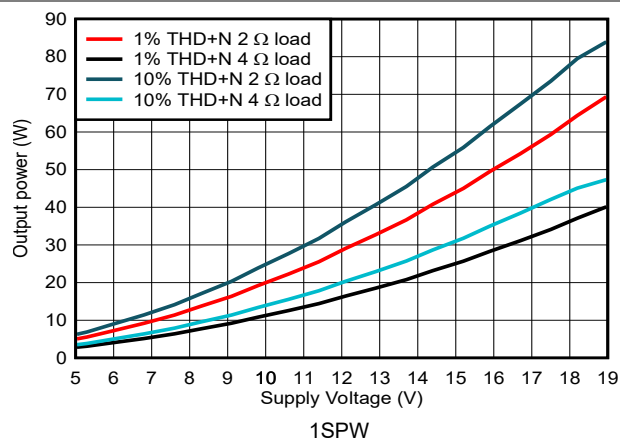
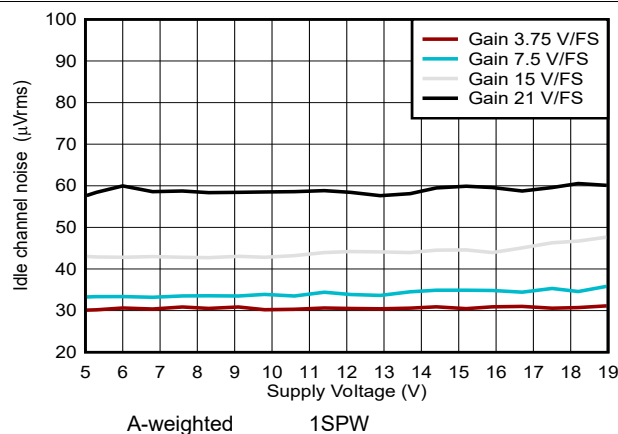
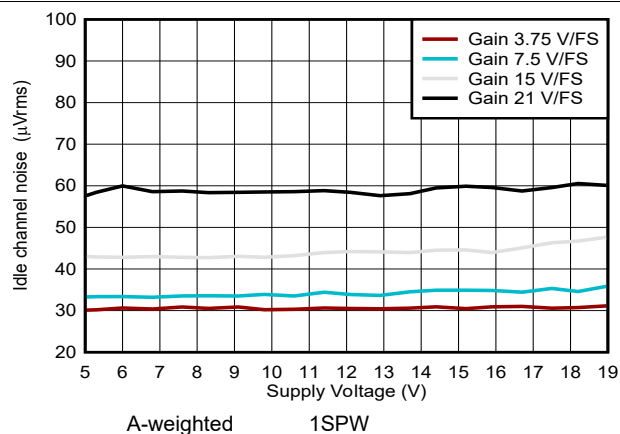
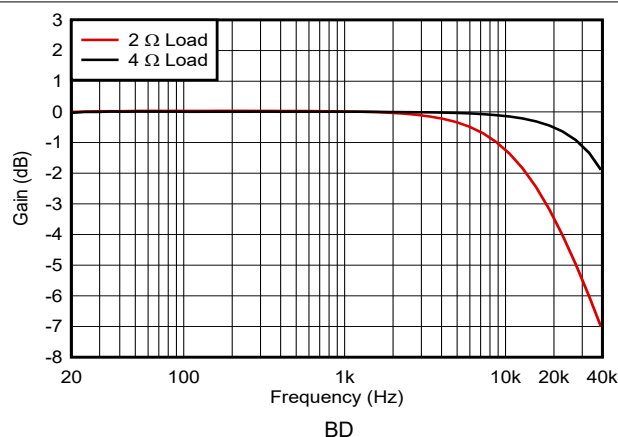
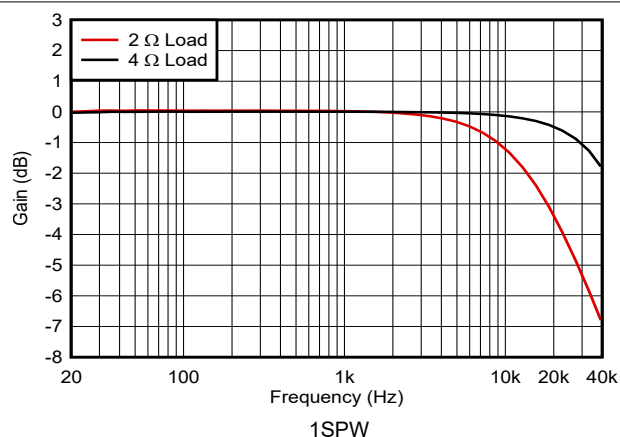
Figure 5-34. THD+N vs Output Power

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5.7 Typical Characteristics (384kHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 384\text{kHz}$, 900k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

**Figure 5-35. Output Power vs Supply Voltage****Figure 5-36. Output Power vs Supply Voltage****Figure 5-37. Noise vs Supply Voltage****Figure 5-38. Noise vs Supply Voltage****Figure 5-39. Frequency Response****Figure 5-40. Frequency Response**

5.7 Typical Characteristics (384kHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 384\text{kHz}$, 900k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

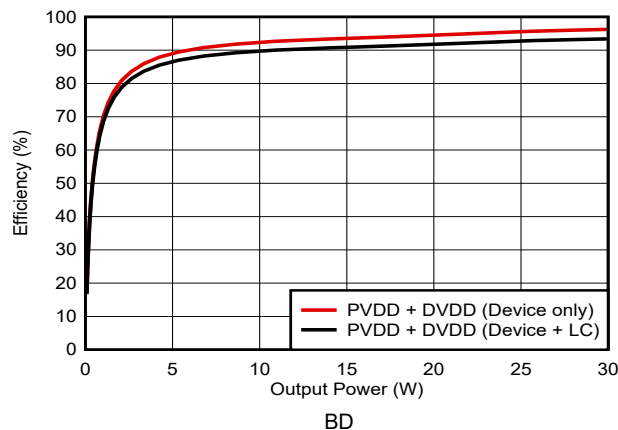


Figure 5-41. Efficiency vs Output Power - 4 Ω

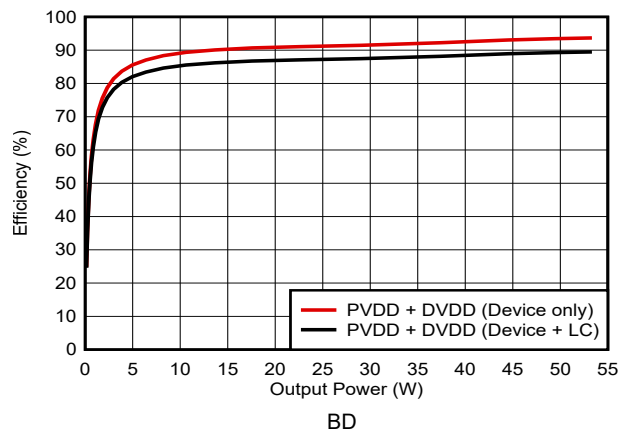


Figure 5-42. Efficiency vs Output Power - 2 Ω

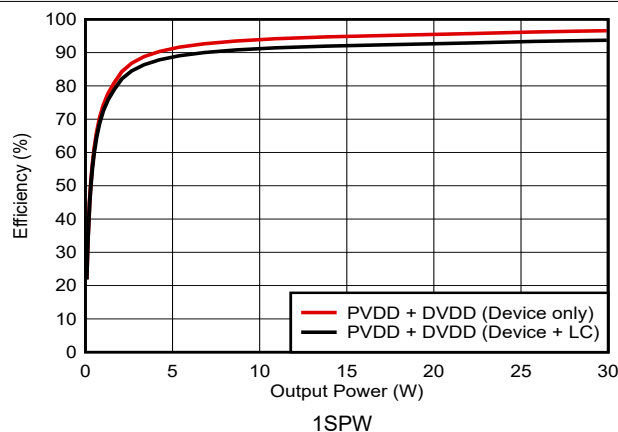


Figure 5-43. Efficiency vs Output Power - 4 Ω

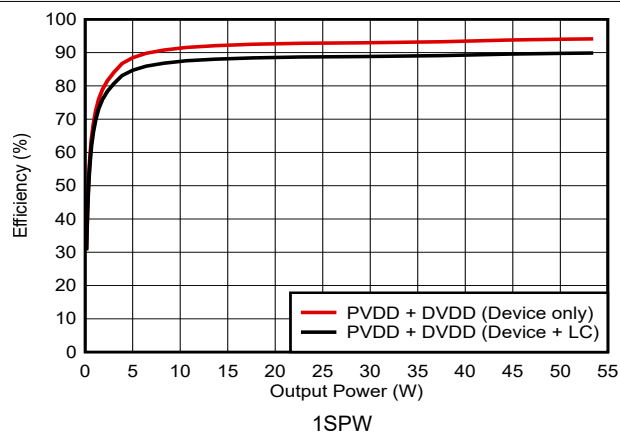


Figure 5-44. Efficiency vs Output Power - 2 Ω

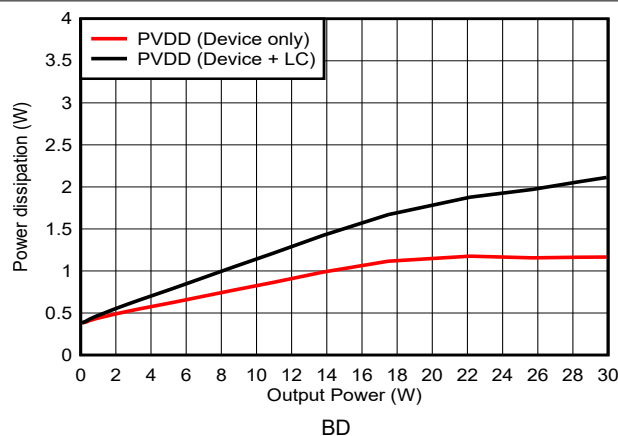


Figure 5-45. Power Dissipation vs Output Power - 4 Ω

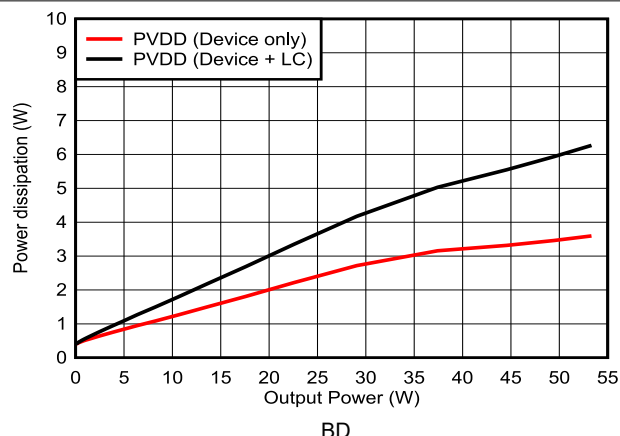


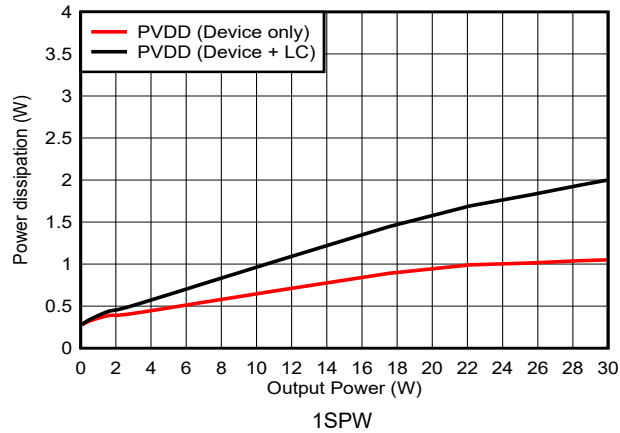
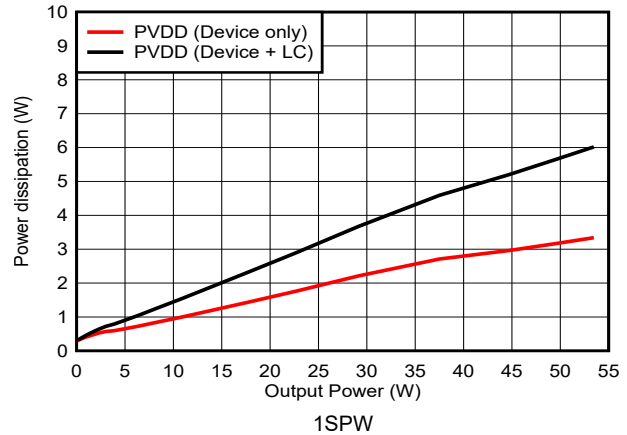
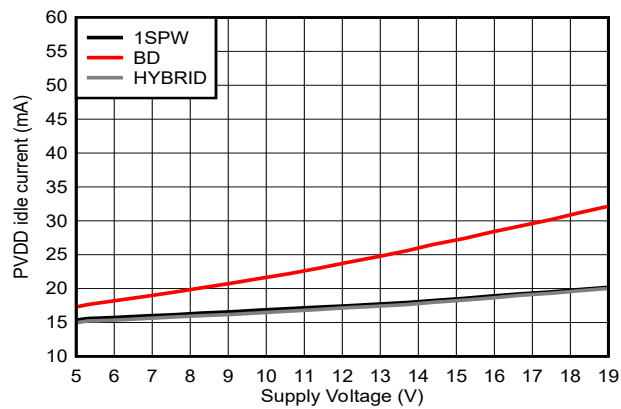
Figure 5-46. Power Dissipation vs Output Power - 2 Ω

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5.7 Typical Characteristics (384kHz) (continued)

Test conditions (unless otherwise noted): $T_C = 25^\circ\text{C}$, $PVDD = 14.4\text{V}$, $DVDD = 1.8\text{V}$, $R_L = 4\Omega$, $P_{out} = 1\text{W/ch}$, $f_{out} = 1\text{kHz}$, $F_{sw} = 384\text{kHz}$, 900k Ω Zero frequency, AES17 Filter, reconstruction filter as described in [Parameter Measurement Information](#), default I2C settings, see application diagram

**Figure 5-47. Power Dissipation vs Output Power - 4 Ω** **Figure 5-48. Power Dissipation vs Output Power - 2 Ω** **Figure 5-49. PVDD Idle Current vs Supply Voltage**

6 Parameter Measurement Information

The parameters for the TAS6511-Q1 device were measured using the circuit in [Section 11.4](#).

For measurements with 2.048MHz switching frequency the below 3.3μH inductors were used.

- 4Ω: Cyntec VCTA32252T-3R3MS6
- 2Ω: Cyntec VCMV053T-3R3MN22M

For measurements with 384kHz switching frequency the below 10μH inductors were used.

- 4Ω: Cyntec VAMV06077E-100MM2
- 2Ω: Cyntec VAMV08089A-100MM2

When enabling Real-Time Load Diagnostics with the integrated pilot tone, an analog balanced input filter must be used to avoid misleading measurement results. An elliptic high pass filter as provided by the APx500 series with a cutoff frequency of 20 Hz and a low-pass filter such as AES17 (20 kHz) are recommended. If the test equipment does not support this filter type, it is recommended to turn off the Real-Time Load Diagnostics for accurate performance measurements.

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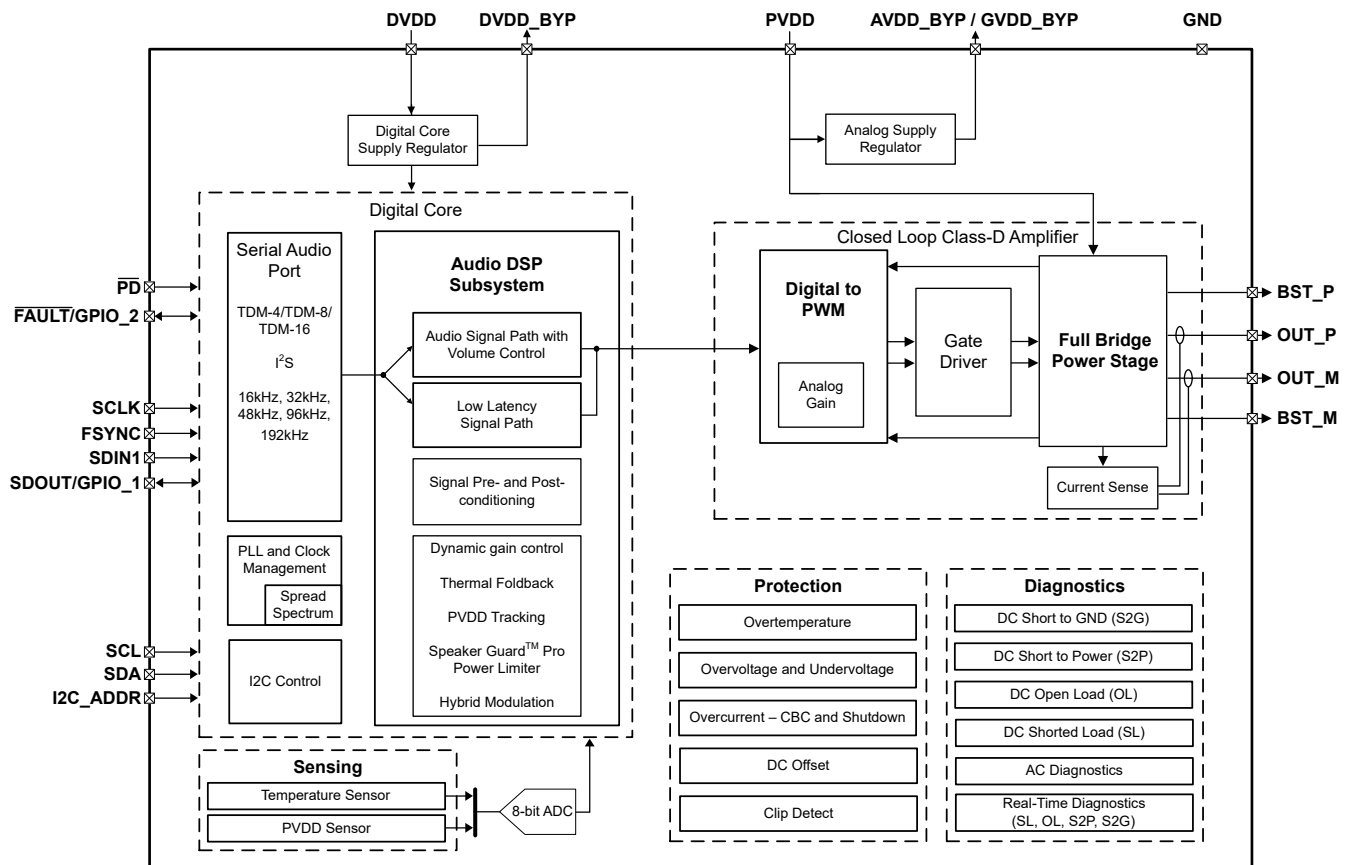
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7 Detailed Description**7.1 Overview**

The TAS6511-Q1 device is a mono-channel digital input Class-D audio amplifier, specifically designed for use in the automotive industry. The ultra-efficient Class-D technology allows for reduced power consumption, reduced PCB area, and less heat in the electrical system. The device realizes a high-fidelity audio sound system design with smaller size, lower weight, and advanced functionality.

The core design blocks are:

- Serial audio port
- PLL and Clock management
- Audio DSP subsystem
- Pulse width modulator (PWM) with output stage feedback
- Gate drive
- Power FETs
- Current Sense
- Diagnostics including Real-Time Load Diagnostics
- Protection
- Power supply
- I²C serial communication bus
- Sensing

7.2 Functional Block Diagram**Figure 7-1. Functional Block Diagram**

7.3 Feature Description

7.3.1 Power Supply

The device has two power supply inputs DVDD and PVDD, which are described as follows:

DVDD This is a 1.8 V or 3.3 V supply that is connected at the DVDD pin and provides power to the digital circuitry.

PVDD This pin is a higher voltage supply that can be connected to the vehicle battery or the regulated voltage rail within the [Recommended Operating Conditions](#). PVDD supplies the power to the output FETs and higher voltage analog circuits.

Several on-chip regulators are included and generate the voltages necessary for the internal circuitry. The external pins are provided only for bypass capacitors to filter the supply and should not be used to power other circuits.

The device reports the supplied PVDD voltage in [PVDD_SENSE Register \(Address = 0x74\)](#).

The device can withstand fortuitous open ground and power conditions within the absolute maximum ratings for the device. Fortuitous open ground usually occurs when a speaker wire is shorted to ground, allowing for a second ground path through the body diode in the output FETs.

7.3.1.1 Power-Supply Sequence

7.3.1.2 Power-Up Sequence

At power-up, the $\overline{\text{PD}}$ pin is recommended to be kept low until both power supply rails (PVDD and DVDD) are within the [Recommended Operating Conditions](#).

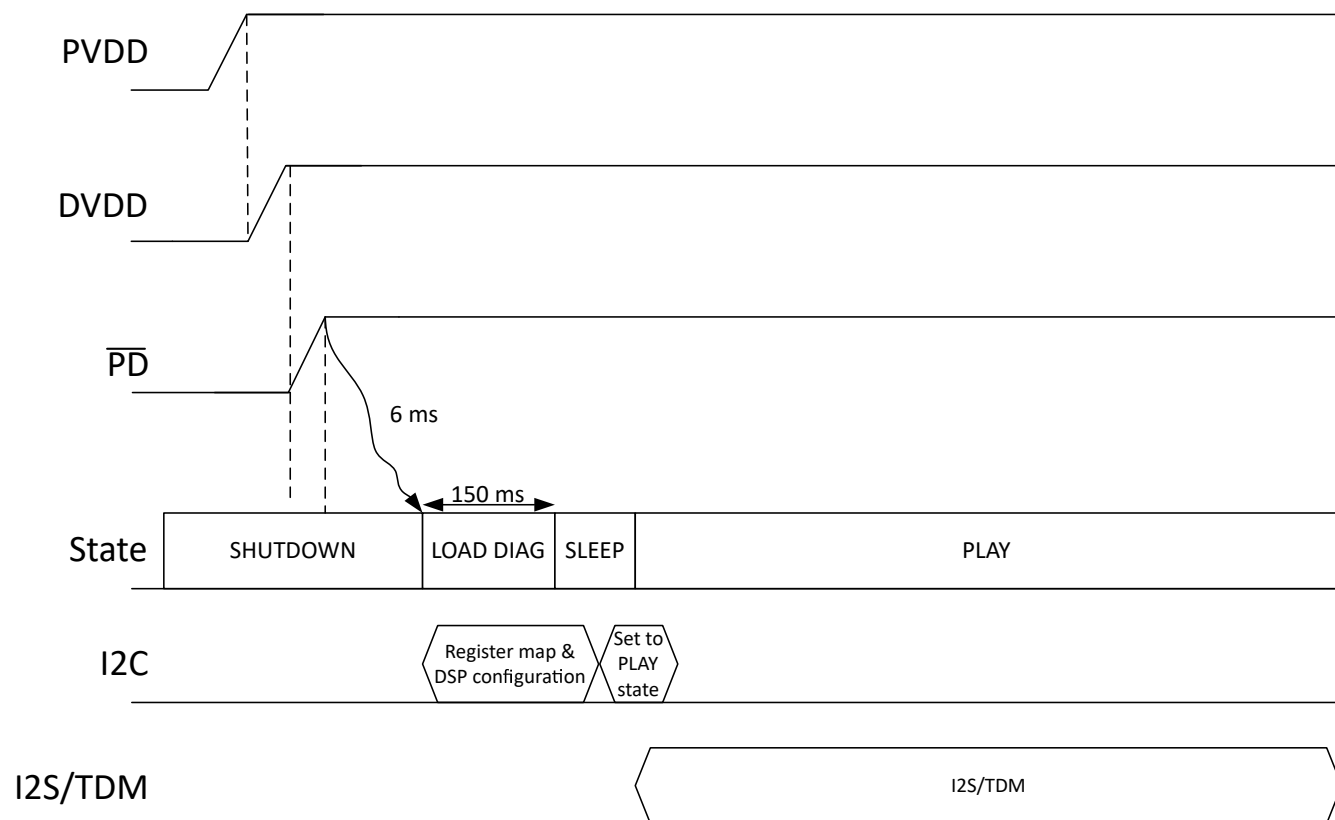
When all power rails are applied and ready, releasing the PD pin will power up the internal digital and analog circuitry. The following state transition might take up to 6 ms in which the device powers up the analog circuitry and ensures a proper internal boot procedure.

If DVDD is applied before PVDD and while the PD pin has been released, then a PVDD Undervoltage Fault will be reported. [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#) bit 1 needs to be read to be cleared after the power-up sequence is completed.

Any time a power fault happens after the analog circuitry is powered up (PVDD ready and $\overline{\text{PD}}$ released), TAS6511-Q1 will leave PLAY or other states and go back to the Auto Recovery (AUTOREC) state, until the power fault disappears.

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Applying DVDD before PVDD will lead to a reported "PVDD Undervoltage Fault" which needs to be cleared

Figure 7-2. TAS6511-Q1 Power-Up Sequence

7.3.1.2.1 Quick-Start Sequence

In some cases a quick startup time from shutdown to audio playback is needed. For the quickest startup the DC Load Diagnostics can be aborted. This allows the device to go into PLAY state without having to wait for DC Load Diagnostics to finish. The below procedure can be used for a quick-start sequence.

Note

Aborting or bypassing the DC Diagnostics can cause the device to turn on the power stage into a fault condition such as a shorted load drawing significant amount of current before triggering overcurrent protection or real-time load diagnostics fault, if enabled.

1. Bring $\overline{\text{PD}}$ HIGH.
2. Wait 1ms
3. Set the LDG ABORT bit in the [DC_LDG_CTRL Register \(Address = 0xB0\)](#)
4. Configure the device DSP and register settings
5. Set channel to PLAY state using [STATE_CTRL Register \(Address = 0x03\)](#)

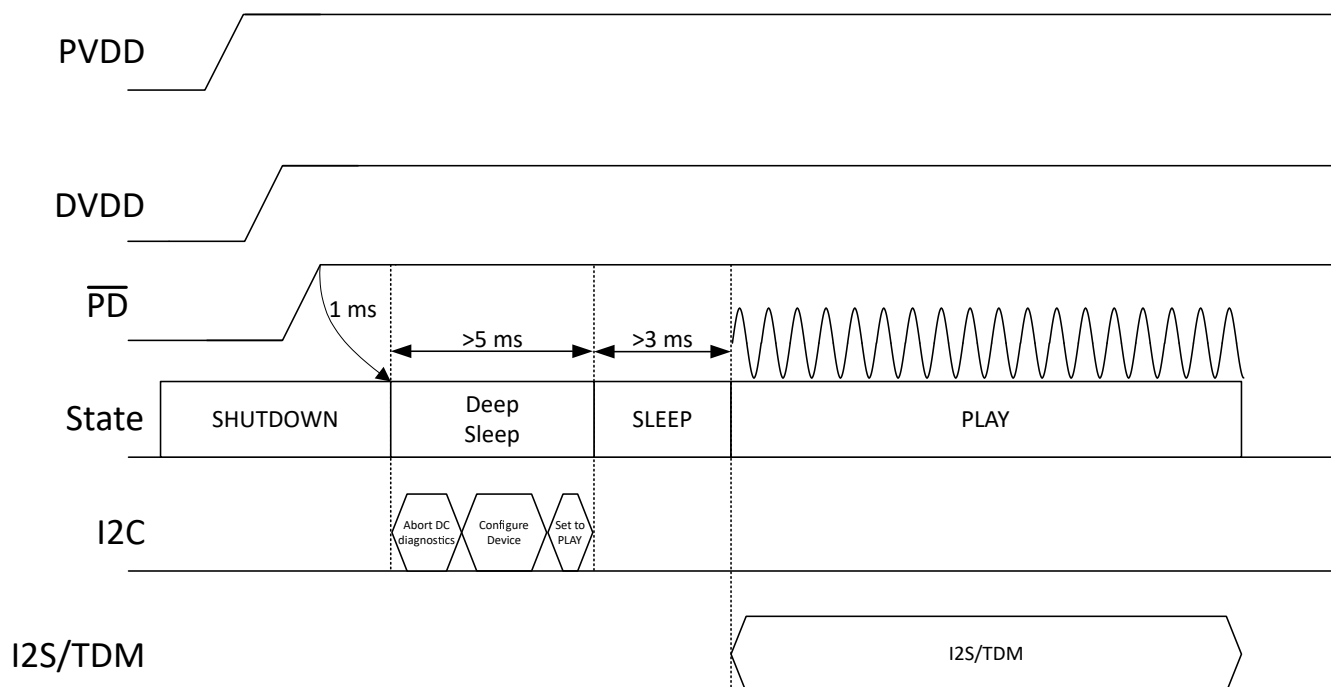


Figure 7-3. TAS6511-Q1 Quick-Start Sequence

7.3.1.3 Power-Down Sequence

To power-down the device, first set the $\overline{\text{PD}}$ pin low for at least 10 ms before removing PVDD, or DVDD. After 10 ms, the power supplies can be removed. Removing PVDD first is recommended before removing the DVDD supply.

7.3.1.4 Device Initialization and Power-On-Reset (POR)

The device initializes when either the system first powers up, the $\overline{\text{PD}}$ pin is pulled high, or when the DVDD voltage falls below the POR threshold and then comes back to normal condition.

During device initialization all I²C registers are set to default values.

The I²C device address is determined from the I2C_ADDR pin. See [I²C Address Selection](#) for details.

After initialization, bit 7 of the [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#) indicates that the device went through a POR cycle. Reading this I²C register resets the fault signal. By default, this signal is not routed to a pin but the signal can be configured accordingly by the $\overline{\text{FAULT}}$ pin in [REPORT_ROUTING_2 Register \(Address = 0x90\)](#) or the $\overline{\text{WARN}}$ pin if a GPIO pin is configured to the $\overline{\text{WARN}}$ function in [REPORT_ROUTING_3 Register \(Address = 0x91\)](#). The pin signal is latching and can be reset by writing '1' to the CLEAR FAULT bit 3 in [RESET Register \(Address = 0x01\)](#).

7.3.2 Serial Audio Port

The Serial Audio Interface can receive data in left-justified, I²S, or DSP mode formats. In addition, time-division multiplexing (TDM) can be implemented to enable multichannel operation with support up to TDM16.

The pin SDIN is available for the data transfer, while any of the GPIO pins can be assigned to SDOUT if required. Refer to [GPIO Pins](#) for more details.

7.3.2.1 Left-Justified Timing

Left-Justified timing uses the FSYNC pin to define when the data is being transmitted for the left channel or the right channel. The MSB of the left channel is valid on the rising edge of the serial clock (SCLK) following the rising edge of the audio frame clock (FSYNC). Similarly, the MSB of the right channel is valid on the rising edge of SCLK clock following the falling edge of FSYNC. A channel offset can be configured and is identical across all

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channels. Whether the device plays the left channel or right channel data can be configured using the [I2S_CTRL Register \(Address = 0x22\)](#) bits 6 and 7.

Configuring Left-Justified Timing:

1. Set the data format to LTJ mode in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 the [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Configure the optional 10-bit offset in bit 6-7 of [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) and [SDIN_AUDIO_OFFSET Register \(Address = 0x28\)](#)

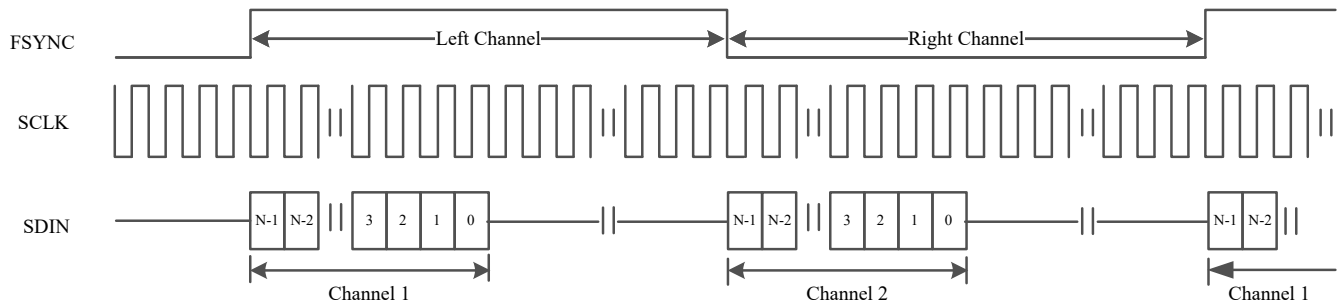


Figure 7-4. Timing Diagram for Left-Justified Timing

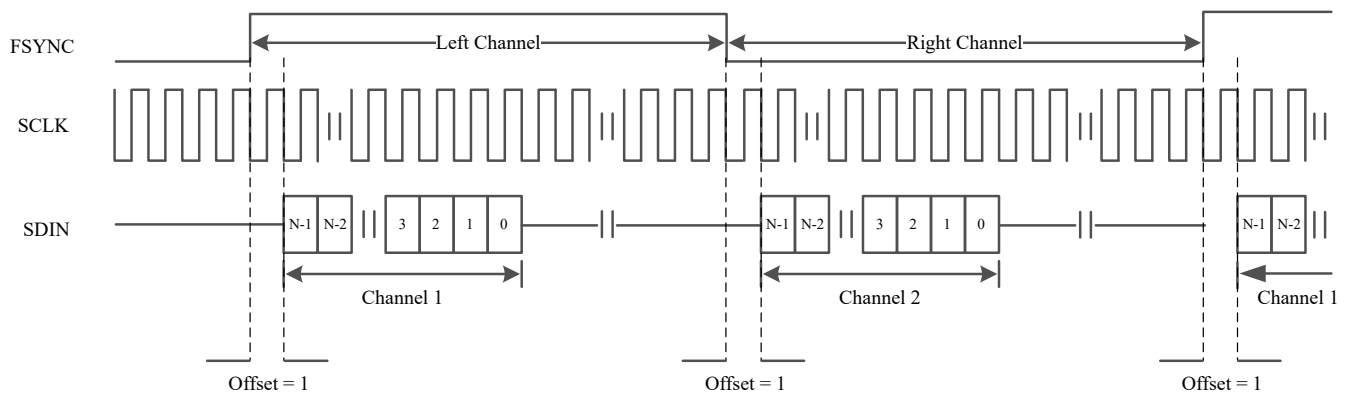


Figure 7-5. Timing Diagram for Left-Justified Timing with Offset 1 = 1

7.3.2.2 I²S Mode

I²S mode uses the FSYNC pin to define when the data is being transmitted for the left channel and when the data is being transmitted for the right channel. In I²S mode, the MSB of the left channel is valid on the second rising edge of the serial clock (SCLK) after the falling edge of the audio frame clock (FSYNC). Similarly the MSB of the right channel is valid on the second rising edge of SCLK after the rising edge of FSYNC. A channel offset can be configured and is identical for across channels. Whether the device plays the left channel or right channel data can be configured using the [I2S_CTRL Register \(Address = 0x22\)](#). The device can also be configured to use the other channel data in parallel as a low latency signal that will be internally mixed. See the [Low Latency Signal Path](#) section of the datasheet for more information on how to use this feature.

Configuring I²S mode:

1. Set the data format to I²S in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 of the [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Select left or right channel data for Audio Data in [I2S_CTRL Register \(Address = 0x22\)](#). The default channel for Audio Data is left.
4. If the secondary Low Latency path will be used, enable in bit 0 of [LL_EN Register \(Address = 0x32\)](#) and select left or right channel Low Latency data in [I2S_CTRL Register \(Address = 0x22\)](#). The default channel for Low Latency Data is right.

5. Configure the optional 10-bit offset in bit 6-7 of **SDIN_OFFSET_MSB Register (Address = 0x27)** and **SDIN_AUDIO_OFFSET Register (Address = 0x28)**

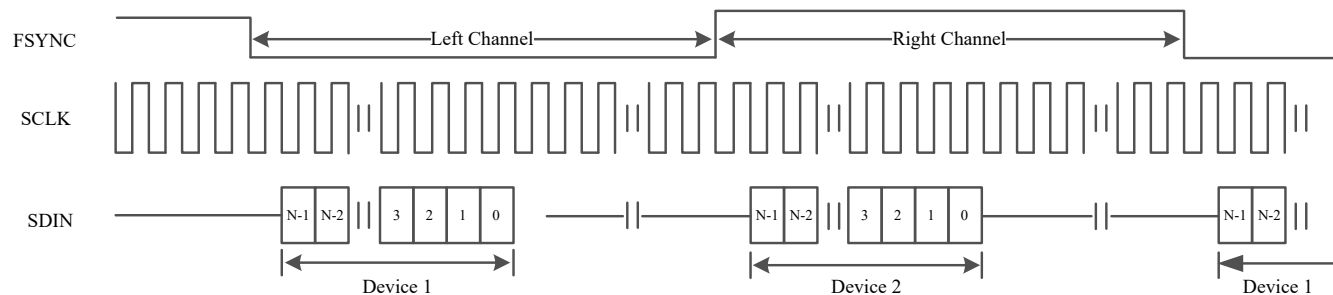


Figure 7-6. Timing Diagram for I2S Mode

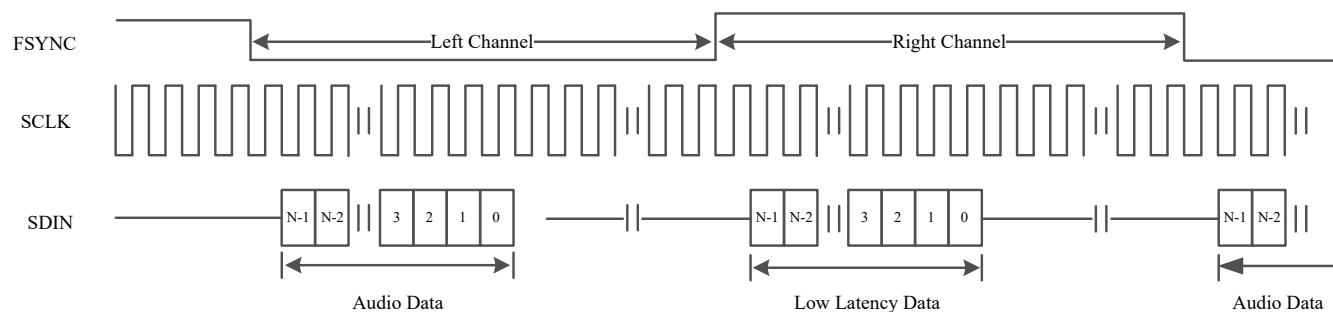


Figure 7-7. Timing Diagram for I2S Mode with Low Latency path

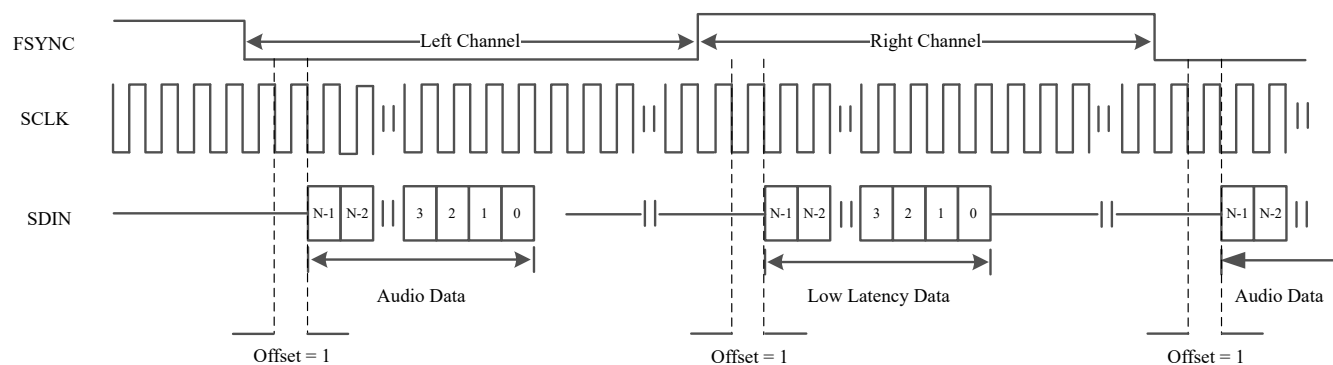


Figure 7-8. Timing Diagram for I2S Mode with Low Latency path and Offset = 1

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7.3.2.3 DSP Mode

DSP mode uses the FSYNC pin to define the start of the audio data, but not to differentiate between channels. The rising edge of the audio frame clock (FSYNC) starts the data transfer with the left channel data first and is immediately followed by the right channel data. Each data bit is valid on the rising edge of the serial clock (SCLK). A 10-bit channel offset can be configured for both the Audio and Low Latency Paths. DSP mode enables the use of the Low Latency Path, and by default Audio data is first, Low Latency Data is second.

Configuring DSP mode:

1. Set the data format to DSP in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 of [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Select the slot for the Audio data in [AUDIO_SLOT_SELECT Register \(Address = 0x33\)](#).
4. If the data stream has an offset (for example, a 1 bit offset), a 10-bit offset is available for configuration in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#)(MSB) and [SDIN_AUDIO_OFFSET Register \(Address = 0x28\)](#) (LSB). The default offset is 0.
 - a. If the bit offset is applied, the same offset must be set in bit 4-5 in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) (MSB) and [SDIN_LL_OFFSET Register \(Address = 0x29\)](#) (LSB). The default offset is 0.
5. If the FSYNC pulse is shorter than 8 x SCLK, set [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#) bit 0-1 to "01"

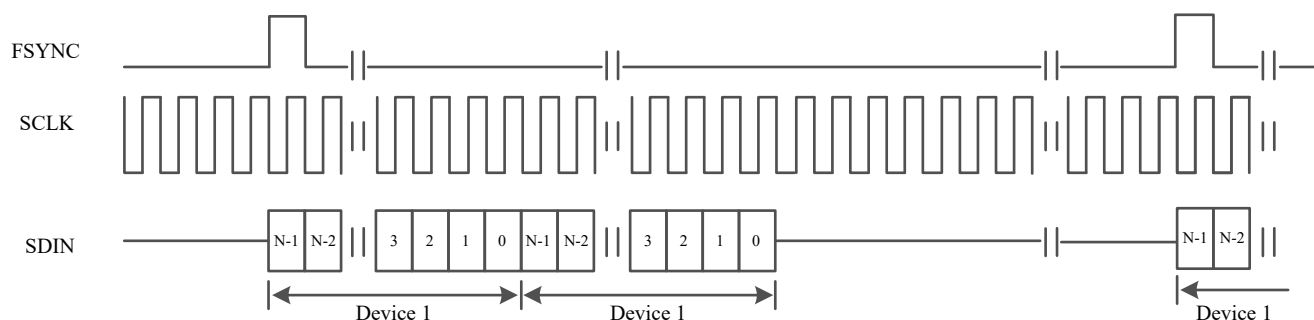


Figure 7-9. Timing Diagram for DSP Mode

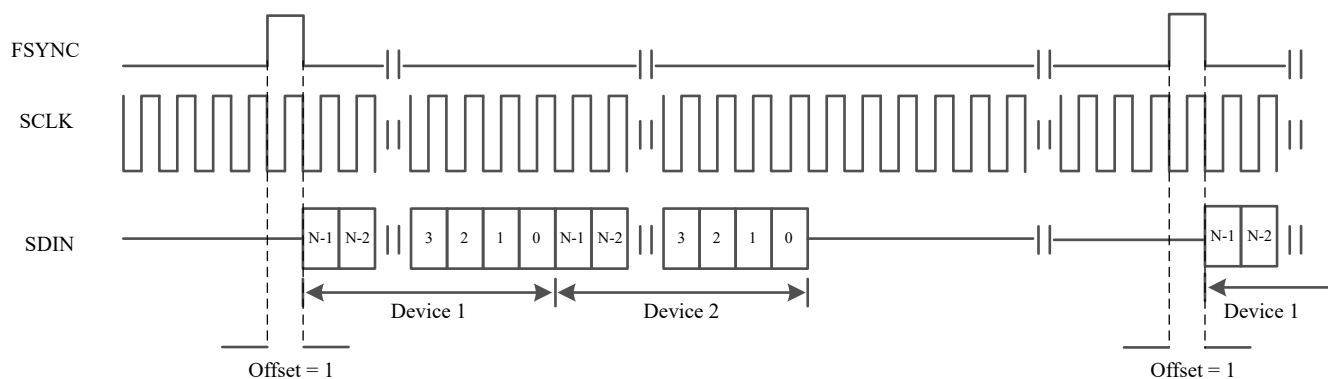


Figure 7-10. Timing Diagram for DSP Mode with Offset = 1

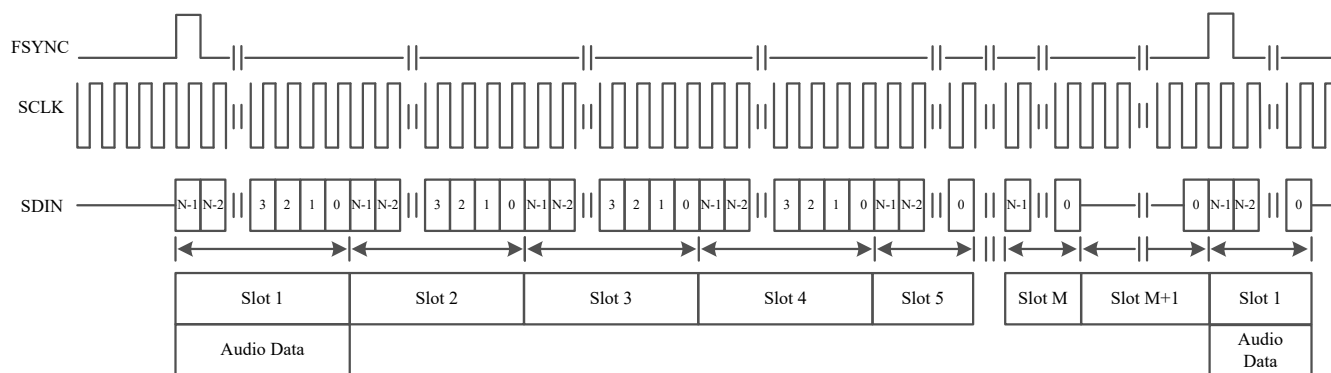
7.3.2.4 TDM Mode

TDM mode supports 4, 8, or 16 channels of audio data through a single pin, SDIN. The data format follows the [DSP Mode](#).

TDM mode enables the possibility to transmit additional data besides audio for TAS6511-Q1. This includes a secondary Low Latency path, which is disabled by default. It can be enabled in [LL_EN Register \(Address = 0x32\)](#). For more information on this function see [Low Latency Signal Path](#).

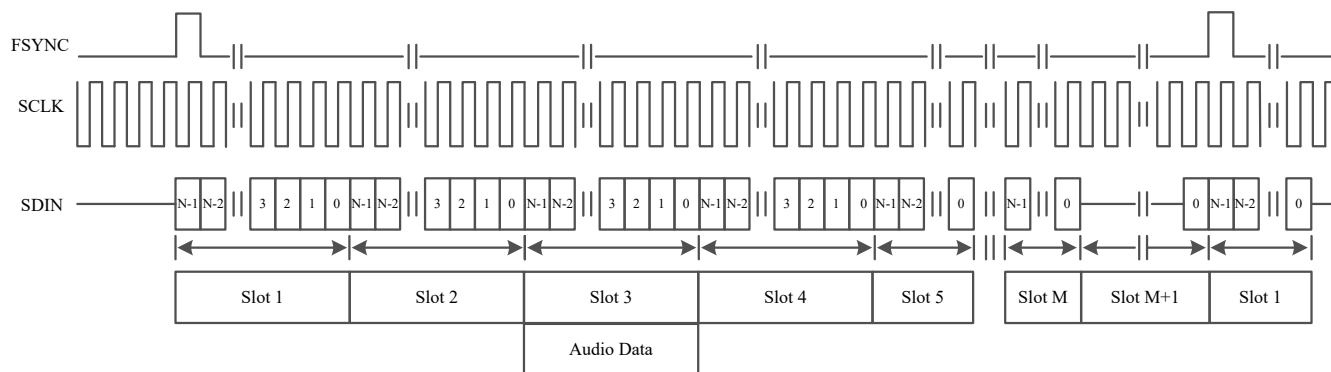
Configuring TDM mode while using the Audio Path only:

1. Set the data format to TDM/DSP in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 of [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Select the TDM slot for the Audio data in [AUDIO_SLOT_SELECT Register \(Address = 0x33\)](#).
4. If the TDM stream has an offset (for example, a 1 bit offset), a 10-bit offset is available for configuration in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#)(MSB) and [SDIN_AUDIO_OFFSET Register \(Address = 0x28\)](#) (LSB). The default offset is 0.
 - a. If the bit offset is applied, the same offset must be set in bit 4-5 in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) (MSB) and [SDIN_LL_OFFSET Register \(Address = 0x29\)](#) (LSB). The default offset is 0.
5. If the FSYNC pulse is shorter than 8 x SCLK, set [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#) bit 0-1 to "01"



Example: Select TDM Slot 1
Register 0x33 = 0x00: Audio Data Slot 1

Figure 7-11. Timing Diagram for TDM Mode

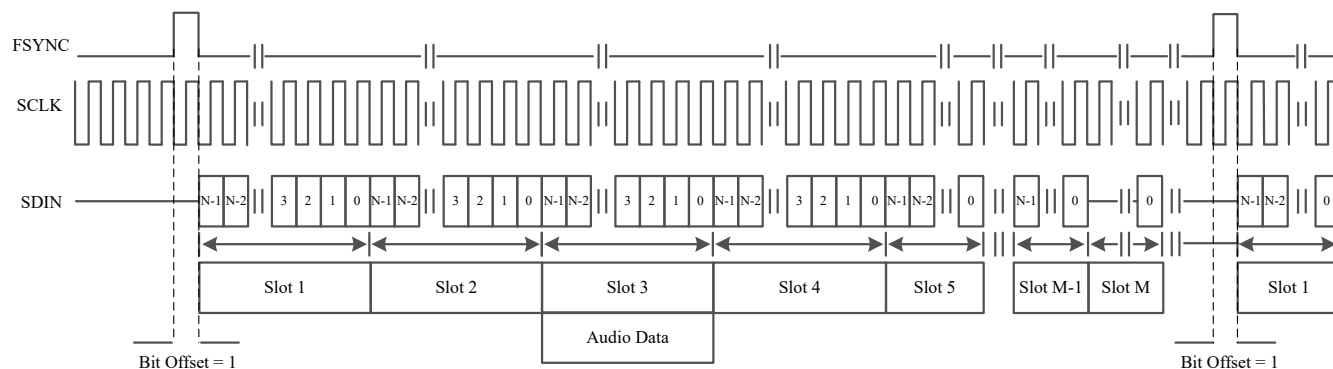


Example: Select TDM Slot 3
Register 0x33 = 0x02: Audio Slot 3

Figure 7-12. Timing Diagram for TDM mode with Slot = 3

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Example: TDM Slot 3 with 1 bit offset
 Register 0x33 = 0x02: Audio Slot 3
 Register 0x27 = 0x00, Register 0x28 = 0x01, Register 0x29 = 0x01: 1 bit offset

Figure 7-13. Timing Diagram for TDM mode with Slot = 3 and Offset = 1**Configuring TDM mode while using the Full Featured Low Latency Path only:**

The Full Featured Low Latency Path expects Audio data in the same place as the standard audio path.

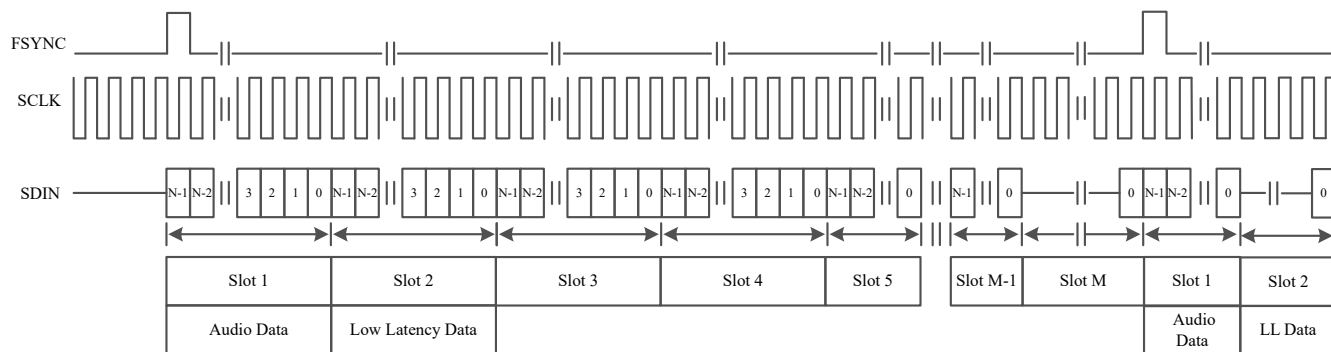
1. Set the data format to TDM/DSP in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 of [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Enable the Full Featured Low Latency Audio path in bit 1 of [LL_EN Register \(Address = 0x32\)](#)
4. Select the TDM slot for the Full featured Low Latency Audio data in [AUDIO_SLOT_SELECT Register \(Address = 0x33\)](#).
5. If the TDM stream has an offset (for example, a 1 bit offset), a 10-bit offset is available for configuration in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#)(MSB) and [SDIN_AUDIO_OFFSET Register \(Address = 0x28\)](#) (LSB). The default offset is 0.
 - a. If the bit offset is applied, the same offset must be set in bit 4-5 in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) (MSB) and [SDIN_LL_OFFSET Register \(Address = 0x29\)](#) (LSB). The default offset is 0.
6. If the FSYNC pulse is shorter than 8 x SCLK, set [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#) bit 0-1 to "01"

The timing diagram for the Full Featured Low Latency Path follows the same configuration as the Audio Path Only.

Configuring TDM mode while using both Audio and Low Latency Paths:

1. Set the data format to TDM/DSP in bit 2-3 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#)
2. Set the data length in bit 2-3 of [SDIN_CTRL Register \(Address = 0x23\)](#)
3. Enable the Low Latency path in bit 0 of [LL_EN Register \(Address = 0x32\)](#)
4. Select TDM slots for Audio and Low Latency Path Data in [AUDIO_SLOT_SELECT Register \(Address = 0x33\)](#) and [LL_SLOT_SELECT Register \(Address = 0x34\)](#), respectively.
 - a. If the default values are left unchanged (Slot 1 for [AUDIO_SLOT_SELECT Register \(Address = 0x33\)](#) and Slot 1 for [LL_SLOT_SELECT Register \(Address = 0x34\)](#)), or are assigned to the same slot, Low Latency Data will immediately follow the Audio Path Data to avoid overlap.
5. If the TDM stream has an offset, (for example, a 1 bit offset), a 10-bit offset is available for each applicable channel group to determine the timing and avoid overlapping data. If an offset is used, the same offset should be set in both data paths. The additional bit offsets can be set in:
 - a. **Audio Channel** Bit 6-7 in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) (MSB) and [SDIN_AUDIO_OFFSET Register \(Address = 0x28\)](#) (LSB). The default offset is 0.
 - b. **Low Latency Channel** Bit 4-5 in [SDIN_OFFSET_MSB Register \(Address = 0x27\)](#) (MSB) and [SDIN_LL_OFFSET Register \(Address = 0x29\)](#) (LSB). The default offset is 0.

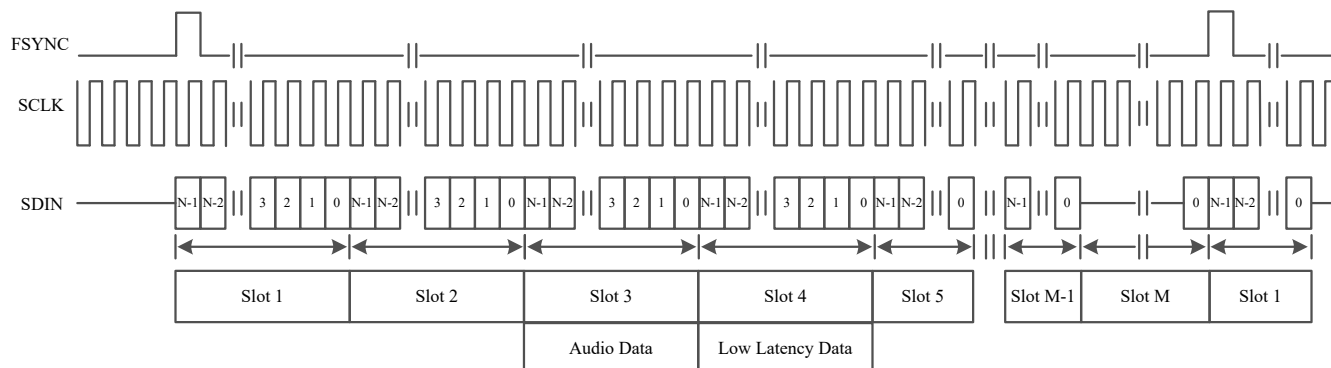
- c. When both the Audio path and Low Latency Path slots are selected to be the same slot (default Slot 1) in **AUDIO_SLOT_SELECT Register (Address = 0x33)** and **LL_SLOT_SELECT Register (Address = 0x34)**, and the 10-bit offset is also the same (default 0), low latency channel data will immediately follow the audio channel data. To avoid data overlap, it is recommended to always set the same bit offset for the Audio and Low Latency Paths.
6. If the FSYNC pulse is shorter than 8 x SCLK, set **AUDIO_INTERFACE_CTRL Register (Address = 0x21)** bit 0-1 to "01"



Example: Select TDM Slot 1 for Audio Data, Slot 2 for Low Latency Data

Register 0x33 = 0x00: Audio Slot 1
Register 0x34 = 0x01: Low Latency Slot 2

Figure 7-14. Timing Diagram for TDM Mode with Audio and Low Latency Data



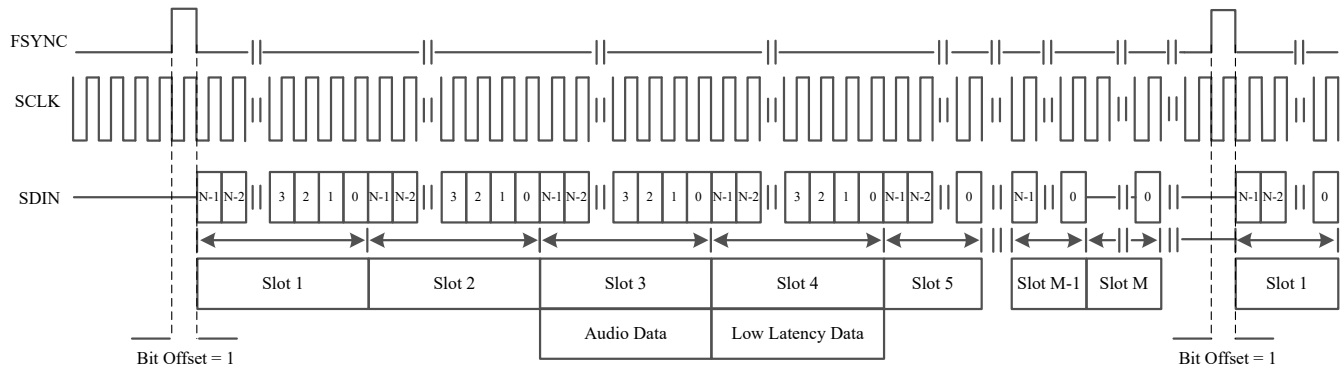
Example: Select TDM Slot 3 for Audio Data, Slot 4 for Low Latency Data

Register 0x33 = 0x02: Audio Slot 3
Register 0x34 = 0x03: Low Latency Slot 4

Figure 7-15. Timing Diagram for TDM Mode with Audio Slot = 3 and Low Latency Data Slot = 4

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Example: Select TDM Slot 3 for Audio Data and TDM Slot 4 for Low Latency Data, with 1 bit offset

Register 0x33 = 0x02: Audio Slot 3

Register 0x34 = 0x03: Low Latency Data Slot 4

Register 0x27 = 0x00, Register 0x28 = 0x01, Register 0x29 = 0x01: 1 bit offset

Figure 7-16. Timing Diagram for TDM Mode with Audio Slot = 3 and Low Latency Data Slot = 4, 1 bit offset for Audio and Low Latency Path

7.3.2.5 SDOUT - Data Output

TAS6511-Q1 can transmit selected data in either I²S mode or TDM mode. The audio input serial clock (SCLK) and audio frame clock (FSYNC) is reused, and the outgoing data has the same sampling frequency and maximum audio frame size as the audio input signal. The word length of the SDOUT data can be configured in the [SDOUT_CTRL Register \(Address = 0x25\)](#).

SDOUT requires the [Serial Audio Port](#) to operate in I²S or TDM mode data formats. Left-justified and DSP mode formats are not supported.

The following data groups can be transmitted through SDOUT:

- **Isense** - Current Sense feedback by channel
- **Vpredict** - Output voltage estimate based on supply voltage and input signal by channel
- **Temperature** - 8-bit device temperature reading from integrated temperature sensor
- **PVDD Voltage** - 8-bit device PVDD sensor voltage reading

The temperature data and PVDD voltage data can be added to the SDOUT data stream by setting bit 5 of the [SDOUT_DATA Register \(Address = 0x5B\)](#) to 1. When this bit is set to 1, the Isense data and Vpredict data is 16-bit else the data is set to the word length configured in [SDOUT_CTRL Register \(Address = 0x25\)](#).

Note

The availability of the data for output transmission depends on the activation of the underlying function. Example: Isense requires Current Sense to be enabled.

Note

The data word length must be set to at 24-bits or greater if temperature and PVDD data is enabled, to avoid data from truncating the LSBs.

Note

The phase offset between Isense and Vpredict data is configurable in the DSP.

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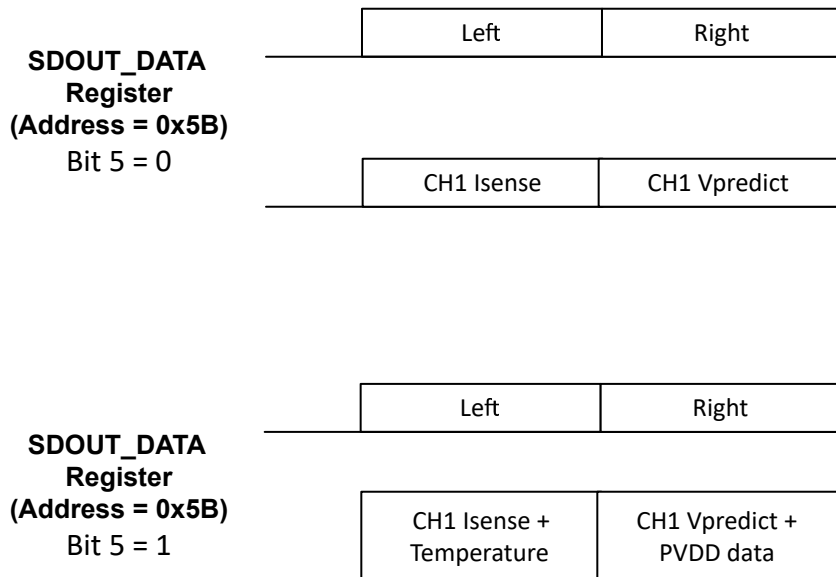
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7.3.2.5.1 SDOUT - I²S Configuration

Using SDOUT in I²S mode requires the usage of one of the GPIO pins to be configured as an SDOUT pin to transmit data. See [General Purpose Output](#) for details on how to configure a GPIO pin as SDOUT. When the SDOUT is configured in I²S format the left and right channel data will be formatted as outlined in [Table 7-1](#)

Table 7-1. SDOUT - I²S Configuration

SDOUT_DATA Register (Address = 0x5B) bit 5	Isense Data Group	Vpredict Data Group
0	24-bit Isense + 8-bit 0	24-bit Vpredict + 8-bit 0
1	16-bit Isense + 8-bit Temperature Data + 8-bit 0	16-bit Vpredict + 8-bit PVDD data + 8-bit 0

**Figure 7-17. SDOUT I²S Configuration**

7.3.2.5.2 SDOUT - TDM Configuration

Transmitting data through SDOUT in TDM mode requires a minimum of one data output.

Similar to the [SDIN TDM configuration](#), a TDM slot selection feature and an additional 10-bit offset is used for the SDOUT data to determine the timing and avoid overlapping data. The slot selection feature selects the TDM slot output for each data group and can be selected in [ISENSE_OUTPUT_SLOT Register \(Address = 0x35\)](#) and [VPREDICT_OUTPUT_SLOT Register \(Address = 0x36\)](#). The additional bit offset is defined as the number of SCLK cycles from the start (MSB) of the audio frame to the start of the data group. The bit offset for the ISENSE data group is located in Bit 6-7 in [SDOUT_OFFSET_MSB Register \(Address = 0x2C\)](#) (MSB) and [ISENSE_OFFSET Register \(Address = 0x2D\)](#) (LSB). The default offset is 0 bits. The bit offset for the Vpredict data group is located in Bit 6-7 in [SDOUT_OFFSET_MSB Register \(Address = 0x2C\)](#) (MSB) and [VPREDICT_OFFSET Register \(Address = 0x2E\)](#) (LSB). The default offset is 0 bits.

The SDOUT data consist of the Isense data, Vpredict data, Temperature data, and PVDD voltage data. The format of the output datastream is outlined in [Table 7-2](#). In multi-device systems the slot select can be utilized to shift data groups to available slots and allow multiple devices to share one TDM line.

Figure 7-18 shows the format of the Isesne and Vpredict data.

Table 7-2. SDOUT - TDM Configuration

SDOUT_DATA Register (Address = 0x5B) Bit 5	Isense Data Group	Vpredict Data Group
0	16-bit Isense + 8-bit 0	16-bit Vpredict + 8-bit 0
1	16-bit Isense + 8-bit Temperature Data + 8-bit 0	16-bit Vpredict + 8-bit PVDD data + 8-bit 0

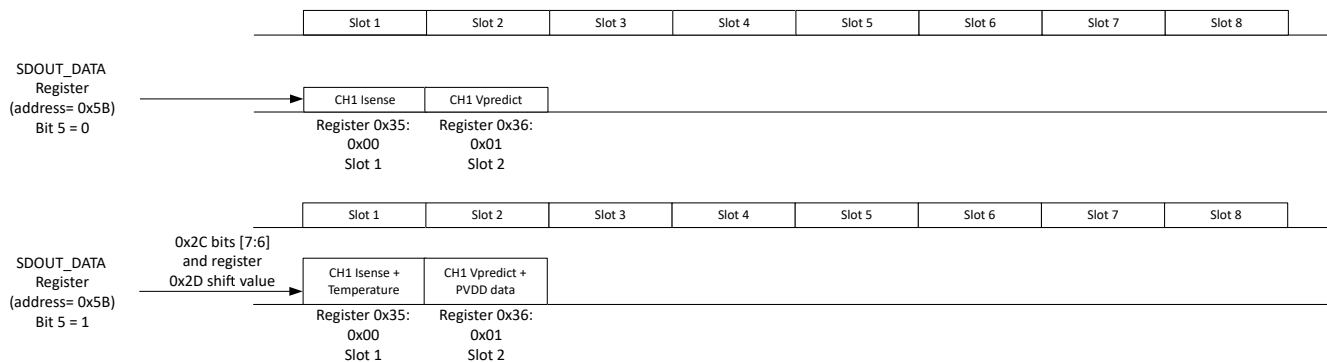


Figure 7-18. TDM SDOUT Format and Configuration

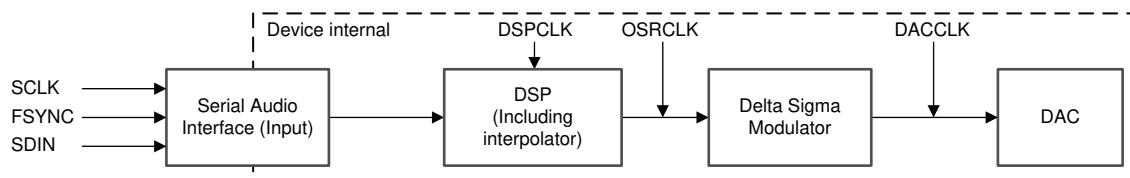
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7.3.2.6 Device Clocking

The TAS6511-Q1 has a flexible clocking system. Internally, the device requires several additional clocks, mostly at related clock rates to function correctly. All of these clocks can be derived from the Serial Audio Interface.

Figure 7-19 shows the basic data flow and clock distribution.

**Figure 7-19. Audio Flow with Respective Clocks**

The Serial Audio Interface typically has 3 connection pins which are listed as follows:

- SCLK (Audio Serial Clock)
- FSYNC (Frame Sync in TDM or Left/Right in I²S)
- SDIN (Input Data)
- Optional: SDOUT for outgoing data transmission.

The device has an internal PLL which uses SCLK as a reference clock and creates the higher rate clocks required by the DSP and the DAC clock.

The TAS6511-Q1 has an audio sampling rate detection circuit that automatically senses the sampling frequency. Common audio sampling frequencies of 16kHz, 32kHz, 44.1kHz – 48 kHz, 88.2 kHz – 96 kHz, and 192 kHz are supported. The sampling frequency detector sets the clock for DAC and DSP automatically.

7.3.2.6.1 Clock Rates

The serial audio interface port is a 3-wire serial port with the signals SCLK, FSYNC and SDIN.

SCLK is the serial audio bit clock used to clock the serial data present on SDIN into the serial shift register of the audio interface. Serial data is clocked into the TAS6511-Q1 device with SCLK.

The FSYNC pin is the serial audio left/right word clock or frame sync when the device is operated in TDM Mode.

SDIN is the TDM or I2S data input.

Table 7-3. Audio Data Formats, Bit Depths and Clock Rates

Format	Data Bits	Maximum FSYNC Frequency (kHz)	SCLK Rate (f_s)
I ² S / LJ	32, 24, 20, 16	16 to 192	x64, x32
TDM	32, 24, 20, 16	16 to 48	x128, x256, x512
		96	x128, x256
		192	x128

When a clock halt or a non-supported SCLK to FSYNC ratio is detected, the device reports the clock halt or a non-supported SCLK to FSYNC ratio as a latched report in bit 0 of [CLK_FAULT_LATCHED Register \(Address = 0x8A\)](#). The latched error report clears on read.

7.3.2.6.2 Clock Halt Auto-recovery

Certain host processors halt the audio clock when no audio is playing. When the clock is halted, the device puts the channel into the Hi-Z state and issues a latched error report in [CLK_FAULT_LATCHED Register \(Address = 0x8A\)](#). The transition to Hi-Z occurs gracefully by holding the last received sample from the audio interface and ramping down the volume. This behavior can be changed in bit 7 of [AUDIO_INTERFACE_CTRL Register \(Address = 0x21\)](#). The latched error report clears once read. After audio clock recovery, the device automatically returns to the previous state.

7.3.2.6.3 Sample Rate on the Fly Change

TAS6511-Q1 supports an on-the-fly change in the FSYNC rate. When changing FSYNC, for example from 48 kHz to 96 kHz, the host processor needs to put the FSYNC/SCLK to a halt state for at least 30 ms before changing to the new sample rate. During this halt state, a clock error is reported. See the [Clock Halt Auto-recovery](#) section for further details.

7.3.2.7 Clock Error Handling

After [Power-On-Reset \(POR\)](#) the device assumes that a clock error exists, but does not assert the clock error flag until the clock error detection result is valid.

If any input clock changes are detected, the auto detect system immediately requests the device to mute, while the auto detect continues to monitor and identify a new stable condition.

The clock error flag output to the $\overline{\text{FAULT}}$ pin can be latched or non-latched, based on the configuration in Bit 6 and 7 of the [REPORT_ROUTING_5 Register \(Address = 0x94\)](#).

In latched configuration, the fault can be cleared by reading the [CLK_FAULT_LATCHED Register \(Address = 0x8A\)](#).

7.3.3 Digital Audio Processing

TAS6511-Q1 offers advanced digital audio processing capabilities including:

- High-Pass Filter / DC Blocking
- Digital Volume Control
- PVDD Foldback / AGL
- Thermal Foldback
- Gain Compensation Biquads
- Hybrid Modulation
- Real-Time Load Diagnostics
- Clip Detect
- Low Latency Path
- SpeakerGuard Pro Power Limiter

The availability of specific features is dependent on the selected sampling frequency. Higher sampling frequencies reduce the available processing time of the integrated DSP and limit the number of functions that can operate in parallel. At all sampling frequencies, maintaining that the total processing need of the enabled functions does not exceed the available amount of processing time.

7.3.3.1 PVDD Foldback

PVDD Foldback applies a smooth compression to the audio signal to maintain a consistent dynamic range while the supply voltage (PVDD) varies. This feature helps to prevent unexpected output clipping and distortion in systems where the audio signal would exceed the supply headroom and can also be described as Automatic Gain Limiter (AGL).

An 8-bit ADC senses the applied PVDD voltage. This PVDD sense data provides the necessary inputs for the DSP to calculate the amount of compression that needs to be applied to signal peaks. In addition, the PVDD sense results can be read back via I²C through the [PVDD_SENSE Register \(Address = 0x74\)](#).

The PVDD foldback engages in two functional modes, depending on the measured value of supply voltage (PVDD).

- Mode 1: If PVDD voltage is greater than the maximum peak output voltage (MPOV), no action will be taken by the PVDD sensing circuit since there is still sufficient headroom for the amplifier to reproduce the audio signals up to 0 dBFS.
- Mode 2: If PVDD voltage is less than MPOV, the PVDD sensing circuit will reduce gain to ensure that signals can fit within the available PVDD voltage to avoid clipping. The attack time and time constants of the foldback are configurable.

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PVDD Foldback can be enabled by setting bit 4 in [FOLDBACK_EN Register \(Address = 0x3A\)](#) to 1.

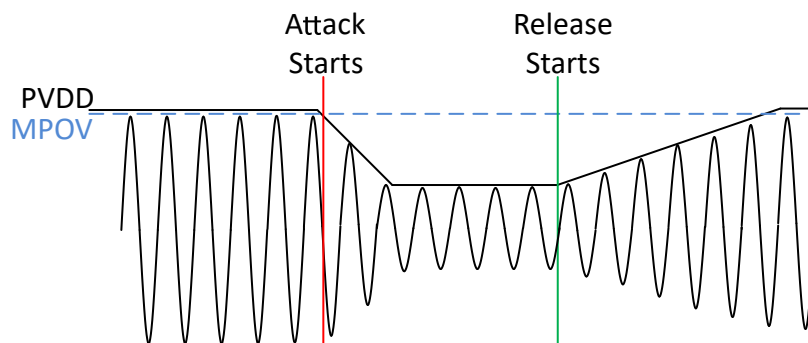


Figure 7-20. PVDD Foldback Example

7.3.3.2 High-Pass Filter

To protect speakers connected to the TAS6511-Q1, a 3Hz DC blocking high pass filter is built into the audio processing path. This filter is turned on by default and be configured in bit 0 of [DC_BLOCK_SPEAKER_GUARD_EN Register \(Address = 0x39\)](#)

7.3.3.3 Analog Gain

TAS6511-Q1 allows the user to set the analog gain for the output channel to 4 different settings.

Analog gain can be configured in [ANALOG_GAIN Register \(Address = 0x4A\)](#).

A gain setting of 0dB corresponds with a peak output voltage of 21V/FS at full scale digital input. TI recommends to select the lowest possible gain for the expected PVDD operation to optimize output noise and dynamic range performance.

The Analog Gain setting is only be changed while the device is in [Hi-Z](#), [DEEP SLEEP](#), or [SLEEP](#) state.

As the device enters [Play](#) state the device gradually ramps the analog gain to the desired value. The ramp speed is configurable in [ANALOG_GAIN_RAMP_CTRL Register \(Address = 0x4E\)](#).

7.3.3.4 Digital Volume Control

The output channel has a digital-volume control with a range from 0 dB to -103 dB in 0.5 dB steps.

The volume control is set through I²C in the register [DIG_VOL_CH1 Register \(Address = 0x40\)](#).

The gain ramp-up and ramp-down rate as well as the step size in dB is programmable through I²C in [DIG_VOL_RAMP_CTRL Register \(Address = 0x44\)](#).

7.3.3.4.1 Auto Mute

When detecting a consecutive stream of zero samples at the audio input, the device can automatically set channel into mute. In this mode, the device continues to monitor the input signal, and, depending on the configuration, unmute the channel at the same time when a valid non-zero signal arrives.

This auto mute feature can be enabled and configured in [AUTO_MUTE_EN Register \(Address = 0x47\)](#). Auto mute is disabled by default.

The required time of consecutive zero samples before auto mute becomes active can be set in [AUTO_MUTE_TIMING Register \(Address = 0x48\)](#).

7.3.3.5 Gain Compensation Biquads

The modulator and output LC filter of the Class-D amplifier can have an undesired influence on frequency response linearity causing frequency drop/peaking. To help compensate for this effect and achieve a flat response, TAS6511-Q1 offers integrated gain compensation biquads.

The biquad is configurable and is disabled by default. To enable the desired tuning, the respective coefficients need to be written to the DSP memory.

7.3.3.6 Low Latency Signal Path

For time-sensitive audio signals that require a minimal processing delay, such as active noise cancellation (ANC) or road noise cancellation (RNC), TAS6511-Q1 offers a low latency signal path. At 48 kHz sampling frequency, this path reduces the signal delay by more than 70% between the input and output of the amplifier by minimizing the internal signal processing.

The low latency signal path is established in parallel to the regular audio signal path. When both signal paths are provided with input data, the two signals - audio and low latency - are internally mixed together right before the output amplification stage. Both signals are added together and the combined signal amplitude must not exceed the available gain range nor the voltage headroom to avoid distortion. Note that the low latency signals pass through the device with less delay than the regular audio path signals.

The low latency signal path is disabled by default. It can be enabled in [LL_EN Register \(Address = 0x32\)](#), bit 0. In TDM mode, a slot selection feature is available to configure the location of the low latency input in the TDM stream. The slot selection can be configured in bit 0-3 of [LL_SLOT_SELECT Register \(Address = 0x34\)](#). See [TDM mode](#) for more details.

In I²S mode the low latency data is selected in [I2S_CTRL Register \(Address = 0x22\)](#) bits 4-5.

Note

The settings in [I2S_CTRL Register \(Address = 0x22\)](#) bits [5:4] and [7:6] must be selected for different audio channel source data.

The low latency signal path is only available at a sampling frequency of 48kHz or 96kHz.

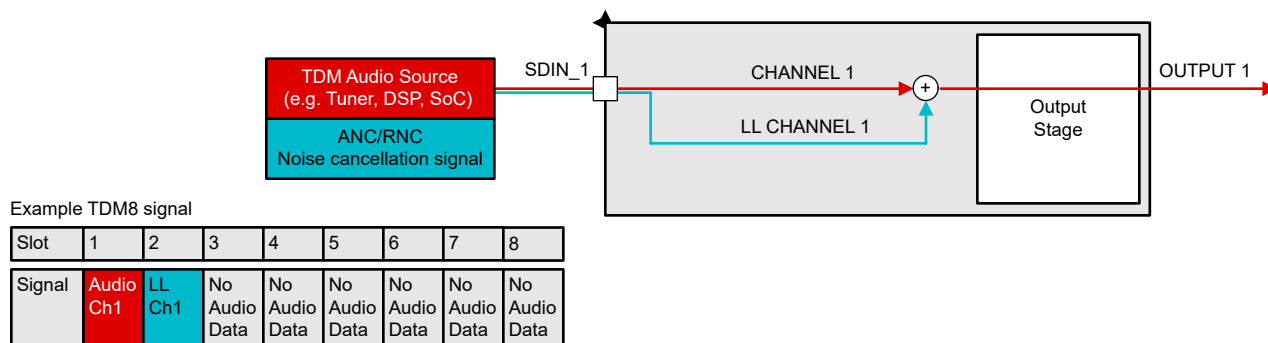


Figure 7-21. Low Latency and Audio Signal Path

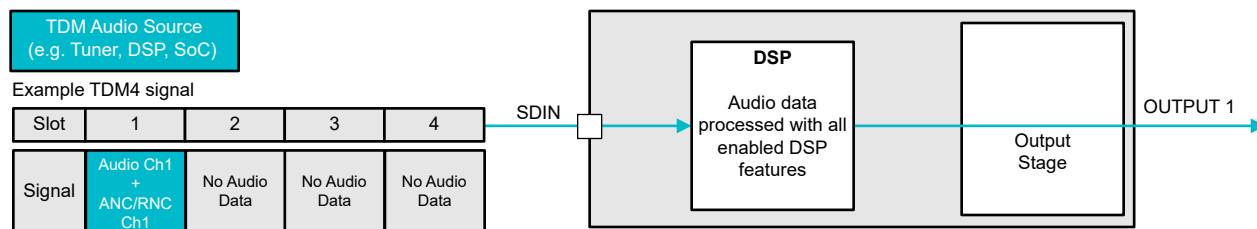
7.3.3.7 Full Feature Low Latency Path

In addition to the Low Latency Signal Path, the TAS6511-Q1 integrates a Full Feature Low Latency Path. Using the Full Feature Low Latency Path the time-sensitive audio signals, such as active noise cancellation (ANC) or road noise cancellation (RNC), can be premixed and do not need to be separated from the non-time-sensitive audio data. The premixed audio data then processed through the DSP and then amplified at the output stage with a lower group delay.

The Full Feature Low Latency Path can be used in both I²S and TDM modes and is disabled by default. To enable, use bit 1 in [LL_EN Register \(Address = 0x32\)](#).

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**Figure 7-22. Full Feature Low Latency Audio Path****7.3.4 Class-D operation and Spread Spectrum Control****7.3.4.1 Modulation**

TAS6511-Q1 supports three modulation schemes: BD modulation, advanced 1SPW modulation and Hybrid modulation. The modulation scheme can be selected in [OUTPUT_CTRL Register \(Address = 0x02\)](#).

7.3.4.1.1 BD Modulation

In BD modulation each output is switching from 0 volts to the supply voltage. The OUT_xP and OUT_xN are in phase with each other with no input signal, resulting in little to no current in the speaker. The duty cycle of OUT_xP is greater than 50% and OUT_xN is less than 50% for positive output voltages. The duty cycle of OUT_xP is less than 50% and OUT_xN is greater than 50% for negative output voltages. In low signal conditions, the voltage across the load sits at 0 V throughout most of the switching period, reducing the switching current and therefore, any I^2R losses in the load.

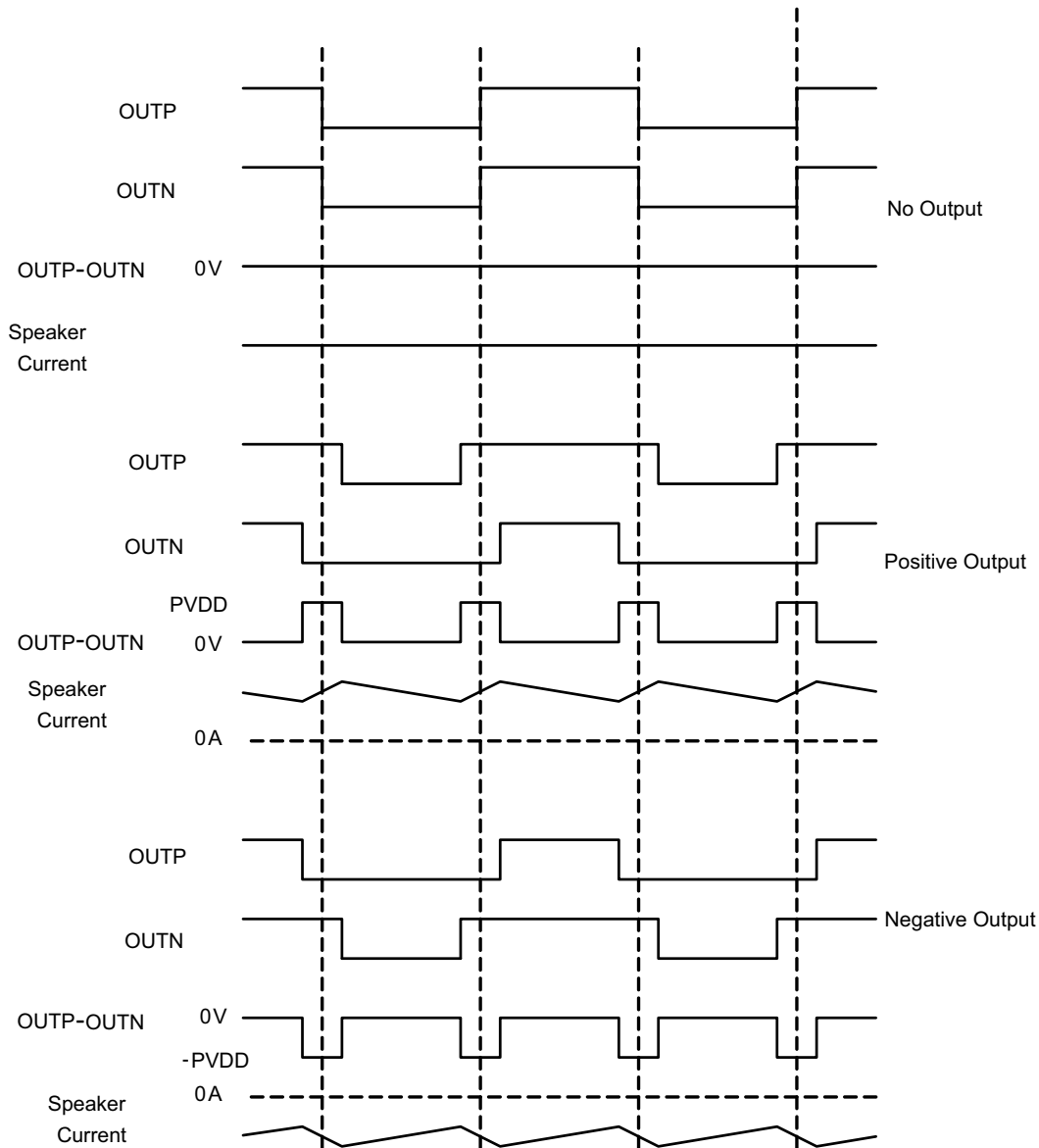


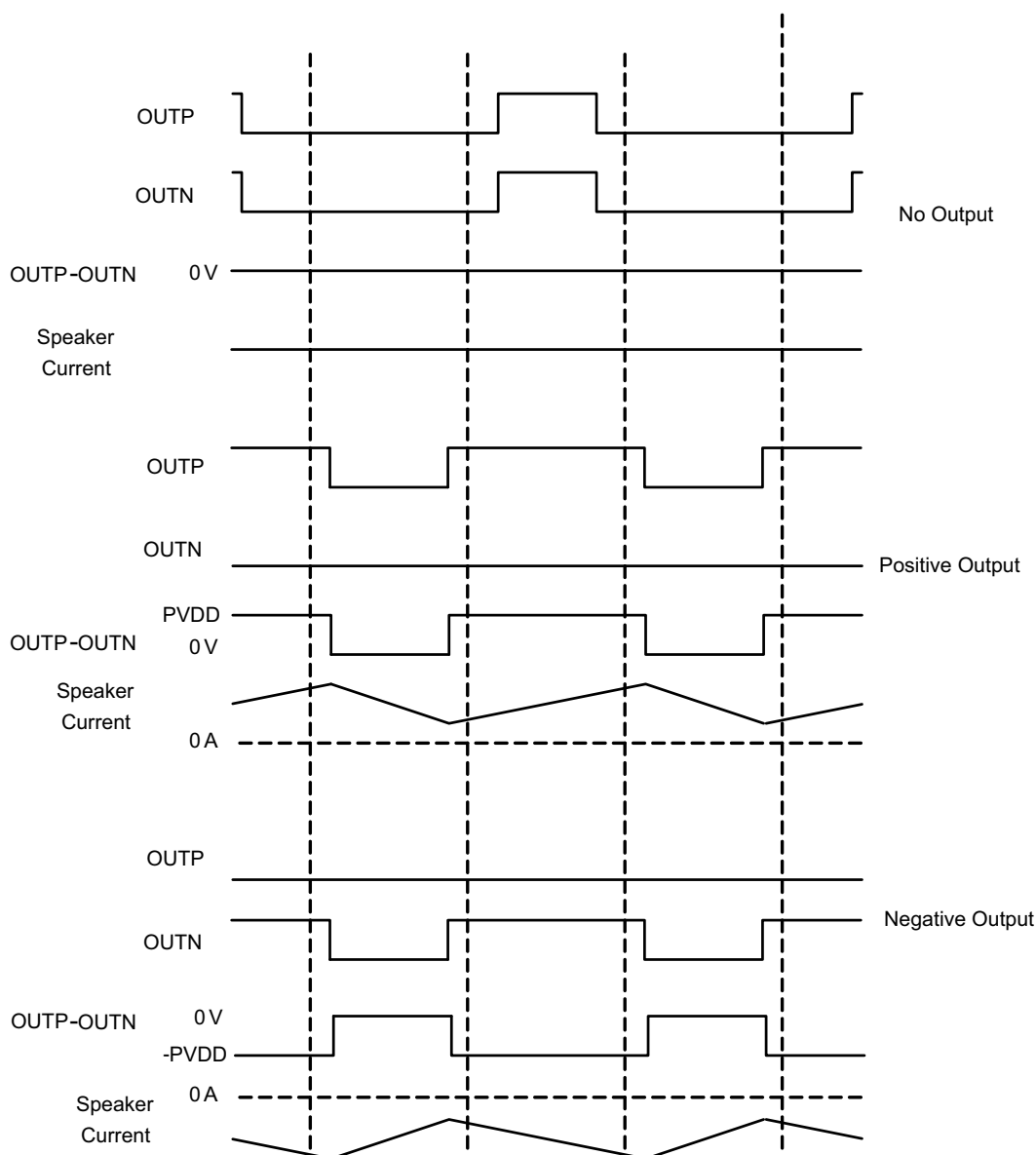
Figure 7-23. BD Modulation

7.3.4.1.2 Advanced 1SPW Modulation

Advanced 1SPW modulation alters the modulation scheme to achieve higher efficiency. In idle or low signal conditions the outputs operate at less than 20% duty cycle, reducing losses to a minimum. When an audio signal is applied, one output of the bridge decreases the duty cycle while the other output side increases. The decreasing output signal rails to GND. At this point, all the audio modulation takes place through the rising output. The result is that only one output is switching during the majority of the audio cycle. Efficiency is improved in this mode due to the reduction of switching losses.

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**Figure 7-24. 1SPW Modulation****7.3.4.1.3 Hybrid Modulation**

Hybrid Modulation is designed for minimized power loss without compromising the high output power performance. With Hybrid modulation, TAS6511-Q1 uses the integrated DSP to detect the input signal level and adjusts the PWM duty cycle as well as other modulation parameters dynamically based on output power. Hybrid modulation achieves ultra low idle current and maintains the excellent audio performance. Unlike 1SPW or BD Modulation, Hybrid Modulation must be activated in the DSP memory before it can be used. The Hybrid modulation configuration is dependent on the selected switching frequency, PVDD supply voltage and output impedance.

7.3.4.2 High-Frequency Pulse-Width Modulator (PWM)

The PWM modulator converts the input audio data into a switched signal of varying duty cycle. The PWM modulator is an advanced design with high bandwidth, low noise, low distortion, and excellent stability.

The output switching frequency is selectable via I²C in the [FSW_CTRL Register \(Address = 0x52\)](#).

The zero frequency resistor of the control loop is recommended to be selected to the corresponding switching frequency using [RZ_CTRL Register \(Address = 0x51\)](#).

If a different PWM output phase is desired, manual phase mode in bit 7 of [PWM_PHASE_CTRL Register \(Address = 0x60\)](#) can be enabled. In manual mode, the output phase can be set in 1.4 degree steps in [RAMP_PHASE_CTRL_GPO Register \(Address = 0x68\)](#).

7.3.4.3 Spread Spectrum Control

TAS6511-Q1 applies spread spectrum control to the modulator's clock signal. Controlling the spectrum of the clock signal translates into an optimized behavior of higher frequency signal components which are visible during EMI testing. Spread spectrum modulation is a PWM modulation technique that reduces the peaks seen in EMI measurements by varying the output PWM frequency, resulting in a wider spectrum but lower level.

The effectiveness of reducing the EMI noise level can be optimized through several configurable parameters:

- Modulation scheme, configured through [SS_CTRL Register \(Address = 0x61\)](#)
 - Triangle
 - Random
 - Triangle + Random
 - Spread Spectrum disabled by turning both schemes off
- Spread spectrum frequency range, configured through [SS_RANGE_CTRL Register \(Address = 0x62\)](#).
- Spread spectrum modulation frequency (F_{SS}), configured through [SS_RANGE_CTRL Register \(Address = 0x62\)](#).

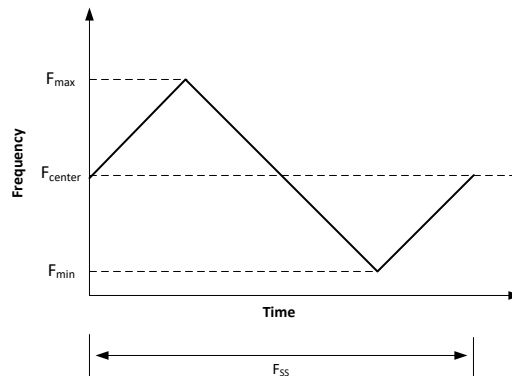


Figure 7-25. Spread-Spectrum Algorithm Diagram

[Table 7-4](#) shows typical spread spectrum configurations. For other PWM frequencies not listed in the table, F_{SS} and modulation depth are slightly different, please find more details in [SS_RANGE_CTRL Register \(Address = 0x62\)](#).

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Table 7-4. Typical Spread Spectrum

FSW_CTRL Register (Address = 0x52) Bit 0-2	SS_CTRL Register (Address = 0x61) Bit 0-2	SS_RANGE_CTRL Register (Address = 0x62)	Spread Spectrum
0b001: 480kHz Fsw	0b010	0x00	Random SS, +0.39% range ⁽¹⁾
		0x10	Random SS, $\pm 0.39\%$ range
		0x20	Random SS, $\pm 1.17\%$ range
		0x30	Random SS, $\pm 2.73\%$ range
		0x40	Random SS, $\pm 5.86\%$ range
		0x50	Random SS, $\pm 12.11\%$ range
	0b001	0x00	Triangle SS, 30 kHz Fss, $\pm 9.5\%$ range
		0x01	Triangle SS, 30 kHz Fss, $\pm 12.5\%$ range
		0x02	Triangle SS, 60 kHz Fss, $\pm 9.5\%$ range
		0x03	Triangle SS, 60 kHz Fss, $\pm 12.5\%$ range
	0b011	0x00	Random SS, +0.39% range + Triangle SS, 30 kHz Fss, $\pm 9.5\%$ range
		0x01	Random SS, $\pm 0.39\%$ range + Triangle SS, 30 kHz Fss, $\pm 12.5\%$ range
		0x10	Random SS, $\pm 1.17\%$ range + Triangle SS, 30 kHz Fss, $\pm 9.5\%$ range
		0x11	Random SS, $\pm 1.17\%$ range + Triangle SS, 30 kHz Fss, $\pm 12.5\%$ range
		
.....	Settings for all other FSW can be found in registers 0x61 and 0x62		
0b011: 2.048MHz Fsw	0b010	0x00	Random SS, +1.67% range
		0x10	Random SS, $\pm 1.67\%$ range
		0x20	Random SS, $\pm 5.00\%$ range
		0x30	Random SS, $\pm 11.67\%$ range
		0x40	Random SS, $\pm 25.00\%$ range
		0x50	Random SS, $\pm 51.67\%$ range
	0b001	0x00	Triangle SS, 128 kHz Fss, $\pm 6.5\%$ range
		0x01	Triangle SS, 128 kHz Fss, $\pm 13.5\%$ range
		0x02	Triangle SS, 170 kHz Fss, $\pm 5\%$ range
		0x03	Triangle SS, 170 kHz Fss, $\pm 10\%$ range
	0b011	0x00	Random SS, +1.67% range + Triangle SS, 128 KHz Fss, $\pm 6.5\%$ range
		0x01	Random SS, $\pm 1.67\%$ range + Triangle SS, 30 kHz Fss, $\pm 13.5\%$ range
		0x10	Random SS, $\pm 5.00\%$ range + Triangle SS, 128 kHz Fss, $\pm 6.5\%$ range
		0x11	Random SS, $\pm 5.00\%$ range + Triangle SS, 30 kHz Fss, $\pm 13.5\%$ range
	0b101	0x08	Random Period Triangle SS 1/Fss to 4/Fss ⁽¹⁾
		

(1) TI recommended spread spectrum configuration

7.3.4.4 Gate Drive

The gate driver accepts the low-voltage PWM signal and level shifts it to drive a high-current, full-bridge, power-FET stage.

The device uses proprietary techniques to optimize EMI and audio performance. The gate driver power supply voltage, GVDD, is internally generated and a decoupling capacitor must be connected at the GVDD_BYP pin.

The full H-bridge output stages use only NMOS transistors. Therefore, bootstrap capacitors are required for the proper operation of the high-side NMOS transistors. A 0.22µF ceramic capacitor of quality X7R or better, rated appropriately for the applied voltages, must be connected from each output to the corresponding bootstrap input. The bootstrap capacitors connected between the BST pins and the corresponding output function as a floating power supply for the high-side N-channel power MOSFET gate drive circuitry. During each high-side switching cycle, the bootstrap capacitors hold the gate-to-source voltage high, keeping the high-side MOSFETs turned on.

7.3.4.5 Power FETs

The BTL output channel comprises four N-channel FETs for high efficiency and maximum power transfer to the load. These FETs are designed to handle the fast switching frequency and large voltage transients during operation within the [Recommended Operating Conditions](#).

7.3.5 Load Diagnostics

The device incorporates both [DC](#) and [AC](#) load diagnostics which are used to determine the status of the load. The DC-diagnostics are turned on by default.

7.3.5.1 DC Load Diagnostics

The DC load diagnostics are used to verify if the load is connected properly.

To support system level start up requirements of a fast time to audio:

- The diagnostics are available as soon as the device leaves the DEEP SLEEP mode and supplies are within the recommended operating range.
- The diagnostics do not rely on external audio input signals or clock and sync frequencies to be available.

DC Diagnostics complete successfully and allow the channel to enter MUTE or PLAY mode if the following tests pass on the output pins:

- No [short to ground](#)
- No [short to power](#)
- No [shorted load](#)
- No [open load](#)

When there is no fault and on completion of the diagnostics routine, the CH1 LDG RESULT bit 3 of [DC_LDГ_RESULT Register \(Address = 0xC2\)](#) is set. If DC load diagnostics identifies a fault, the CH1 LDG RESULT bit 3 in register [DC_LDГ_RESULT Register \(Address = 0xC2\)](#) stays low indicating 'DC Load Diagnostic did not complete without faults on channel 1'. Details of the fault is reported in [DC_LDГ_REPORT Register \(Address = 0xC0\)](#). The channel is retested after approximately 750ms until either the fault has been eliminated or the diagnostics function is turned off by I²C control.

Any of the following conditions start the DC Load Diagnostics:

- [Automatic DC load diagnostics at device initialization](#). Automatically at device initialization, and after the PD pin is pulled low, after transitioning from [DEEP SLEEP state](#) to [SLEEP state](#) and under the condition that all power supplies are within the recommended operating range, the device automatically starts DC load diagnostics. This diagnostic can be aborted, if needed.
- [Automatic DC load diagnostics during Hi-Z or PLAY](#). DC diagnostics can automatically run after the channel fault occurs during HI-Z or PLAY state.
- [Manual start of DC load diagnostics](#). DC diagnostics can be enabled manually to run on the channel.

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7.3.5.1.1 Automatic DC Load Diagnostics at Device Initialization

The TAS6511-Q1 supports automatic and autonomous DC load diagnostics at device start-up. When leaving **DEEP SLEEP state** and under the condition that all power supplies are within the recommended operating range, the device transitions into **SLEEP state** and automatically starts DC load diagnostics. Automatic DC load diagnostics at device initialization can be aborted by setting bit 0 and bit 7 in **DC_LDГ_CTRL Register (Address = 0xB0)** to '1' if desired. Both bits remain in this configuration until the channel transitions into **Hi-Z state** or **PLAY state**. Afterward, the bit values can either remain or the bit values can be restored to the default of '0' through a manual change or when the device resets.

Neither I²C configuration nor any audio signals are necessary for the TAS6511-Q1 to perform short-to-power (S2P), short-to-ground (S2G), open-load (OL), and shorted-load (SL) tests based on default configuration. Systems can benefit from this autonomous operation as running the load diagnostics while bringing up the digital part of the audio chain is possible.

A successful diagnostics without faults sets the respective bit in **DC_LDГ_RESULT Register (Address = 0xC2)** to 1. Once the system is ready to set the channel status to PLAY mode, no further delay is introduced. If a fault is detected during the diagnostics, the channel re-runs the DC load diagnostics after approximately 750ms until either the fault has been eliminated or the LDГ BYPASS bit 1 in **DC_LDГ_CTRL Register (Address = 0xB0)** is set.

If automatic DC load diagnostics with default values is not desired, a GPIO pin configured as a $\overline{\text{STBY}}$ pin can be held low until the device is fully configured via I²C.

7.3.5.1.2 Automatic DC load diagnostics during Hi-Z or PLAY

When a fault occurs while the channel is in Hi-Z or PLAY state, the device places the channel in either **FAULT state** or **Auto Recovery (AUTOREC) state**. After the fault is resolved or cleared, the device runs automatic DC load diagnostics on the channel and recover to the previous **Hi-Z** or **PLAY state** unless a different state was requested through I²C.

This function is enabled by default through the LDГ BYPASS bit 0 in **DC_LDГ_CTRL Register (Address = 0xB0)**.

If DC load diagnostics identifies a fault, the channel CH1 LDГ RESULT bit 3 in **DC_LDГ_RESULT Register (Address = 0xC2)** stays low indicating 'DC Load Diagnostic did not complete without faults on channel 1'. Details of the fault are reported in **DC_LDГ_REPORT Register (Address = 0xC0)**. The channel is retested after approximately 750ms until either the fault has been eliminated or the diagnostics function is turned off by I²C control.

A successful diagnostics without faults, sets the CH1 LDГ RESULT bit 3 to 1.

Note

Automatic DC load diagnostics does not be run if a clock fault is detected

7.3.5.1.3 Manual start of DC load diagnostics

Manual DC load diagnostics can be enabled in any state after all power supplies are within the recommended operating range and after the device has transitioned to **SLEEP state** for the first time. DC diagnostics can be enabled manually by setting the I²C control state register to **LOAD DIAG state** to run on the channel. If either the $\overline{\text{STBY}}$ pin (if configured to a GPIO pin) or a GPIO pin function set the device to **SLEEP** or **DEEP SLEEP state**, manual DC Load diagnostics cannot be run. This doesn't apply when the device is set to **SLEEP** or **DEEP SLEEP state** through I²C control, in which manual DC Load diagnostics are available.

Procedure:

- Make sure all power supplies are within the recommended operating range and device initialization is complete.
- Set channel to **Hi-Z** or **SLEEP** state in bit 4-6 **STATE_CTRL Register (Address = 0x03)**

- Write any desired control parameters for DC load diagnostics in [DC_LDG_CTRL Register \(Address = 0xB0\)](#), [DC_LDG_TIME_CTRL Register \(Address = 0xB2\)](#), [DC_LDG_SL_CTRL Register \(Address = 0xB3\)](#).
- Set audio channel into Diag mode to start DC Diagnostics by setting CH1 STATE CONTROL bit 4-6 in [STATE_CTRL Register \(Address = 0x03\)](#) to '001'.
- If the diagnostics completes without faults, the CH1 LDG RESULT bit in [DC_LDG_RESULT Register \(Address = 0xC2\)](#) is set to 1. Once the system is ready to set the channel status to PLAY mode, no further delay is introduced.
 - If a fault is detected during the diagnostic routine, the fault type can be determined by reading the results stored in [DC_LDG_REPORT Register \(Address = 0xC0\)](#).

7.3.5.1.4 Short-to-Ground

The Short-to-Ground (S2G) tests triggers a fault condition if there is a conductive path from output pin OUT_M or OUT_P of the tested channel to GND with an impedance below that specified in the [Electrical Characteristics](#) section.

7.3.5.1.5 Short-to-Power

The Short-to-Power (S2P) tests triggers a fault condition if there is a conductive path from output pin OUT_M or OUT_P of the tested channel to a power rail with an impedance below that specified in the [Electrical Characteristics](#) section.

7.3.5.1.6 Shorted-Load and Open-Load

The Shorted-Load (SL) test triggers a fault condition if the conductive path between the OUT_M pin and OUT_P pin of the tested channel (i) has an impedance below the threshold set in [DC_LDG_SL_CTRL Register \(Address = 0xB3\)](#). The SL test has a configurable threshold depending on the expected load to be connected.

The Open-Load (OL) test triggers a fault condition if the conductive path between the OUT_M pin and OUT_P pin of the tested channel has an impedance higher than that specified in the [Electrical Characteristics](#) section.

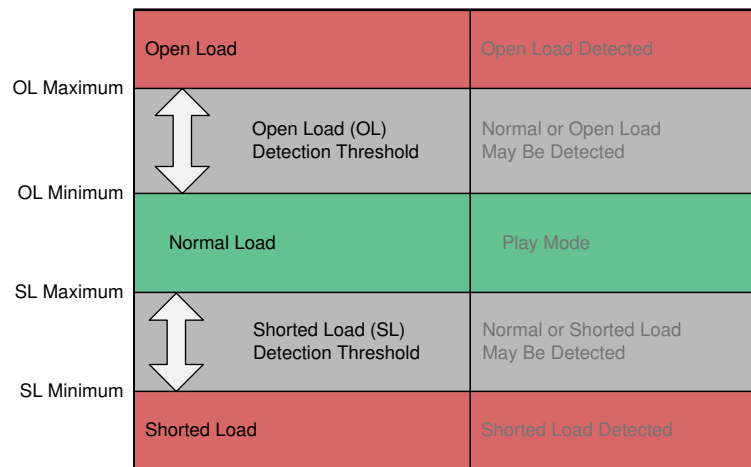


Figure 7-26. DC Load Diagnostic Reporting Thresholds

7.3.5.2 Line Output Diagnostics

The device also includes an optional test to detect a line output load (LO). A line output load is a high-impedance load that is above the open load (OL) threshold such that the DC-load diagnostics report an OL condition. If the line output detection bit is set high, when an OL condition is detected during the DC Diagnostic test, the system will also test if a line output load is present. The [DC_LDG_LO_CTRL Register \(Address = 0xB1\)](#) can be used to configure the channel to be tested for a line output load. If the channel is configured to test for a line output load the channel should be muted.

After the line output diagnostics runs the status is reported in the [DC_LDG_RESULT Register \(Address = 0xC2\)](#).

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7.3.5.3 AC Load Diagnostics

The AC load diagnostic is used to determine the proper connection of a capacitive coupled speaker or tweeter when used with a passive crossover. The AC load diagnostic is controlled through I²C. The TAS6511-Q1 provides a required signal source to determine the AC impedance and reports the tweeter detection result back to I²C registers. The I²C selected test frequency creates a current flow through the desired speaker for proper detection. AC Load Diagnostics can operate without the TDM/I²S clocks being present.

Note

If a fault occurs during AC diagnostics, the AC diagnostics is stopped. AC Diagnostics is not allowed to be performed again until the DC Diagnostics are performed. This is to make sure the fault is not a potential hazard during AC diagnostics.

7.3.5.3.1 Operating Principal

The AC Load Diagnostic circuit of TAS6511-Q1 provides an internally generated stimulus to the load; captures the response of the load; provides real and imaginary parts of the captured complex load impedance; and offers a magnitude estimator and tweeter detection comparator.

7.3.5.3.2 Stimulus

The frequency of the stimulus is set in [AC_LDQ_FREQ_CTRL Register \(Address = 0xB8\)](#). The device drives a low level, 10 mA output current through the load which does not create any significant sound pressure levels from the speaker.

For load impedances below 8 Ω it is recommended to set the AC DIAG GAIN bit to '1' in [AC_LDQ_CTRL Register \(Address = 0xB5\)](#) to increase the reported result resolution.

7.3.5.3.3 Load Impedance

The load impedance as seen by the device is simply the ratio of the voltage across the output pins and the current flowing through the load.

Typically the load has a frequency dependent magnitude and causes current and voltage to have a phase shift. The TAS6511-Q1 internally captures the load impedance as a complex value consisting of a real and imaginary part. Expressing a load impedance in magnitude and phase or in real and imaginary part is mathematically equivalent. Both forms can be transformed into each other without loss of information. After AC load diagnostics have finished, the real and imaginary parts of the complex impedance are available in the [AC_LDQ_REPORT_CH1_R Register \(Address = 0xC3\)](#) and [AC_LDQ_REPORT_CH1_I Register \(Address = 0xC4\)](#).

7.3.5.3.4 Tweeter Detection

In most cases, it is sufficient to use the TAS6511-Q1 built-in magnitude estimator and tweeter detection report to perform the desired tweeter detection test. If a tweeter is properly connected in the system, the magnitude of the load impedance is close to the nominal impedance of the speaker, for example 4 Ω . Once AC load diagnostics finished, the magnitude of the load impedance is calculated and compared against a threshold set in [TWEETER_DETECT_THRESH Register \(Address = 0xB7\)](#). If the measured impedance is lower than the set threshold, the tweeter is detected and marked accordingly in the [TWEETER_REPORT Register \(Address = 0xCB\)](#).

7.3.5.3.5 Operation

To perform AC load diagnostics on TAS6511-Q1:

- Use the State Control Register ([STATE_CTRL Register \(Address = 0x03\)](#)) to put the channel into SLEEP state.
- Start the AC diagnostics by marking the channel in the [AC_LDQ_CTRL Register \(Address = 0xB5\)](#).
- Poll the channel state from [STATE_REPORT Register \(Address = 0x72\)](#). Once CH1 STATUS returns to 'SLEEP' the AC load diagnostics results are ready to be read.

7.3.5.4 DC Resistance Measurement

The TAS6511-Q1 supports a DC Resistance Measurement of the loads connected to each channel that can be read back to the system processor via I²C. To read out the DC resistance of the load connected to each channel, DC load diagnostics must be completed. After DC load diagnostics is completed, registers [DC_LDG_DCR_MSB Register \(Address = 0xC5\)](#) and [DC_LDG_DCR_LSB Register \(Address = 0xC6\)](#) are updated and can be read.

7.3.5.5 Real-Time Load Diagnostics

Real-Time Load Diagnostics (RTLTDG) allows the detection of shorted load (SL), open load (OL), Short-to-Power (S2P) and Short-to-Ground (S2G) conditions during audio operation of the amplifier. To monitor the load impedance while in [PLAY](#) state TAS6511-Q1 uses its integrated current sense to measure the output impedance by channel and compare it with configurable thresholds. An internally generated pilot tone ensures the continuous detection of the output impedance, regardless if an external audio input signal is present. The configurable pilot tone is by default a 6 Hz, -36 dBfs signal.

Prerequisites to run Real-Time Load Diagnostics:

- Sampling frequency of 16 kHz, 32 kHz, 48 kHz or 96 kHz. RTLTDG is not supported at 192 kHz sampling frequency
- [Current Sense](#) is enabled

The detection of SL/OL and S2P/S2G events during RTLTDG can be enabled/disabled individually and if desired, run in parallel. For SL/OL detection the device will compare the measured output impedance at the pilot tone frequency against user-configurable thresholds. S2P/S2G detection is performed by comparing the sensed DC current of OUT_xP and OUT_xM against a user-configurable current threshold.

```

w B0 00 00      / Page switching (first 00) to page 0 (2nd 00)
w B0 7F 00      / Change to book 0
### Enable Current Sense and RTLTDG detection ###
w B0 05 08      / Enable Current Sense
w B0 5B 08      / Enable Current Sense calibration
w B0 4E 0C      / Adjust analog gain ramp down time
w B0 37 08      / Enable RTLTDG OL/SL detection
w B0 38 08      / Enable RTLTDG S2P/S2G detection
### Enable Pilot Tone & Set Threshold ###
w B0 00 00      / Page switching (first 00) to page 0 (2nd 00)
w B0 7F 8C      / Change to book 8C. It's required to be in page 0 before changing a book
w B0 00 22      / Go to page 22 in book 8C
w B0 C8 00 3E BB 7E / Pilot tone ramp down speed
w B0 88 00 10 68 00 / Write to offset 88, 24-bit wide, set Open load threshold e.g. ~14ohm
w B0 8C 00 01 E0 00 / Write to offset 8C, 24-bit wide, set Short load threshold e.g. ~1ohm
w B0 00 00      / Return to page 0 of book 8C
w B0 7F 00      / Return to book 0, page 0

```

Output clipping as well as current limiting events impact the result reporting accuracy and it is recommended to avoid or prevent them during RTLTDG operation. If [Clip Detect](#) is enabled, RTLTDG results will not be updated if Clipping occurs and is detected by the device during an update cycle. The results will be refreshed after the next update cycle without Clipping. Note: To operate Clip Detect and RTLTDG in parallel, the Clip Detect related configuration must be completed before enabling RTLTDG.

Shorted Load and Open Load register flags are reported to [RTLTDG_OL_SL_FAULT_LATCHED Register \(Address = 0x8B\)](#). Short-to-Power and Short-to-Ground register flags are reported to [RTLTDG_S2G_S2P_FAULT_LATCHED Register \(Address = 0x8C\)](#). These signals can optionally be routed directly to I/O pins as either [Fault Events](#) or [Warning Events](#). Refer to [REPORT_ROUTING_5 Register \(Address = 0x94\)](#).

If the channel encounters an SL, OL, S2P or S2G threshold violation the channel will stop switching and move into [FAULT state](#). The CLEAR FAULT bit in [RESET Register \(Address = 0x01\)](#) must be set to '1' before the channel can restart.

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7.3.6 Protection and Monitoring**7.3.6.1 Overcurrent Limit (Cycle-By-Cycle)**

Under normal operation, during high level music playback, it is possible that dynamic load currents can rise beyond the maximum load current, I_{LIM} , of the device. In these cases, the device dynamically limits the current into the load and operation continues without disruption and prevents undesired shutdown for transient music events.

The channel is monitored and limited. For each of the four over current (OC) levels that can be set in [CURRENT_LIMIT_CTRL Register \(Address = 0x55\)](#), there is a corresponding I_{LIM} as shown in the [Electrical Characteristics](#).

If the load current limit is active for at least 25% of a 21.3 ms window, the device generates an [Overcurrent Limit Warning Even](#) for the affected channel.

In case the load current warning event is active continuously for 170.4 ms the device generates an [Overcurrent Limit Fault Event](#) and the channel is placed in the [FAULT State](#). This puts the output stage in high impedance.

Note

If using 1.8V DVDD and driving a 2Ω load with PVDD >16V, Cycle-By-Cycle current limit should be disabled.

7.3.6.2 Overcurrent Shutdown

If the output load current reaches I_{SD} , such as during an output short to GND, then an Overcurrent Shutdown (OCS) event occurs, limiting the peak current and shutting down the affected channel. The time to shutdown the channel varies depending on the severity of the short condition.

The channel is placed into the [FAULT state](#) with the output stage in Hi-Z.

Based on the configuration, a fault signal is generated, which by default generates an active low signal at the [FAULT](#) pin.

The overcurrent limit is programmable to 4 levels and can be set in bit 0-1 of the [CURRENT_LIMIT_CTRL Register \(Address = 0x55\)](#).

7.3.6.3 Current Sense

TAS6511-Q1 can measure the output current of the channel. This functionality is completely integrated and requires no external components.

The channel output current measurement is performed at the rate of the sampling frequency F_s . The measured current amplitude is provided through [SDOUT](#). For more details on the data transmission configuration see [SDOUT](#). Note that the current measurement and the data transmission are two separate functions and both require proper setup before the data can be made available.

The current sense feature is disabled by default and can be enabled in [ISENSE_CTRL Register \(Address = 0x05\)](#).

7.3.6.4 SpeakerGuard Pro Power Limiter

The SpeakerGuard Pro power limiter limits the peak output voltage of the amplifier to prevent speakers from exceeding the specified power rating. If the input signal exceeds the configured peak voltage threshold the Speaker Guard clips the signal at the configured threshold to avoid potentially damaging the speaker. Once the voltage limit is reached the device automatically reduces the gain at the configured attack rate until the signal is within the voltage limit. Once the signal is within the voltage limit the device then releases the gain at the configured release rate. The voltage limit threshold, attack rate, release rate, and max attenuation can be configured in the DSP memory. [Figure 7-27](#) shows the behavior of the Speaker Guard when limiting the output voltage level.

Speaker Guard is disabled by default and can be enabled by setting bit 6 in the [DC_BLOCK_SPEAKER_GUARD_EN Register \(Address = 0x39\)](#).

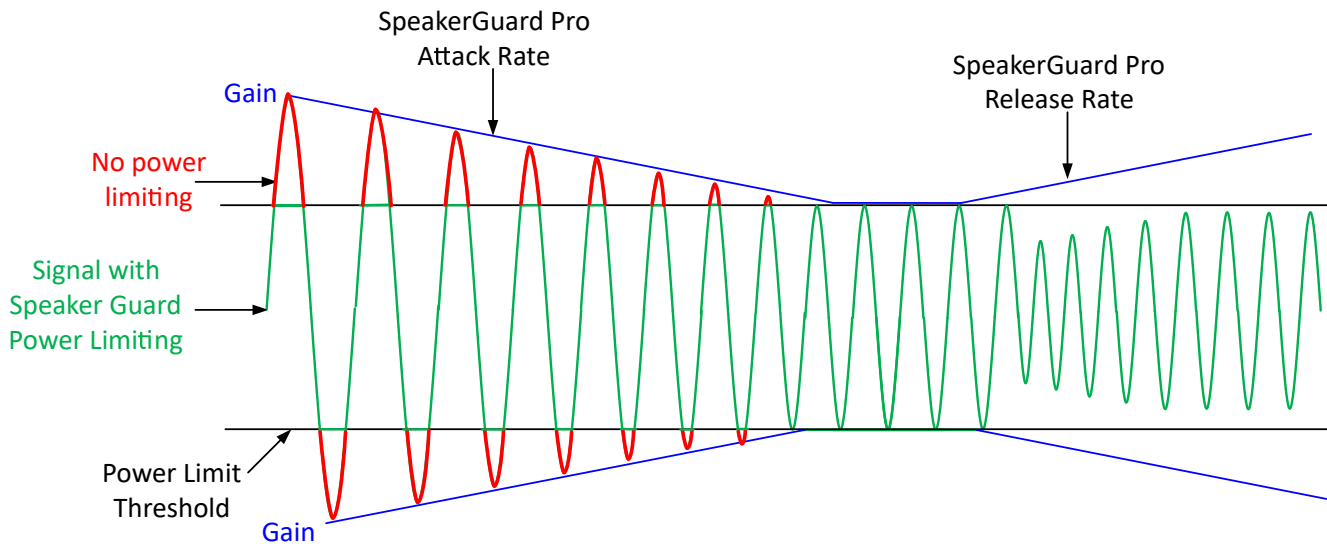


Figure 7-27. SpeakerGuard Pro-Power Limiter Example

7.3.6.5 DC Detect

This circuit measures the DC offset continuously at the output of the amplifier during normal operation. If the DC offset exceeds the DC_{FAULT} threshold, that channel triggers a DC Fault Event and is placed in the **FAULT state** and the output stage is set to high impedance.

Based on the configuration, a fault signal is generated, which by default generates an active low signal at the \overline{FAULT} Pin.

7.3.6.6 Clip Detect

The TAS6511-Q1 supports a configurable clip detection monitor. The DSP monitors the audio signal of the channel and compares the magnitude of the audio signal at the input to the interpolation filters to a configurable threshold.

Clip Detect is disabled default. Clip Detect can be enabled through bit 6 in the [CLIP_DETECT_CTRL Register \(Address = 0x93\)](#)

Report registers:

- Unlatched/Status: [CLIP_WARN_STATUS Register \(Address = 0x83\)](#)
- Latched/Memory: [CLIP_WARN_LATCHED Register \(Address = 0x89\)](#). The latched error report clears on read.

If configured accordingly in [REPORT_ROUTING_5 Register \(Address = 0x94\)](#) bit 1, the Clip Detect status can be routed as a Warning signal.

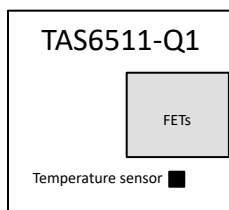
7.3.6.7 Temperature Protection and Monitoring

The device monitors temperature using an integrated temperature sensor to monitor the output stage of the channel. Based on the temperature sensor, warning and fault signals can be generated. A [Thermal Gain Foldback](#) scheme is available that autonomously regulates audio gain and consequently limits die temperature.

The temperature of the temperature sensor is reported through an 8-bit ADC at a sampling rate of 48 kHz to [TEMP_SENSOR Register \(Address = 0x75\)](#) and read through I²C.

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**Figure 7-28. Abstract Temperature Sensor Locations Within the Device****7.3.6.7.1 Overtemperature Shutdown**

The temperature thresholds for OTSD is set to fixed values. Refer to [Electrical Characteristics](#) for the nominal temperature and recovery hysteresis values.

OTSD: If the junction temperature rises above the OTSD threshold, the channel is placed into a protective shutdown state and an [Overtemperature Shutdown \(OTSD\) Event](#) is created.

- If over-temperature auto-recovery is enabled in bit 1 of [OTSD_RECOVERY_EN Register \(Address = 0x8F\)](#), the channel is put into [Auto Recovery \(AUTOREC\) State](#) and recover the state the channel was in before OTSD occurred once the temperature has cooled down below respective threshold and the recovery hysteresis.
- If over-temperature auto-recovery is disabled in bit 1 of [OTSD_RECOVERY_EN Register \(Address = 0x8F\)](#), the channel is put into a [FAULT state](#). The channel only recovers after setting the CLEAR FAULT bit in [RESET Register \(Address = 0x1\)](#). This clears the faults and the channel return to the previous state.

The tolerance of the warning levels and OTSD temperatures track each other.

By default, a fault signal generates an active low signal on the $\overline{\text{FAULT}}$ Pin when an OTSD event occurs.

7.3.6.7.2 Overtemperature Warning

The temperature threshold for Overtemperature Warning (OTW) can be configured to 7 difference levels through bit 0-2 of [OTW_LEVEL Register \(Address = 0x56\)](#).

During operation, if the device heats up and crosses the threshold, a [Overtemperature Warning Event](#) is generated. While the device continues to operate, the OTW information enables higher level software to make decisions to optimize thermal system performance.

As described in the [Overtemperature Warning Event](#), the report can either be polled via I²C register or a hardware signal can be generated by assigning a GPIO Pin for Warning Signals and enabling the OTW report routing.

7.3.6.7.3 Thermal Gain Foldback

Thermal Gain Foldback (TGFB) is a power limiting feature to protect the TAS6511-Q1 from excessive die temperature while maintaining audio output. Thermal foldback is disabled by default and can be enabled in bit 0 of [FOLDBACK_EN Register \(Address = 0x3A\)](#).

The main purpose of foldback power limiting is to keep the output stage within its safe power dissipation limit to avoid unexpected [Overtemperature Shutdown](#). The feature provides a smooth audio response and allows for uninterrupted music playback when temperature limits are crossed. That means the TAS6511-Q1 does not simply shut down, but continues to operate with considerable music output power while avoiding the trigger of OTSD.

The DSP of TAS6511-Q1 monitors the die temperature continuously in real-time for safe operation. The device can warn the host if the die temperature is approaching the [\(OTW\) limits](#). TAS6511-Q1 still functions until the temperature reaches the [OTSD threshold](#), at which the amplifier is shut down.

When the temperature decreases below the foldback level, the attenuation will be held for a configurable number of samples before the attenuation will begin releasing at the gain step rate of 0.1 dB per sample. This release rate of the TGFB can be programmed in the DSP memory.

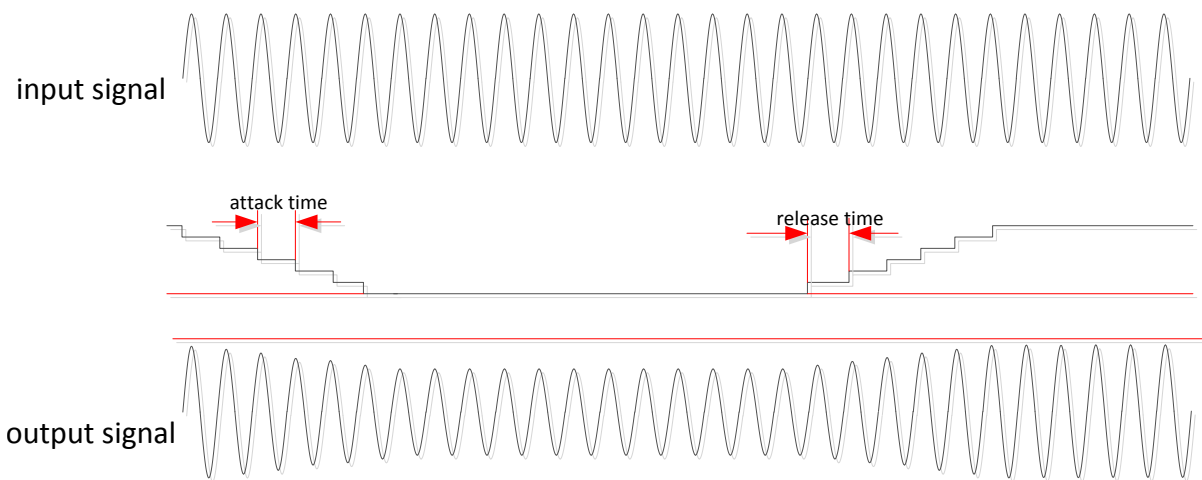


Figure 7-29. Thermal Foldback Attack and Release

7.3.6.8 Power Failures

The PVDD power supply is monitored for undervoltage and overvoltage events as described in the [Power Fault Events](#) section. This automatically engages shutdown and protects the device. PVDD safe operating voltage ranges can be found in the [Recommended Operating Conditions](#) table.

The device will shut down if the DVDD supply falls below V_{POR_OFF} . The DVDD POR fault event is described in the [Power Fault Events](#) section.

7.3.7 Hardware Control Pins

7.3.7.1 \overline{PD} Pin

The \overline{PD} pin is active low. When asserted the device goes into shutdown and the current draw is limited to a minimum. During shut down, all internal blocks are powered off and registers initialize to their default values during the next start-up. I²C is not active.

This pin has a 110 k Ω internal pull-down resistor.

7.3.7.2 GPIO Pins

TAS6511-Q1 offers two configurable GPIO pins. The GPIO pins can be configured as input or outputs. The pins must be configured through I²C before becoming operational after [Device Initialization and Power-On-Reset \(POR\)](#). By default GPIO_1 functions as an input pin and GPIO_2 functions as a FAULT pin. This can be controlled individually for each pin through bit 6-7 of [GPIO_CTRL Register \(Address = 0xA0\)](#).

7.3.7.2.1 \overline{FAULT} Pin

By default a GPIO pin is configured as a \overline{FAULT} pin. The \overline{FAULT} pin reports fault events and is active low under any of the following conditions:

- Overtemperature shutdown (OTSD) - Latching and non-latching
- Overcurrent Limit and Shutdown events - Latching
- DC Detect - Latching

Register bits are available to mask fault categories from reporting to the \overline{FAULT} pin. These bits only mask the setting of the pin and do not affect the register reporting or protection of the device. Additional fault events can be assigned to be reported by the FAULT pin. These include:

- Power Faults - Latching and non-latching
- DC Load Diagnostic faults
- Real-time Load Diagnostic reports - Latching and non-latching
- Clock Errors - Latching and non-latching
- Warning events

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The related configurations are located in [REPORT_ROUTING_2 Register \(Address = 0x90\)](#), [REPORT_ROUTING_4 Register \(Address = 0x92\)](#) and [REPORT_ROUTING_5 Register \(Address = 0x94\)](#).

This pin is an open-drain output with an internal 110 kΩ pull-up resistor to DVDD.

7.3.7.2.2 General Purpose Input

A General Purpose Input (GPI) pin can be configured by assigning a function to the pin through I²C in the related register.

See [Table 7-5](#) for an overview of all available input functions and the associated register in which they can be configured.

For a GPIO pin to operate as input, the relevant register bit in [GPIO_CTRL Register \(Address = 0xA0\)](#) must be set to input configuration.

Table 7-5. General Purpose Input functional overview

Function	Description	Register Name and Address
Hi-Z	The state of the channel is set to Hi-Z state	Bit 0-2 of GPIO_INPUT_SLEEP_HIZ Register (Address = 0x9B)
DEEP SLEEP	The state of the channel is set to DEEP SLEEP state	Bit 4-6 of GPIO_INPUT_SLEEP_HIZ Register (Address = 0x9B)
SLEEP	The state of the channel is set to SLEEP state	Bit 0-2 of GPIO_INPUT_PLAY_SLEEP Register (Address = 0x9C)
PLAY	The state of the channel is set to PLAY state	Bit 4-6 of GPIO_INPUT_PLAY_SLEEP Register (Address = 0x9C)
MUTE	Mutes the device output (active low)	Bit 0-2 of GPIO_INPUT_MUTE Register (Address = 0x9D)
Phase Sync	Input to sync phase with another device (recipient)	Bit 0-2 of GPIO_INPUT_SYNC Register (Address = 0x9E)

7.3.7.2.3 General Purpose Output

A General Purpose Output (GPO) pin can be configured by writing the value of the intended output function to the GPO pin configuration register through I²C. [Table 7-6](#) lists the GPO configuration register address for all GPIO pins.

See [Table 7-7](#) for an overview of all available output functions and the associated register value which determines the selected GPIO function.

In order for a GPIO pin to operate as output, the relevant register bit in [GPIO_CTRL Register \(Address = 0xA0\)](#) must be set to output configuration.

Table 7-6. General Purpose Output Configuration Register

GPIO Pin	GPO Configuration Register
GPIO_1	GPIO1_OUTPUT_SELECT Register (Address = 0x95)
GPIO_2	GPIO2_OUTPUT_SELECT Register (Address = 0x96)

Table 7-7. General Purpose Output Functional Overview

Function	Mode	Description - Match table with regmap	Register value
Low	Output Buffer	Pin continuously drives logic low output	0x00
Auto Mute	Open Drain	Active in response to Auto Mute on channel 1	0x06
SDOUT	Output Buffer	I ² S / TDM data output	0x09
WARN	Open Drain	Active in response to Warning Events	0x0A
FAULT	Open Drain	Active in response to Fault Events	0x0B
Clock Sync	Output Buffer	Output for clock sync with another device (for example, DCDC) as Primary	0x0E
Invalid Clock	Output Buffer	Active in response to a Invalid Clock Fault Event , Clock missing or Clock change	0x0F
High	Output Buffer	Pin continuously drives logic high output.	0x13

Table 7-7. General Purpose Output Functional Overview (continued)

Function	Mode	Description - Match table with regmap	Register value
All register values that are not listed in this table are RESERVED			

GPO pin signals can be inverted by setting the relevant bit in [GPIO_INVERT Register \(Address = 0xA1\)](#) to 1.

7.3.7.2.4 *STBY Pin*

Any of the GPIO pins can be configured to function as an active low $\overline{\text{STBY}}$ pin by configuring a GPIO pin to set the device into DEEP SLEEP state in bit 4-6 of [GPIO_INPUT_SLEEP_HIZ Register \(Address = 0x9B\)](#). When asserted it sets the device into DEEP SLEEP state. In this mode the device has a reduced current while the output pins are placed into a Hi-Z state. All internal analog bias are disabled. In DEEP SLEEP and while DVDD is present, the I²C bus is active and the internal registers are active.

This pin has a 110 kΩ internal pull-down resistor.

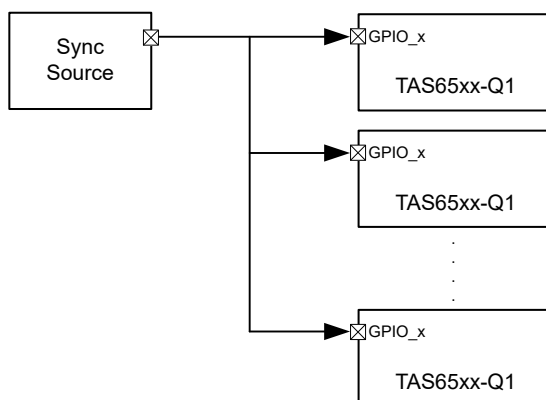
7.3.7.2.5 *Advanced GPIO functions*

7.3.7.2.5.1 *Clock Synchronization*

TAS6511-Q1 supports multiple options for clock synchronization to improve system EMI behavior and control supply peak current conditions.

7.3.7.2.5.1.1 *External SYNC signal (GPIO sync)*

Multiple TAS6511-Q1 synchronize clocks by using an externally provided sync signal.

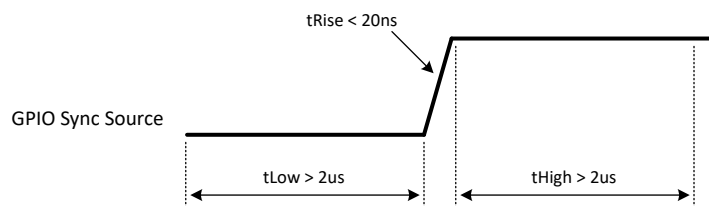
**Figure 7-30. External SYNC signal architecture**

Setup:

- Set one GPIO pin to "Phase Sync" input. The selected GPIO sync pins of all applicable devices should be connected together
- In the [PWM_PHASE_CTRL Register \(Address = 0x60\)](#)
 - Set the PWM PHASE SYNC ENABLE bit 0 to "1" to enable phase sync function
 - Set the PWM PHASE SYNC SELECT bit 1 to "0" to enable GPIO sync
- Select the output phase settings for each device and its respective channels
 - Manual phase mode can optionally be used to select preferable output channel phase offsets across all channels in the systems. More details can be found in [High-Frequency Pulse-Width Modulator \(PWM\)](#)
- Set all channels on each synchronized device to Hi-Z state
- Toggle the GPIO Sync source as shown in the [Figure 7-31](#)
- Set the channel to PLAY state. It can take up to $3F_{sw}$ switching cycles before the devices are switching synchronized.

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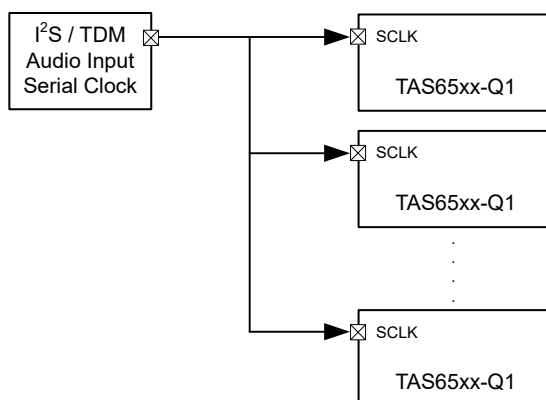
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**Figure 7-31. GPIO Sync source signal****Note**

Spread Spectrum acts synchronized between all TAS6511-Q1 when configured with the same settings on each device.

7.3.7.2.5.1.2 Synchronization through the audio serial clock (SCLK)

Multiple TAS6511-Q1 synchronize their clocks through the Audio Serial Clock (SCLK).

**Figure 7-32. Audio serial clock (SCLK) Synchronization architecture**

Setup:

1. Halt the Audio input Serial clock (SCLK). The I²C communication remains enabled
2. In register [PWM_PHASE_CTRL Register \(Address = 0x60\)](#)
 - a. Set the PWM PHASE SYNC ENABLE bit 0 to "1" to enable phase sync function
 - b. Set the PWM PHASE SYNC SELECT bit 1 to "1" to enable internal sync
3. Select the output phase settings for each device and its respective channels
 - Manual phase mode can optionally be used to select preferable output channel phase offsets across all channels in the systems. More details can be found in [High-Frequency Pulse-Width Modulator \(PWM\)](#)
4. Set all channels on each synchronized device to Hi-Z state
5. Provide the Audio input Serial clock (SCLK) and wait a minimum of 2ms before proceeding to the next step
6. Set each channel to PLAY state

Note

There can be up to 1 SCLK cycle offset between the devices.

Spread Spectrum will act synchronized between all TAS6511-Q1 when configured with the same settings on each device.

7.3.7.2.5.1.3 TAS6511-Q1 as clock source for external devices

This synchronization option allows the TAS6511-Q1 to share its clock with external system components such as a DC-DC regulator. In this mode the device shares its internal ramp clock through the selected GPIO pin. If

Spread Spectrum is enabled, this clock output will be affected and share the spread signal frequency with the connected component. Refer to the technical documentation of the connected system components to ensure correct sequencing for clock synchronization and avoiding unexpected system behavior.

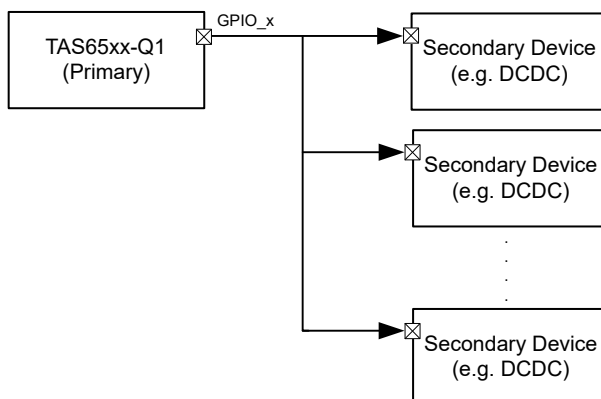


Figure 7-33. Clock source for external devices architecture

Setup:

1. Select a TAS6511-Q1 to operate as Primary Clock. On this device, configure a GPIO pin as “Clock Sync” output. Connect this pin to the clock input of all Clock secondary devices
2. In register [PWM_PHASE_CTRL Register \(Address = 0x60\)](#) set the PWM PHASE SYNC ENABLE bit 0 to “1” to enable phase sync function
 - By default the GPO Clock Sync operates at the selected device output switching frequency. If the sync should occur at a different frequency, a divider can be set before enabling the Clock sync output in [SS_CTRL Register \(Address = 0x61\)](#), bit 6-7
3. The Clock Sync will ramp at a phase offset of 0 degrees in relation to the output channels. A different phase offset can be configured in [RAMP_PHASE_CTRL_GPO Register \(Address = 0x68\)](#). This setting is only available when manual phase mode is enabled in bit 7 of [PWM_PHASE_CTRL Register \(Address = 0x60\)](#)
4. Set the channel on each synchronized device to Hi-Z state
5. Set the channel to PLAY state

Note

If [Spread Spectrum](#) is enabled, it will be reflected on the SYNC signal. This mode cannot be used to synchronize multiple TAS6511-Q1 with each other.

8 Device Functional Modes

8.1 Internal Reporting Signals

To support software driver development, the TAS6511-Q1 allows the flexible configuration of internal fault and warning signals. These signals, where applicable, can be configured based on current device status registers or events stored in memory registers. These signals can be configured and routed to the available GPIO pins for signaling purposes.

8.1.1 Fault Signal

Automotive systems have a high demand on gathering device information in case of unexpected conditions. The registers [REPORT_ROUTING_2 Register \(Address = 0x90\)](#), [REPORT_ROUTING_4 Register \(Address = 0x92\)](#) and [REPORT_ROUTING_5 Register \(Address = 0x94\)](#) of the TAS6511-Q1 allow for a flexible configuration of fault information necessary for higher level system software to effectively control the system.

The Fault Signal can be configured to be active in response to the following [Fault Events](#):

- Power Fault (latched or non-latched)
- Overtemperature Shutdown (latched or non-latched)
- DC Load Diagnostic events
- Overcurrent limiting and shutdown (latched)
- DC Detect (latched)
- Channels entering the FAULT state
- Real-Time Load Diagnostics faults (latched)
- Clock error (latched or non-latched)

The Fault Signal, by default, gets routed to the [FAULT Pin](#) to create a HW signal. The Fault Signal can optionally be routed to an additional [GPIO pin](#).

There are two report bits for Fault signals:

- GLOBAL FAULT ([POWER_FAULT_STATUS Register \(Address = 0x80\)](#), bit 6) - Reports any active fault in device, regardless of fault signal configuration
- FAULT SIGNAL ([OT_FAULT Register \(Address = 0x81\)](#), bit 6) - Reports active fault signals that are configured accordingly in the fault signal configuration registers

8.1.2 Warning Signal

[REPORT_ROUTING_3 Register \(Address = 0x91\)](#), [REPORT_ROUTING_4 Register \(Address = 0x92\)](#), and [REPORT_ROUTING_5 Register \(Address = 0x94\)](#) of the TAS6511-Q1 allow for a flexible configuration of warning information necessary for higher level system software to effectively control the system.

The Warning Signal can be configured to be active in response to the following [Warning Events](#):

- Power Fault (latched or non-latched)
- Overtemperature Shutdown (latched or non-latched)
- Overtemperature Warning (latched or non-latched)
- DC Load Diagnostic events
- Overcurrent limiting (latched or non-latched)
- Clip Detect (latched or non-latched)
- Real-Time Load Diagnostics faults (latched)
- Clock error (latched or non-latched)
- Thermal foldback (latched or non-latched)
- PVDD foldback (latched or non-latched)

The Warning Signal is by default not routed to a pin. TAS6511-Q1 can be configured to route warning signals to [GPIO pins](#) to create a HW signal. Alternatively, all active Warning signals can be routed to the [FAULT pin](#) by setting bit 0 in register [REPORT_ROUTING_4 Register \(Address = 0x92\)](#) to '1'.

- GLOBAL WARNING ([POWER_FAULT_STATUS Register \(Address = 0x80\)](#), bit 7) - Reports any active warning in device, regardless of warning signal configuration with the exception of Clock Fault events.
- WARNING SIGNAL ([OT_FAULT Register \(Address = 0x81\)](#), bit 7) - Reports active warning signals that are configured accordingly in the warning signal configuration registers

8.2 Device States and Flags

8.2.1 Audio Channel States

The audio channel has a set of states that carefully control the set up and shut down procedure of an audio path from source to load. These states are listed in [Table 8-1](#). The current channel states are reported in [STATE_REPORT Register \(Address = 0x72\)](#).

After the $\overline{\text{PD}}$, is pulled high, the states can be selected by setting the CH1 STATE CONTROL bits in the [STATE_CTRL Register \(Address = 0x03\)](#) or by using [GPIO control](#) if a GPIO pins is configured as a [STBY Pin](#).

Table 8-1. Audio Channel States

STATE NAME	OUTPUT FETS	DSP	OSCILLATOR	I ² C
SHUTDOWN	Hi-Z	Stopped	Stopped	High impedance
DEEP SLEEP	Hi-Z	Stopped	Active	Active
LOAD DIAG	Hi-Z	Stopped	Active	Active
SLEEP	Hi-Z	Stopped	Active	Active
HI-Z	Hi-Z	Active	Active	Active
PLAY	Switching with audio	Active	Active	Active
FAULT	Hi-Z	Stopped	Active	Active
AUTOREC	Hi-Z	Stopped	Active	Active

8.2.1.1 SHUTDOWN State

The device remains in shutdown when the $\overline{\text{PD}}$ pin is pulled low. All internal regulators are disabled for minimal power consumption.

Releasing the $\overline{\text{PD}}$ pin starts the device and resets all registers to their default value.

8.2.1.2 DEEP SLEEP State

DEEP SLEEP puts the device in a standby state. In DEEP SLEEP, the I²C communication and registers as well as the 1.5V LDO for the digital core are active. All other regulators remain deactivated to save energy.

This state is an excellent choice to configure the device through I²C before powering up. Unlike SHUTDOWN state, entering or exiting DEEP SLEEP state maintains the register map and DSP memory.

Note

The DSP is deactivated in DEEP SLEEP.

DEEP SLEEP can be controlled through a GPIO pin (if configured to $\overline{\text{STBY}}$) and I²C control in the state control registers. Pin control supersedes I²C control. When the $\overline{\text{STBY}}$ pin is pulled high, the channel needs to enter this state through I²C control in registers [STATE_CTRL Register \(Address = 0x03\)](#) for DEEP SLEEP to take effect.

By default, when leaving [DEEP SLEEP state](#) and under the condition that all power supplies are within the recommended operating range, the device transitions into [SLEEP state](#) and automatically starts DC load diagnostics. This load diagnostic can be bypassed by setting DC LDG BYPASS bit 0 and can be aborted through LDG ABORT bit 7 in [DC_LDG_CTRL Register \(Address = 0xB0\)](#) and transition the device directly to [SLEEP state](#).

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8.2.1.3 LOAD DIAG State

Diagnostic mode engages the DC Diagnostic circuitry to test for Short to Power, Short to Ground, Shorted Load and Open Load without activating the output power stage. These tests must be completed without fault before the Output FETs can be activated. For a more detailed description see [DC Load Diagnostics](#).

The DC diagnostics are available as soon as the device supplies are within the [Recommended Operating Conditions](#). The DC diagnostics do not rely on external audio input signals or clock and sync frequencies to be available. DC Diagnostic results are reported for the channel through the I²C registers [DC LDG Rprt CH1 Register \(Address = 0xC0\)](#).

The channel transitions to [SLEEP state](#) mode after successfully passing the diagnostic tests.

8.2.1.4 SLEEP State

SLEEP state activates further functional blocks in comparison to the DEEP SLEEP state, including the internal LDO for analog circuitry and gate driver. The supply for the Digital-to-PWM conversion remains deactivated.

The channel transitions to [Hi-Z state](#) by setting the State Control register to either Hi-Z or PLAY under the condition that no clock error is present.

8.2.1.5 Hi-Z State

In Hi-Z state the output driver is set to a high impedance state while all other blocks are fully functional.

The channel transitions to [Section 8.2.1.6](#) by setting the State Control register to PLAY.

8.2.1.6 PLAY State

In PLAY state the device is fully operational. The output stages are active, switching and amplify the input signal.

In PLAY state, MUTE can be activated through the MUTE bit in the respective State Control Register ([STATE_CTRL Register \(Address = 0x03\)](#)) or a GPIO pin, if configured accordingly. The transition between MUTE and PLAY is gradual and the volume ramp can be configured in [DIG_VOL_RAMP_CTRL Register \(Address = 0x44\)](#).

[Real-Time Load Diagnostics](#) can be activated to monitor the connected load for shorts or open conditions.

8.2.1.7 FAULT State

FAULT state is a device-internally generated mode that cannot be manually set by the user.

If the channel of the device is in PLAY state and encounter a fault, the device may need to take protective actions and shutdown the audio channel. The output FETs of the affected channel are turned off and the output pins become high impedance. The reported state for the affected channel is 'FAULT'.

Possible reasons for the channel to enter this state are:

- Overcurrent Shutdown
- Load Current fault
- DC fault
- Real-Time Load Diagnostic fault
- Channel over temperature shutdown, if configured to no auto-recovery

The following registers hold all information necessary to identify the reason for the device being in this state:

- [OT_FAULT Register \(Address = 0x81\)](#)
- [CBC_FAULT_WARN_LATCHED Register \(Address = 0x8D\)](#)
- [OC_DC_FAULT_LATCHED Register \(Address = 0x8E\)](#)
- [RTLDCG_OL_SL_FAULT_LATCHED Register \(Address = 0x8B\)](#)
- [RTLDCG_S2G_S2P_FAULT_LATCHED Register \(Address = 0x8C\)](#)

Note

If the channel is in FAULT State, the channel faults only recover after setting the CLEAR FAULT bit 3 in [RESET Register \(Address = 0x01\)](#).

This clears the faults and sets the affected channel into Hi-Z state.

8.2.1.8 Auto Recovery (AUTOREC) State

AUTOREC is a device-internally generated state that cannot be manually set by the user.

If the channel of the device are in PLAY state and encounter a fault, the device needs to take protective actions and shutdown the audio channel. The output FETs of the affected channel are turned off and the output pins become high impedance. Once the cause for the protective shutdown is no longer present, the device auto-recovers and resumes back to PLAY. The reported state for the affected channel is 'AUTOREC'.

Possible reason for the channel to enter this state is:

- Over temperature shutdown if configured to auto-recovery
- Power failures
- Clock Error

The following registers hold all information necessary to identify the reason for the device being in this state:

- [OT_FAULT Register \(Address = 0x81\)](#)
- [POWER_FAULT_STATUS Register \(Address = 0x80\)](#)
- [CLK_FAULT_LATCHED Register \(Address = 0x8A\)](#)

8.2.2 Status and Memory Registers

8.2.2.1 Status Registers

The device reports device states and environmental information by means of status and reporting registers. The following set of registers, at any time, hold the full set of device status: [CH CBC Warn Status Register \(Address = 0x85\)](#)

Register and Address	Status Information
AUTO_MUTE_STATUS Register (Address = 0x71)	Auto Mute
STATE_REPORT Register (Address = 0x72)	Device Channel State Channel 1
POWER_FAULT_STATUS Register (Address = 0x80)	Power Faults, Global Fault, Global Warning
OT_FAULT Register (Address = 0x81)	Overtemperature shutdown, Fault Signal, Warning Signal
OTW_STATUS Register (Address = 0x82)	Temperature (OTW) Warning
CLIP_WARN_STATUS Register (Address = 0x83)	Clip Detect
CBC_WARNING_STATUS Register (Address = 0x85)	Overcurrent Limit Warning
DC_LDG_REPORT Register (Address = 0xC0)	DC Load Diagnostic Report CH1
DC_LDG_RESULT Register (Address = 0xC2)	DC Load Diagnostic Pass
TWEETER_REPORT Register (Address = 0xCB)	AC diagnostic tweeter detect

Interrupt driven signaling to the controlling host device is supported by creation of events. Events can be configured to create [Warning Signal](#) and [Fault Signal](#).

Alternatively software can routinely read this set of registers to gather device status (polling mode).

8.2.2.2 Memory Registers

The device provides a set of memory registers which store latch events. This allows software drivers to properly analyze fault situations.

The following set of memory registers is available:

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Register and Address	Memory Information
POWER_FAULT_LATCHED Register (Address = 0x86)	Power Faults
OTSD_LATCHED Register (Address = 0x87)	Overtemperature shutdown
OTW_LATCHED Register (Address = 0x88)	Temperature (OTW) Warning
CLIP_WARN_LATCHED Register (Address = 0x89)	Clip Detect
CLK_FAULT_LATCHED Register (Address = 0x8A)	Clock Fault
RTLDC_OL_SL_FAULT_LATCHED Register (Address = 0x8B)	RTLDC Open Load and Shorted Load Faults
RTLDC_S2G_S2P_FAULT_LATCHED Register (Address = 0x8C)	RTLDC Short-to Power and Short-to-Ground Faults
CBC_FAULT_WARN_LATCHED Register (Address = 0x8D)	Overcurrent Limit Fault and Warning
OC_DC_FAULT_LATCHED Register (Address = 0x8E)	Overcurrent Shutdown and DC Fault

Note

Memory registers only provide information to the controlling host. Reading the memory register clears the content. The status of the device does not change by reading the memory registers.

8.3 Fault Events**8.3.1 Power Fault Events**

Current status of power fault events is reported in [POWER_FAULT_STATUS Register \(Address = 0x80\)](#) and latched events are reported in [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#).

Power fault events are by default masked from pin reporting. This can be enabled. See [FAULT pin](#) for more details.

8.3.1.1 DVDD Power-On-Reset (POR)

When DVDD falls below V_{POR_OFF} , the device shuts down. The channel is set to SLEEP State, the DSP is disabled and I²C communication terminates. When DVDD rises above V_{POR_SET} or when the device is first powered and DVDD rises above V_{POR_SET} the device initiates a Power-On-Reset routine. During this routine all registers and device states are set to default values.

The intended behavior is that [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#), bit 7 reports "DVDD power on reset event stored" after power up. As DVDD POR is a transient event and is not reported in the Power Fault Status register.

8.3.1.2 DVDD Undervoltage Fault

The DVDD undervoltage (UV) protection detects low voltages on the DVDD pin. In the event of a UV condition, the device moves the channel from PLAY/Hi-Z to [Auto Recovery \(AUTOREC\) state](#), disable the DSP, and update the I²C report registers.

Report registers:

- Unlatched: [POWER_FAULT_STATUS Register \(Address = 0x80\)](#), bit 4
- Latched: [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#), bit 4

Note

[POWER_FAULT_LATCHED Register \(Address = 0x86\)](#), bit 4, can only be read one time while the device remains in the fault state. Once read, the bit is cleared and not reset until the device completes a successful startup and a new DVDD undervoltage condition occurs.

8.3.1.3 PVDD Overvoltage Fault

When the PVDD supply rail rises above nominal range, a PVDD Overvoltage Fault event is created and the device enters into [Auto Recovery \(AUTOREC\) State](#). Once PVDD falls back down into nominal range, the fault event is cleared.

Report registers:

- Unlatched: [POWER_FAULT_STATUS Register \(Address = 0x80\)](#), bit 3
- Latched: [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#), bit 3

8.3.1.4 PVDD Undervoltage Fault

When the PVDD supply rail falls below nominal range, a PVDD Underoltage Fault event is created and the device enters into [Auto Recovery \(AUTOREC\) state](#). Once PVDD rises back up into nominal range, the fault event is cleared.

Report registers:

- Unlatched: [POWER_FAULT_STATUS Register \(Address = 0x80\)](#), bit 1
- Latched: [POWER_FAULT_LATCHED Register \(Address = 0x86\)](#), bit 1

8.3.2 Overtemperature Shutdown (OTSD) Event

Section [Overtemperature Shutdown](#) describes the circumstances under which the device creates an OTSD event as well as the configurable recovery behavior.

Report registers for Overtemperature Shutdown (OTSD) events:

- Unlatched: [OT_FAULT Register \(Address = 0x81\)](#), bit 4
- Latched: [OTSD_LATCHED Register \(Address = 0x87\)](#), bit 4

8.3.3 Overcurrent Limit Fault Event

Section [Overcurrent Limit \(Cycle-By-Cycle\)](#) describes the circumstances under which the device creates an Overcurrent Limit Fault event. This is a transient event that only lasts for a limited time.

Report register:

- Latched: [CBC_FAULT_WARN_LATCHED Register \(Address = 0x8D\)](#), bit 3

8.3.4 Overcurrent Shutdown Event

The [Overcurrent protection](#) section describes the circumstances under which the device creates an OCSD event.

As Overcurrent Shutdown (OCSD) Event is a transient event it is not reported in a status register. The latched OCSD events are reported in Channel Overcurrent and DC Detection Fault Memory Register. The channel is then placed into a [FAULT State](#).

Report register:

- Latched: [OC_DC_FAULT_LATCHED Register \(Address = 0x8E\)](#), bit 7

8.3.5 DC Fault Event

The [DC Detect](#) section describes the circumstances under which the device creates an DC Fault event.

As DC Fault Event is a transient event and is not reported in a status register. The latched DC Fault events are reported in Overcurrent and DC Detection Fault Memory Register. The channel is placed in [FAULT state](#).

Report register:

- Latched: [OC_DC_FAULT_LATCHED Register \(Address = 0x8E\)](#), bit 3

8.3.6 Clock Error Event

The [Clock Rates](#) section describes the supported Audio Data Formats, Bit Depths, and Clock Rates. If these conditions are violated or the clock is halted, the device reports a Clock Error Fault event and the device gracefully transitions to the [AUTOREC state](#). After audio clock recovery, the device automatically returns to the previous state.

As Clock Error Event is a transient event it is not reported in a status register.

Note

Clock error events are detected in Hi-Z and Play Mode

Report register:

- Latched: [CLK_FAULT_LATCHED Register \(Address = 0x8A\)](#), bit 0

8.3.7 Warning Events

8.3.7.1 Overtemperature Warning Event

The [Overtemperature Warning](#) section describes the circumstances under which the device creates a Overtemperature Warning event.

Report registers:

- Unlatched/Status: [OTW_STATUS Register \(Address = 0x82\)](#), bit 4
- Latched/Memory: [OTW_LATCHED Register \(Address = 0x88\)](#), bit 4

8.3.7.2 Overcurrent Limit Warning Event

The [Overcurrent Limit \(Cycle-By-Cycle\)](#) section describes the circumstances under which the device creates an Overcurrent Limit Warning event. This is a transient event that only lasts for a limited time.

Report register:

- Unlatched/Status: [CBC_WARNING_STATUS Register \(Address = 0x85\)](#), bit 7
- Latched/Memory: [CBC_FAULT_WARN_LATCHED Register \(Address = 0x8D\)](#), bit 7

8.3.7.3 Clip Detect Warning Event

The [Clip Detect](#) section describes the circumstances under which the device creates a Clip Detect Warning event.

Report registers:

- Unlatched/Status: [CLIP_WARN_STATUS Register \(Address = 0x83\)](#), bit 3
- Latched/Memory: [CLIP_WARN_LATCHED Register \(Address = 0x89\)](#), bit 3

9 Programming

9.1 I²C Serial Communication Bus

The device communicates with the system processor through the I²C serial communication bus as an I²C target-only device and supports 100-kHz and 400-kHz data transfer rates for random and sequential write and read operation. The processor can poll the device through I²C to determine the operating status, configure settings, or run diagnostics.

The TAS6511-Q1 register map and DSP memory span multiple pages and books. The user should change from page to page before writing individual registers or DSP memory. Changing from page to page is accomplished via register 0 on each page. This register value selects the page address, from 0 to 255. All registers listed in the TAS6511-Q1 Data sheet belong to Page 0.

For a complete list and description of all I²C controls, see the Register Maps section.

9.2 I²C Address Selection

TAS6511-Q1 supports eight I²C addresses, thus up to eight devices can be used together in a system with no additional bus switching hardware.

The pull-up or pull-down resistor connected between the device I2C_ADDR pin and the DVDD-rail (pull-up) or GND (pull-down) determines the I²C address during power up. The I2C address latches after a POR event and is locked until the next POR event.

Table 9-1. I²C Addresses

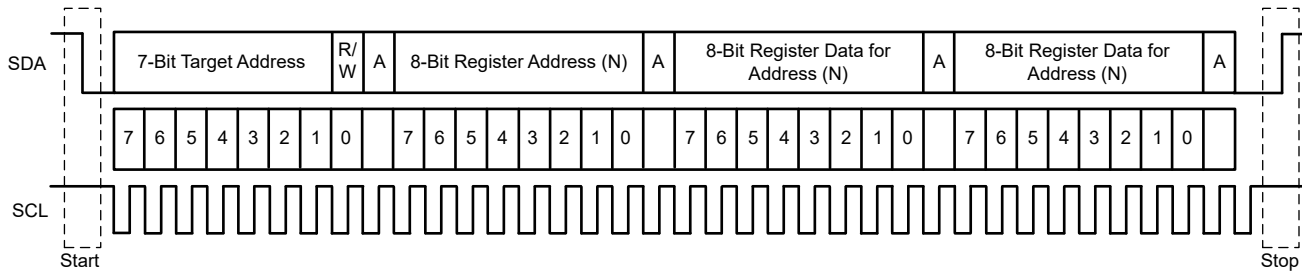
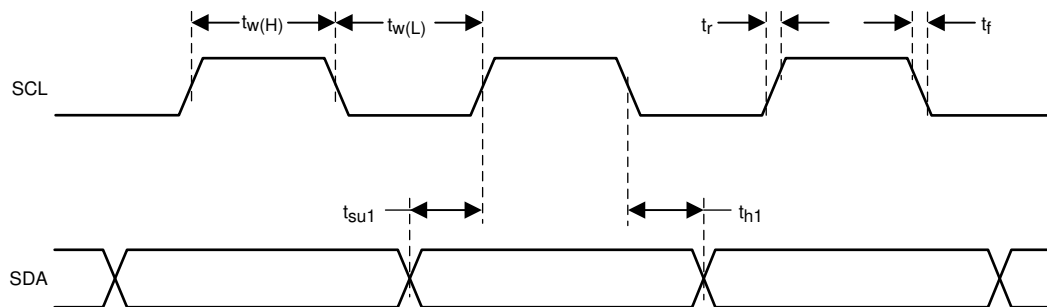
I2C_ADDR Pin Pull-Up resistor	I2C_ADDR Pin Pull-Down resistor	I ² C Write	I ² C Read
-	0	0xB0	0xB1
-	1 kΩ	0xB2	0xB3
-	4.7 kΩ	0xB4	0xB5
-	24 kΩ	0xB6	0xB7
24 kΩ	-	0xB8	0xB9
4.7 kΩ	-	0xBA	0xBB
1 kΩ	-	0xBC	0xBD
0	-	0xBE	0xBF

9.3 I²C Bus Protocol

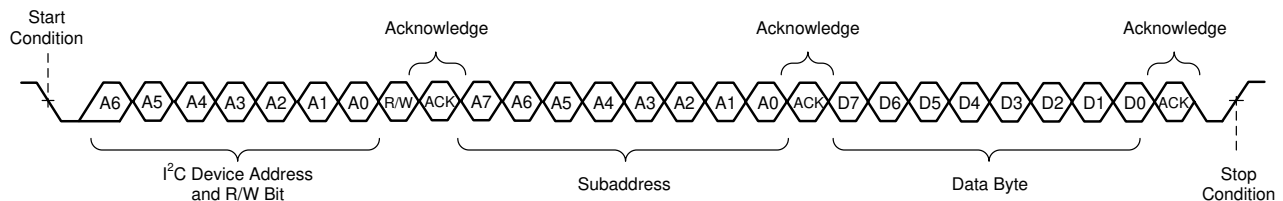
The I²C bus uses two signals, SDA (data) and SCL (clock), to communicate between integrated circuits in a system. Data is transferred on the bus serially, one bit at a time. The address and data are transferred in byte (8-bit) format with the most-significant bit (MSB) transferred first. In addition, each byte transferred on the bus is acknowledged by the receiving device with an acknowledge bit. Each transfer operation begins with the controller device driving a start condition on the bus and ends with the controller device driving a stop condition on the bus. The bus uses transitions on the data terminal (SDA) while the clock is HIGH to indicate a start and stop conditions. A HIGH-to-LOW transition on SDA indicates a start, and a LOW-to-HIGH transition indicates a stop. Normal data bit transitions must occur within the low time of the clock period. The controller generates the 7-bit target address and the read/write (R/W) bit to open communication with another device and then wait for an acknowledge condition. The device holds SDA LOW during the acknowledge-clock period to indicate an acknowledgment. When this occurs, the controller transmits the next byte of the sequence. Each device is addressed by a unique 7-bit target address plus a R/W bit (1 byte). All compatible devices share the same signals via a bidirectional bus using a wired-AND connection. An external pull-up resistor must be used for the SDA and SCL signals to set the HIGH level for the bus. The number of bytes that can be transmitted between start and stop conditions is unlimited. When the last word transfers, the controller generates a stop condition to release the bus.

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**Figure 9-1. Typical I²C Sequence****Figure 9-2. SCL and SDA Timing****9.4 Random Write**

As shown in [Figure 9-3](#), a single-byte data-write transfer begins with the controller device transmitting a start condition, followed by the I²C device address, and then read/write bit. The read/write bit determines the direction of the data transfer. For a write data transfer, the read/write bit is a 0. After receiving the correct I²C device address and the read/write bit, the device responds with an acknowledge bit. Next, the controller transmits the address byte or bytes corresponding to the internal memory address being accessed. After receiving the address byte, the device again responds with an acknowledge bit. Next, the controller device transmits the data byte to be written to the memory address being accessed. After receiving the data byte, the device again responds with an acknowledge bit. Finally, the controller device transmits a stop condition to complete the single-byte data-write transfer.

**Figure 9-3. Random Write Transfer****9.5 Random Read**

As shown in [Figure 9-4](#), a single-byte data-read transfer begins with the controller device transmitting a start condition followed by the I²C device address and the read/write bit. For the data-read transfer, both a write followed by a read are done. Initially, a write is done to transfer the address byte or bytes of the internal memory address to be read. As a result, the read/write bit is a 0. After receiving the address and the read/write bit, the device responds with an acknowledge bit. In addition, after sending the internal memory address byte or bytes, the controller device transmits another start condition followed by the address and the read/write bit again.

This time the read/write bit is a 1, indicating a read transfer. After receiving the address and the read/write bit, the device again responds with an acknowledge bit. Next, the device transmits the data byte from the memory address being read. After receiving the data byte, the controller device transmits a not-acknowledge followed by a stop condition to complete the single-byte data-read transfer.

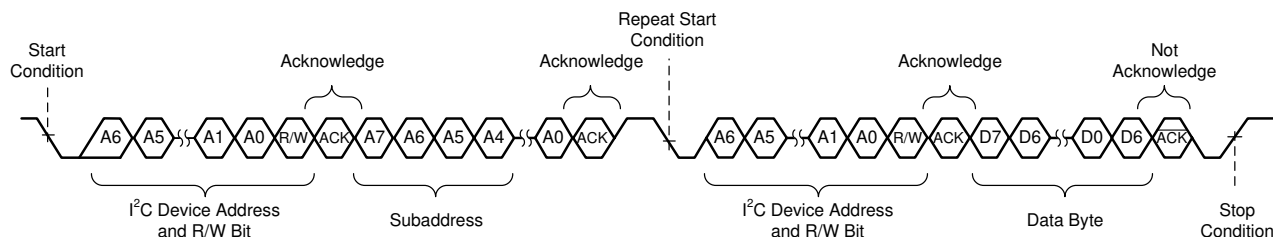


Figure 9-4. Random Read Transfer

9.6 Sequential Read

A sequential data-read transfer is identical to a single-byte data-read transfer except that multiple data bytes are transmitted by the device to the controller device as shown in Figure 9-5. Except for the last data byte, the controller device responds with an acknowledge bit after receiving each data byte and automatically increments the I²C subaddress by one. After receiving the last data byte, the controller device transmits a not-acknowledge followed by a stop condition to complete the transfer.

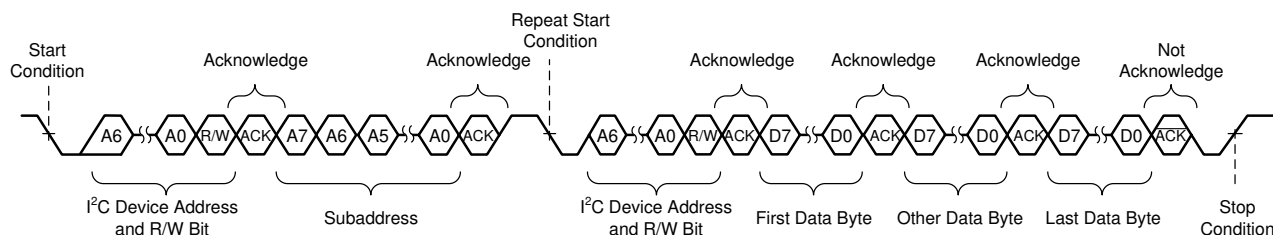


Figure 9-5. Sequential Read Transfer

9.7 DSP Memory Book and Page

The DSP memory is arranged in books, pages, and registers. Each book has several pages and each page has several registers. As the TAS6511-Q1 register map spans several books and pages, the user must select the correct book and page before writing individual register bits or bytes.

To change the book, the user must be on page 0x00. Register 0x7F on page 0x00 is used to change the book. Register 0x00 of each page is used to change the page.

Changing a book: First write 0x00 to register 0x00 to switch to page 0. Afterward, write the desired book number to register 0x7F on page 0.

Changing a page inside a book: Write the desired page number to register 0x00.

24-bit wide registers: When reading or writing 24-bit wide registers in the DSP memory, the sequential read/write is recommended.

Example using 0xB0 as I²C address:

W B0 00 00	/ Page switching (1st 00) to page 0 (2nd 00)
W B0 7F 8C	/ 7F 8C = change to book 8C. It's required to be in page 0 before changing a

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book	
W B0 00 page	/ Go to the desired page in book 8C
W B0 12 00 XX XX XX	/ Sequential write to register/offset 12, 4 x 8 bit
R B0 12 04	/ Sequential read register 0x12-0x15, 4 x 8 bit
W B0 00 00	/ Return to page 0 of book 8C
W B0 7F 00	/ Return to book 0, page 0

10 Register Maps

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10.1 page0 Registers

[Table 10-1](#) lists the memory-mapped registers for the page0 registers. All register offset addresses not listed in [Table 10-1](#) should be considered as reserved locations and the register contents should not be modified.

Table 10-1. PAGE0 Registers

Address	Acronym	Register Name	Section
0x01	RESET	Reset Control	Section 10.1.1
0x02	OUTPUT_CTRL	Output Configuration Control	Section 10.1.2
0x03	STATE_CTRL	State Control	Section 10.1.3
0x05	ISENSE_CTRL	Current Sense Control	Section 10.1.4
0x20	SCLK_INV_CTRL	SCLK Polarity Control	Section 10.1.5
0x21	AUDIO_INTERFACE_CTRL	Audio Interface Control	Section 10.1.6
0x22	I2S_CTRL	I2S Control	Section 10.1.7
0x23	SDIN_CTRL	SDIN Control	Section 10.1.8
0x25	SDOUT_CTRL	SDOUT Control	Section 10.1.9
0x27	SDIN_OFFSET_MSB	SDIN Offset MSB	Section 10.1.10
0x28	SDIN_AUDIO_OFFSET	SDIN Audio Path Offset	Section 10.1.11
0x29	SDIN_LL_OFFSET	SDIN Low Latency Path Offset	Section 10.1.12
0x2C	SDOUT_OFFSET_MSB	SDOUT Offset MSB	Section 10.1.13
0x2D	ISENSE_OFFSET	Current Sense SDOUT Offset	Section 10.1.14
0x2E	VPREDICT_OFFSET	Vpredict SDOUT Offset	Section 10.1.15
0x32	LL_EN	Low Latency Path Enable	Section 10.1.16
0x33	AUDIO_SLOT_SELECT	Audio Path TDM Slot Selection	Section 10.1.17
0x34	LL_SLOT_SELECT	Low Latency Path TDM Slot Selection	Section 10.1.18
0x35	ISENSE_OUTPUT_SLOT	Current Sense TDM Output Slot Selection	Section 10.1.19
0x36	VPREDICT_OUTPUT_SLOT	Vpredict TDM Output Slot Selection	Section 10.1.20
0x37	RTLKG_EN	Real-time Load Diagnostic Open Load/Shorted Load Enable	Section 10.1.21
0x38	RTLKG_S2PG_EN	Real-time Load Diagnostic Short to Power/Ground Enable	Section 10.1.22
0x39	DC_BLOCK_SPEAKER_GUARD_EN	DC Blocking and Speaker Guard Enable	Section 10.1.23
0x3A	FOLDBACK_EN	PVDD and Thermal Foldback Enable	Section 10.1.24
0x3B	PAGE_AUTO_INC	Page Auto Increment	Section 10.1.25
0x40	DIG_VOL_CH1	Channel 1 Digital Volume	Section 10.1.26
0x44	DIG_VOL_RAMP_CTRL	Digital Volume Ramp Control	Section 10.1.27
0x47	AUTO_MUTE_EN	Auto Mute Enable	Section 10.1.28
0x48	AUTO_MUTE_TIMING	Auto Mute Time	Section 10.1.29
0x4A	ANALOG_GAIN	Analog Gain Channel 1	Section 10.1.30
0x4E	ANALOG_GAIN_RAMP_CTRL	Analog Gain Ramp Control	Section 10.1.31
0x51	RZ_CTRL	Zero Frequency Control	Section 10.1.32
0x52	FSW_CTRL	Switching Frequency Control	Section 10.1.33
0x54	CBC_CTRL	CBC Control	Section 10.1.34
0x55	CURRENT_LIMIT_CTRL	Current Limit Control	Section 10.1.35
0x56	OTW_LEVEL	Overttemperature Warning Control	Section 10.1.36
0x5B	SDOUT_DATA	SDOUT Data Selection	Section 10.1.37
0x60	PWM_PHASE_CTRL	PWM Phase Control	Section 10.1.38
0x61	SS_CTRL	Spread Spectrum Control	Section 10.1.39
0x62	SS_RANGE_CTRL	Spread Spectrum Range Control	Section 10.1.40

Table 10-1. PAGE0 Registers (continued)

Address	Acronym	Register Name	Section
0x68	RAMP_PHASE_CTRL_GPO	Switching Clock Phase Control for GPO	Section 10.1.41
0x69	PWM_PHASE_M_CTRL	Switching Clock Phase Control 1	Section 10.1.42
0x71	AUTO_MUTE_STATUS	Auto Mute Status	Section 10.1.43
0x72	STATE_REPORT	Status Channel 1	Section 10.1.44
0x74	PVDD_SENSE	PVDD Voltage Sense	Section 10.1.45
0x75	TEMP_SENSOR	Temperature Readout	Section 10.1.46
0x76	FS_MON	FS Monitor	Section 10.1.47
0x77	SCLK_MON	SCLK Monitor	Section 10.1.48
0x80	POWER_FAULT_STATUS	Power Fault Status	Section 10.1.49
0x81	OT_FAULT	Temperature (OTSD) and Fault Status	Section 10.1.50
0x82	OTW_STATUS	Temperature (OTW) Warning Status	Section 10.1.51
0x83	CLIP_WARN_STATUS	Channel Clip Detect Status	Section 10.1.52
0x85	CBC_WARNING_STATUS	CBC Warning Report	Section 10.1.53
0x86	POWER_FAULT_LATCHED	Power Fault Latched	Section 10.1.54
0x87	OTSD_LATCHED	Temperature (OTSD) Fault Latched	Section 10.1.55
0x88	OTW_LATCHED	Temperature (OTW) Warning Latched	Section 10.1.56
0x89	CLIP_WARN_LATCHED	Channel Clip Detect Warning Memory	Section 10.1.57
0x8A	CLK_FAULT_LATCHED	Clock Error Latched	Section 10.1.58
0x8B	RTLDDG_OL_SL_FAULT_LATCHED	Real-Time Load Diagnostic OL/SL Latched	Section 10.1.59
0x8C	RTLDDG_S2G_S2P_FAULT_LATCHED	Real-Time Load Diagnostic S2G/S2P Latched	Section 10.1.60
0x8D	CBC_FAULT_WARN_LATCHED	Channel Load Current Fault Latched	Section 10.1.61
0x8E	OC_DC_FAULT_LATCHED	Channel Over Current and DC Detection Fault Latched	Section 10.1.62
0x8F	OTSD_RECOVERY_EN	Overttemperature Shutdown Auto-recovery Enable	Section 10.1.63
0x90	REPORT_ROUTING_2	Enable Faults to GPIO	Section 10.1.64
0x91	REPORT_ROUTING_3	Enable Warnings to GPIO	Section 10.1.65
0x92	REPORT_ROUTING_4	Enable Faults and Warnings Reported to GPIO	Section 10.1.66
0x93	CLIP_DETECT_CTRL	Clip Detect Control	Section 10.1.67
0x94	REPORT_ROUTING_5	Enable Faults and Warnings Reported to GPIO	Section 10.1.68
0x95	GPIO1_OUTPUT_SELECT	Select Signals to GPIOs	Section 10.1.69
0x96	GPIO2_OUTPUT_SELECT	Select Signals to GPIOs	Section 10.1.70
0x9B	GPIO_INPUT_SLEEP_HIZ	Select Signals from GPIOs	Section 10.1.71
0x9C	GPIO_INPUT_PLAY_SLEEP	Select Signals from GPIOs	Section 10.1.72
0x9D	GPIO_INPUT_MUTE	Select Signals from GPIOs	Section 10.1.73
0x9E	GPIO_INPUT_SYNC	Select Signals from GPIOs	Section 10.1.74
0xA0	GPIO_CTRL	General GPIO Control	Section 10.1.75
0xA1	GPIO_INVERT	Invert GPIO Signals	Section 10.1.76
0xB0	DC_LD_G_CTRL	DC Load Diagnostics Control	Section 10.1.77
0xB1	DC_LD_G_LO_CTRL	DC Load Diagnostic Line-out Control	Section 10.1.78
0xB2	DC_LD_G_TIME_CTRL	DC Load Diagnostic Timing Control	Section 10.1.79
0xB3	DC_LD_G_SL_CTRL	DC Load Diagnostic Shorted-load Threshold	Section 10.1.80
0xB5	AC_LD_G_CTRL	AC Load Diagnostic Control	Section 10.1.81
0xB6	TWEETER_DETECT_CTRL	Tweeter Detection Control	Section 10.1.82
0xB7	TWEETER_DETECT_THRESH	Tweeter Detection Threshold	Section 10.1.83
0xB8	AC_LD_G_FREQ_CTRL	AC Load Diagnostic Frequency Control	Section 10.1.84

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Table 10-1. PAGE0 Registers (continued)

Address	Acronym	Register Name	Section
0xC0	DC_LDГ_REPORT	DC Load Diagnostic Report	Section 10.1.85
0xC2	DC_LDГ_RESULT	DC Load Diagnostic Result Report	Section 10.1.86
0xC3	AC_LDГ_REPORT_CH1_R	AC Load Diagnostic Report Real Channel 1	Section 10.1.87
0xC4	AC_LDГ_REPORT_CH1_I	AC Load Diagnostic Report Imaginary Channel 1	Section 10.1.88
0xC5	DC_LDГ_DCR_MSB	DC Diagnostic DC Resistance Measurement MSB	Section 10.1.89
0xC6	DC_LDГ_DCR_LSB	DC Diagnostic DC Resistance Measurement LSB	Section 10.1.90
0xCB	TWEETER_REPORT	Tweeter Detection Report	Section 10.1.91
0xD1	CH1_RTLDГ_IMP_MSB	Real-time Load Diagnostic Channel 1 Impedance MSB	Section 10.1.92
0xD2	CH1_RTLDГ_IMP_LSB	Real-time Load Diagnostic Channel 1 Impedance LSB	Section 10.1.93

Complex bit access types are encoded to fit into small table cells. [Table 10-2](#) shows the codes that are used for access types in this section.

Table 10-2. page0 Access Type Codes

Access Type	Code	Description
Read Type		
R	R	Read
Write Type		
W	W	Write
Reset or Default Value		
-n		Value after reset or the default value

10.1.1 RESET Register (Address = 0x01) [Reset = 0x00]

RESET is shown in [Figure 10-1](#) and described in [Table 10-3](#).

Return to the [Summary Table](#).

Reset Control

Figure 10-1. RESET Register

7	6	5	4	3	2	1	0
RESERVED			DEVICE RESET	CLEAR FAULT	RESERVED	RESERVED	REGISTER RESET
W-0x0			W-0x0	W-0x0	W-0x0	W-0x0	W-0x0

Table 10-3. RESET Register Field Descriptions

Bit	Field	Type	Reset	Description
7-5	RESERVED	W	0x0	
4	DEVICE RESET	W	0x0	This bit will auto clear. 0: Normal operation 1: Device will be reset
3	CLEAR FAULT	W	0x0	This bit will auto clear. 0: Normal operation 1: Clear analog fault, not including load diagnostic fault
2	RESERVED	W	0x0	Reserved
1	RESERVED	W	0x0	Reserved
0	REGISTER RESET	W	0x0	This bit will auto clear. This bit resets the mode registers back to their initial values. This bit must be set only when the device is in SLEEP or DEEP SLEEP mode. 0: Normal operation 1: Reset mode registers

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10.1.2 OUTPUT_CTRL Register (Address = 0x02) [Reset = 0x00]OUTPUT_CTRL is shown in [Figure 10-2](#) and described in [Table 10-4](#).Return to the [Summary Table](#).

Output Configuration Control

Figure 10-2. OUTPUT_CTRL Register

7	6	5	4	3	2	1	0
CH1 LO MODE	RESERVED					MODULATION CTRL	
R/W-0x0	R/W-0x0					R/W-0x0	

Table 10-4. OUTPUT_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 LO MODE	R/W	0x0	0: Channel 1 is in normal / speaker mode 1: Channel 1 is in line output mode
6-2	RESERVED	R/W	0x0	
1-0	MODULATION CTRL	R/W	0x0	00: BD mode 01: 1SPW mode 10: Hybrid mode

10.1.3 STATE_CTRL Register (Address = 0x03) [Reset = 0x20]

STATE_CTRL is shown in [Figure 10-3](#) and described in [Table 10-5](#).

Return to the [Summary Table](#).

State Control

Figure 10-3. STATE_CTRL Register

7	6	5	4	3	2	1	0
CH1 MUTE	CH1 STATE CTRL			RESERVED			
R/W-0x0	R/W-0x2			R/W-0x0			

Table 10-5. STATE_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 MUTE	R/W	0x0	Mute Channel 1 This bit issues soft mute request for channel 1. The volume will be smoothly ramped down/up to avoid pop/click noise. 0: Normal volume 1: Mute
6-4	CH1 STATE CTRL	R/W	0x2	Channel 1 State Control 000: DEEP SLEEP 001: LOAD DIAG 010: SLEEP 011: HI-Z 100: PLAY
3-0	RESERVED	R/W	0x0	

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10.1.4 ISENSE_CTRL Register (Address = 0x05) [Reset = 0x00]ISENSE_CTRL is shown in [Figure 10-4](#) and described in [Table 10-6](#).Return to the [Summary Table](#).

Current Sense Control

Figure 10-4. ISENSE_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				CH1 ISENSE ENABLE	RESERVED		
R/W-0x0				R/W-0x0	R/W-0x0		

Table 10-6. ISENSE_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3	CH1 ISENSE ENABLE	R/W	0x0	0: Disable Current Sense Channel 1 1: Enable Current Sense Channel 1
2-0	RESERVED	R/W	0x0	

10.1.5 SCLK_INV_CTRL Register (Address = 0x20) [Reset = 0x00]

SCLK_INV_CTRL is shown in [Figure 10-5](#) and described in [Table 10-7](#).

Return to the [Summary Table](#).

SCLK Polarity Control

Figure 10-5. SCLK_INV_CTRL Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED	SCLK INV TX	SCLK INV	RESERVED	RESERVED	RESERVED	RESERVED
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-7. SCLK_INV_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6	RESERVED	R/W	0x0	Reserved
5	SCLK INV TX	R/W	0x0	SCLK Polarity This bit sets the Inverted SCLK mode. In inverted SCLK mode, the DAC assumes that the FSYNC and DIN edges are aligned to the rising edge of the SCLK. In Normal SCLK mode, the FSYNC and DIN edges are assumed to be aligned to the falling edge of the SCLK. 0: Normal SCLK mode 1: Inverted SCLK mode
4	SCLK INV	R/W	0x0	SCLK Polarity This bit sets the inverted SCLK mode. In inverted SCLK mode, the DAC assumes that the FSYNC and DIN edges are aligned to the rising edge of the SCLK. Normally they are assumed to be aligned to the falling edge of the SCLK. 0: Normal SCLK mode 1: Inverted SCLK mode
3-2	RESERVED	R/W	0x0	
1	RESERVED	R/W	0x0	Reserved
0	RESERVED	R/W	0x0	Reserved

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10.1.6 AUDIO_INTERFACE_CTRL Register (Address = 0x21) [Reset = 0x00]AUDIO_INTERFACE_CTRL is shown in [Figure 10-6](#) and described in [Table 10-8](#).Return to the [Summary Table](#).

Audio Interface Control

Figure 10-6. AUDIO_INTERFACE_CTRL Register

7	6	5	4	3	2	1	0
LAST SAMPLE HOLD	RESERVED	RESERVED	RESERVED	ASI FORMAT		FS PULSE WIDTH	
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0		R/W-0x0	

Table 10-8. AUDIO_INTERFACE_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	LAST SAMPLE HOLD	R/W	0x0	Disable Last Sample Hold This bit controls whether to hold the last sample at audio interface in the event of clock error. The last known good sample is held to prevent erroneous samples to flow through the DAC. 0: Enable last sample hold 1: Disable last sample hold
6	RESERVED	R/W	0x0	Reserved
5	RESERVED	R/W	0x0	
4	RESERVED	R/W	0x0	Reserved
3-2	ASI FORMAT	R/W	0x0	Data Format These bits control both input and output audio interface formats for DAC operation. 00: I2S 01: TDM/DSP 10: RTJ 11: LTJ
1-0	FS PULSE WIDTH	R/W	0x0	FSYNC pulse < 8 x SCLK 00: High width of FSYNC in TDM/DSP mode is equal or greater than 8 cycles of SCLK 01: High width of FSYNC in TDM/DSP mode is less than 8 cycles of SCLK 10 / 11: Reserved

10.1.7 I2S_CTRL Register (Address = 0x22) [Reset = 0x50]

I2S_CTRL is shown in [Figure 10-7](#) and described in [Table 10-9](#).

Return to the [Summary Table](#).

I2S Control

Figure 10-7. I2S_CTRL Register

7	6	5	4	3	2	1	0
AUDIO I2S		LOW LATENCY I2S		RESERVED			
R/W-0x1		R/W-0x1		R/W-0x0			

Table 10-9. I2S_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	AUDIO I2S	R/W	0x1	I2S Audio Left/Right Data Selection Select left or right I2S data for the Audio path. 00: Zero data (mute) 01: Left channel data 10: Right channel data 11: Reserved
5-4	LOW LATENCY I2S	R/W	0x1	I2S Low Latency Left/Right Data Selection Select left or right I2S data for the Low Latency path. 00: Zero data (mute) 01: Right channel data 10: Left channel data 11: Reserved
3-0	RESERVED	R/W	0x0	

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10.1.8 SDIN_CTRL Register (Address = 0x23) [Reset = 0x08]SDIN_CTRL is shown in [Figure 10-8](#) and described in [Table 10-10](#).Return to the [Summary Table](#).

SDIN Control

Figure 10-8. SDIN_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				SDIN WL SELECT		RESERVED	
R/W-0x0				R/W-0x2		R/W-0x0	

Table 10-10. SDIN_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-2	SDIN WL SELECT	R/W	0x2	In non-TDM mode, these bits are used to control input Channel 1. In TDM mode, these bits are used to control the word length of input for both audio and low latency path channels. 00: 16 bits 01: 20 bits 10: 24 bits 11: 32 bits
1-0	RESERVED	R/W	0x0	

10.1.9 SDOUT_CTRL Register (Address = 0x25) [Reset = 0x08]

SDOUT_CTRL is shown in [Figure 10-9](#) and described in [Table 10-11](#).

Return to the [Summary Table](#).

SDOUT Control

Figure 10-9. SDOUT_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				SDOUT WL SELECT		RESERVED	
R/W-0x0				R/W-0x2		R/W-0x0	

Table 10-11. SDOUT_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-2	SDOUT WL SELECT	R/W	0x2	I2S Word Length These bits control output audio interface sample word lengths for isense and vpredict output channels. 00: 16 bits 01: 20 bits 10: 24 bits 11: 32 bits
1-0	RESERVED	R/W	0x0	

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10.1.10 SDIN_OFFSET_MSB Register (Address = 0x27) [Reset = 0x00]SDIN_OFFSET_MSB is shown in [Figure 10-10](#) and described in [Table 10-12](#).Return to the [Summary Table](#).

SDIN Offset MSB

Figure 10-10. SDIN_OFFSET_MSB Register

7	6	5	4	3	2	1	0
AUDIO PATH OFFSET MSB		LL PATH OFFSET MSB		RESERVED			
R/W-0x0		R/W-0x0		R/W-0x0			

Table 10-12. SDIN_OFFSET_MSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	AUDIO PATH OFFSET MSB	R/W	0x0	MSB for Audio Path Offset, refer to SDIN_AUDIO_OFFSET (0x28)
5-4	LL PATH OFFSET MSB	R/W	0x0	MSB for Low Latency Path Offset, refer to SDIN_LL_OFFSET (0x29)
3-0	RESERVED	R/W	0x0	

10.1.11 SDIN_AUDIO_OFFSET Register (Address = 0x28) [Reset = 0x00]

SDIN_AUDIO_OFFSET is shown in [Figure 10-11](#) and described in [Table 10-13](#).

Return to the [Summary Table](#).

SDIN Audio Path Offset

Figure 10-11. SDIN_AUDIO_OFFSET Register

7	6	5	4	3	2	1	0
AUDIO PATH OFFSET LSB							
R/W-0x0							

Table 10-13. SDIN_AUDIO_OFFSET Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	AUDIO PATH OFFSET LSB	R/W	0x0	Used with AUDIO PATH OFFSET MSB in SDIN OFFSET MSB register (0x27), for a total of 10 bits. Selects the offset of whole Audio Path between 0 SCLK to 511 SCLK. 0000000000: offset = 0 SCLK (no offset) 0000000001: offset = 1 SCLK 0000000010: offset = 2 SCLKs ... 0111111111: offset = 511 SCLKs 1000000000 - 1111111111: Reserved

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10.1.12 SDIN_LL_OFFSET Register (Address = 0x29) [Reset = 0x00]SDIN_LL_OFFSET is shown in [Figure 10-12](#) and described in [Table 10-14](#).Return to the [Summary Table](#).

SDIN Low Latency Path Offset

Figure 10-12. SDIN_LL_OFFSET Register

7	6	5	4	3	2	1	0
LOW LATENCY PATH OFFSET LSB							
R/W-0x0							

Table 10-14. SDIN_LL_OFFSET Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	LOW LATENCY PATH OFFSET LSB	R/W	0x0	Used with LL PATH OFFSET MSB in SDIN Offset MSB register (0x27), for a total of 10 bits. Selects the offset of whole Low Latency Path between 0 SCLK to 511 SCLK. 0000000000: offset = 0 SCLK (no offset) 0000000001: offset = 1 SCLK 0000000010: offset = 2 SCLKs ... 0111111111: offset = 511 SCLKs

10.1.13 SDOUT_OFFSET_MSB Register (Address = 0x2C) [Reset = 0x00]

SDOUT_OFFSET_MSB is shown in [Figure 10-13](#) and described in [Table 10-15](#).

Return to the [Summary Table](#).

SDOUT Offset MSB

Figure 10-13. SDOUT_OFFSET_MSB Register

7	6	5	4	3	2	1	0
ISENSE OFFSET MSB		VPREDICT OFFSET MSB		RESERVED			
R/W-0x0		R/W-0x0		R/W-0x0			

Table 10-15. SDOUT_OFFSET_MSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	ISENSE OFFSET MSB	R/W	0x0	MSB for Current Sense data offset, refer to ISENSE_OFFSET register (0x2D)
5-4	VPREDICT OFFSET MSB	R/W	0x0	MSB for Vpredict data offset, refer to VPREDICT_OFFSET register (0x2E)
3-0	RESERVED	R/W	0x0	

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10.1.14 ISENSE_OFFSET Register (Address = 0x2D) [Reset = 0x00]ISENSE_OFFSET is shown in [Figure 10-14](#) and described in [Table 10-16](#).Return to the [Summary Table](#).

Current Sense SDOUT Offset

Figure 10-14. ISENSE_OFFSET Register

7	6	5	4	3	2	1	0
ISENSE_OFFSET LSB							
R/W-0x0							

Table 10-16. ISENSE_OFFSET Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	ISENSE_OFFSET LSB	R/W	0x0	Used with ISENSE_OFFSET_MSB in SDOUT_OFFSET_MSB register (0x2C), for a total of 10 bits. Defines the offset of Current Sense data between 0 SCLK to 511 SCLKs. 0000000000: offset = 0 SCLK 0000000001: offset = 1 SCLK 0000000010: offset = 2 SCLKs ... 0111111111: offset = 511 SCLKs

10.1.15 VPREDICT_OFFSET Register (Address = 0x2E) [Reset = 0x00]

VPREDICT_OFFSET is shown in [Figure 10-15](#) and described in [Table 10-17](#).

Return to the [Summary Table](#).

Vpredict SDOUT Offset

Figure 10-15. VPREDICT_OFFSET Register

7	6	5	4	3	2	1	0
VPREDICT OFFSET LSB							
R/W-0x0							

Table 10-17. VPREDICT_OFFSET Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	VPREDICT OFFSET LSB	R/W	0x0	Used with VPREDICT OFFSET MSB in SDOUT_OFFSET_MSB register (0x2C), for a total of 10 bits. Defines the offset of Vpredict data between 0 SCLK to 511 SCLKs. 0000000000: offset = 0 SCLK 0000000001: offset = 1 SCLK 0000000010: offset = 2 SCLKs ... 0111111111: offset = 511 SCLKs

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10.1.16 LL_EN Register (Address = 0x32) [Reset = 0x00]

LL_EN is shown in [Figure 10-16](#) and described in [Table 10-18](#).

Return to the [Summary Table](#).

Low Latency Path Enable

Figure 10-16. LL_EN Register

7	6	5	4	3	2	1	0
RESERVED						FLLP ENABLE	LLP ENABLE
R/W-0x0						R/W-0x0	R/W-0x0

Table 10-18. LL_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-2	RESERVED	R/W	0x0	
1	FLLP ENABLE	R/W	0x0	0: Disable Full Feature Low Latency path 1: Enable Full Feature Low Latency path
0	LLP ENABLE	R/W	0x0	0: Disable Low latency path 1: Enable Low latency path

10.1.17 AUDIO_SLOT_SELECT Register (Address = 0x33) [Reset = 0x00]

AUDIO_SLOT_SELECT is shown in [Figure 10-17](#) and described in [Table 10-19](#).

Return to the [Summary Table](#).

Audio Path TDM Slot Selection

Figure 10-17. AUDIO_SLOT_SELECT Register

7	6	5	4	3	2	1	0
RESERVED				AUDIO PATH SLOT SELECT			
R/W-0x0				R/W-0x0			

Table 10-19. AUDIO_SLOT_SELECT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-0	AUDIO PATH SLOT SELECT	R/W	0x0	<p>TDM Slot selection</p> <p>These bits control the offset of audio data in the audio frame for input. The offset is defined as the number of TDM time slots. AUDIO PATH SLOT SELECT controls the time slot assigned to audio path.</p> <p>0000: Slot 1 0001: Slot 2 0010: Slot 3 ... 1111: Slot 16</p>

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10.1.18 LL_SLOT_SELECT Register (Address = 0x34) [Reset = 0x00]LL_SLOT_SELECT is shown in [Figure 10-18](#) and described in [Table 10-20](#).Return to the [Summary Table](#).

Low Latency Path TDM Slot Selection

Figure 10-18. LL_SLOT_SELECT Register

7	6	5	4	3	2	1	0
RESERVED				LL PATH SLOT SELECT			
R/W-0x0				R/W-0x0			

Table 10-20. LL_SLOT_SELECT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-0	LL PATH SLOT SELECT	R/W	0x0	TDM Slot selection These bits control the offset of audio data in the audio frame for input. The offset is defined as the number of TDM time slots. LL PATH SLOT SELECT controls the time slot assigned to low latency audio path. 0000: Slot 1 0001: Slot 2 0010: Slot 3 ... 1111: Slot 16

10.1.19 ISENSE_OUTPUT_SLOT Register (Address = 0x35) [Reset = 0x00]

ISENSE_OUTPUT_SLOT is shown in [Figure 10-19](#) and described in [Table 10-21](#).

Return to the [Summary Table](#).

Current Sense TDM Output Slot Selection

Figure 10-19. ISENSE_OUTPUT_SLOT Register

7	6	5	4	3	2	1	0
RESERVED				ISENSE SLOT SELECT			
R/W-0x0				R/W-0x0			

Table 10-21. ISENSE_OUTPUT_SLOT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-0	ISENSE SLOT SELECT	R/W	0x0	<p>TDM Slot selection</p> <p>These bits control the offset of audio data in the audio frame for output. The offset is defined as the number of TDM time slots. ISENSE SLOT SELECT controls the time slot of current sense output data path.</p> <p>0000: Slot 1 0001: Slot 2 0010: Slot 3 ... 1111: Slot 16</p>

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10.1.20 VPREDICT_OUTPUT_SLOT Register (Address = 0x36) [Reset = 0x00]VPREDICT_OUTPUT_SLOT is shown in [Figure 10-20](#) and described in [Table 10-22](#).Return to the [Summary Table](#).

Vpredict TDM Output Slot Selection

Figure 10-20. VPREDICT_OUTPUT_SLOT Register

7	6	5	4	3	2	1	0
RESERVED				VPREDICT SLOT SELECT			
R/W-0x0				R/W-0x0			

Table 10-22. VPREDICT_OUTPUT_SLOT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-0	VPREDICT SLOT SELECT	R/W	0x0	TDM Slot selection These bits control the offset of audio data in the audio frame for output. The offset is defined as the number of TDM time slots. VPREDICT SLOT SELECT controls the time slot of vpredict output data path. 0000: Slot 1 0001: Slot 2 0010: Slot 3 ... 1111: Slot 16

10.1.21 RTLDG_EN Register (Address = 0x37) [Reset = 0x00]

RTLDG_EN is shown in [Figure 10-21](#) and described in [Table 10-23](#).

Return to the [Summary Table](#).

Real-time Load Diagnostic Open Load/Shorted Load Enable

Figure 10-21. RTLDG_EN Register

7	6	5	4	3	2	1	0
RESERVED				CH1 RTLDG OLSL ENABLE	RESERVED		
R/W-0x0				R/W-0x0	R/W-0x0		

Table 10-23. RTLDG_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3	CH1 RTLDG OLSL ENABLE	R/W	0x0	0: Disable Real-time load diagnostic open load/shorted load Channel 1 1: Enable Real-time load diagnostic open load/shorted load Channel 1
2-0	RESERVED	R/W	0x0	

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10.1.22 RTLDG_S2PG_EN Register (Address = 0x38) [Reset = 0x00]

RTLDG_S2PG_EN is shown in [Figure 10-22](#) and described in [Table 10-24](#).

Return to the [Summary Table](#).

Real-time Load Diagnostic Short to Power/Ground Enable

Figure 10-22. RTLDG_S2PG_EN Register

7	6	5	4	3	2	1	0
RESERVED				CH1 RTLDG S2PG ENABLE	RESERVED		
R/W-0x0				R/W-0x0	R/W-0x0		

Table 10-24. RTLDG_S2PG_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3	CH1 RTLDG S2PG ENABLE	R/W	0x0	0: Disable Real-time load short to power/ground diagnostic Channel 1 1: Enable Real-time load short to power/ground diagnostic Channel 1
2-0	RESERVED	R/W	0x0	

10.1.23 DC_BLOCK_SPEAKER_GUARD_EN Register (Address = 0x39) [Reset = 0x00]

DC_BLOCK_SPEAKER_GUARD_EN is shown in [Figure 10-23](#) and described in [Table 10-25](#).

Return to the [Summary Table](#).

DC Blocking and Speaker Guard Enable

Figure 10-23. DC_BLOCK_SPEAKER_GUARD_EN Register

7	6	5	4	3	2	1	0
RESERVED	SPEAKER GUARD ENABLE	RESERVED					DC BLOCK BYPASS
R/W-0x0	R/W-0x0	R/W-0x0					R/W-0x0

Table 10-25. DC_BLOCK_SPEAKER_GUARD_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6	SPEAKER GUARD ENABLE	R/W	0x0	0: Disable Speaker Guard 1: Enable Speaker Guard
5-1	RESERVED	R/W	0x0	
0	DC BLOCK BYPASS	R/W	0x0	0: Enable DC Blocking 1: Bypass DC Blocking

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10.1.24 FOLDBACK_EN Register (Address = 0x3A) [Reset = 0x00]FOLDBACK_EN is shown in [Figure 10-24](#) and described in [Table 10-26](#).Return to the [Summary Table](#).

PVDD and Thermal Foldback Enable

Figure 10-24. FOLDBACK_EN Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED	RESERVED	PVDD FOLDBACK ENABLE	RESERVED	RESERVED	RESERVED	THERMAL FOLDBACK ENABLE
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-26. FOLDBACK_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6	RESERVED	R/W	0x0	Reserved
5	RESERVED	R/W	0x0	Reserved
4	PVDD FOLDBACK ENABLE	R/W	0x0	PVDD Foldback (AGL tracking) 0: Disable PVDD Foldback 1: Enable PVDD Foldback
3	RESERVED	R/W	0x0	Reserved
2	RESERVED	R/W	0x0	Reserved
1	RESERVED	R/W	0x0	Reserved
0	THERMAL FOLDBACK ENABLE	R/W	0x0	Thermal Foldback 0: Disable Thermal Foldback 1: Enable Thermal Foldback

10.1.25 PAGE_AUTO_INC Register (Address = 0x3B) [Reset = 0x00]

PAGE_AUTO_INC is shown in [Figure 10-25](#) and described in [Table 10-27](#).

Return to the [Summary Table](#).

Page Auto Increment

Figure 10-25. PAGE_AUTO_INC Register

7	6	5	4	3	2	1	0
RESERVED				PAGE AUTO INCREMENT DISABLE	RESERVED	RESERVED	
R/W-0x0				R/W-0x0	R/W-0x0	R/W-0x0	

Table 10-27. PAGE_AUTO_INC Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3	PAGE AUTO INCREMENT DISABLE	R/W	0x0	Page auto increment disable Disable page auto increment mode for non-zero books. When end of page is reached it goes back to 4th address location of next page when this bit is 0. When this bit is 1 the device goes to the start location of the current page 0: Enable Page auto increment 1: Disable Page auto increment
2	RESERVED	R/W	0x0	
1-0	RESERVED	R/W	0x0	Reserved

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10.1.26 DIG_VOL_CH1 Register (Address = 0x40) [Reset = 0x30]DIG_VOL_CH1 is shown in [Figure 10-26](#) and described in [Table 10-28](#).Return to the [Summary Table](#).

Channel 1 Digital Volume

Figure 10-26. DIG_VOL_CH1 Register

7	6	5	4	3	2	1	0
CH1 DIGITAL VOLUME							
R/W-0x30							

Table 10-28. DIG_VOL_CH1 Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 DIGITAL VOLUME	R/W	0x30	The digital volume is 0 dB to -103 dB in -0.5 dB steps. 00110000: 0.0 dB 00110001: -0.5 dB ... 11111110: -103 dB 11111111: Mute

10.1.27 DIG_VOL_RAMP_CTRL Register (Address = 0x44) [Reset = 0x33]

DIG_VOL_RAMP_CTRL is shown in [Figure 10-27](#) and described in [Table 10-29](#).

Return to the [Summary Table](#).

Digital Volume Ramp Control

Figure 10-27. DIG_VOL_RAMP_CTRL Register

7	6	5	4	3	2	1	0
DIGITAL VOLUME RAMP DOWN FREQUENCY		DIGITAL VOLUME RAMP DOWN STEP		DIGITAL VOLUME RAMP UP FREQUENCY		DIGITAL VOLUME RAMP UP STEP	
R/W-0x0		R/W-0x3		R/W-0x0		R/W-0x3	

Table 10-29. DIG_VOL_RAMP_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	DIGITAL VOLUME RAMP DOWN FREQUENCY	R/W	0x0	These bits control the frequency of the digital volume updates when the volume is ramping down. 00: Update every 1 FS period 01: Update every 2 FS periods 10: Update every 4 FS periods 11: Directly set the volume to zero (Instant mute)
5-4	DIGITAL VOLUME RAMP DOWN STEP	R/W	0x3	These bits control the step of the digital volume updates when the volume is ramping down. 00: Decrement by 4 dB for each update 01: Decrement by 2 dB for each update 10: Decrement by 1 dB for each update 11: Decrement by 0.5 dB for each update
3-2	DIGITAL VOLUME RAMP UP FREQUENCY	R/W	0x0	These bits control the frequency of the digital volume updates when the volume is ramping up. 00: Update every 1 FS period 01: Update every 2 FS periods 10: Update every 4 FS periods 11: Directly restore the volume (Instant unmute)
1-0	DIGITAL VOLUME RAMP UP STEP	R/W	0x3	These bits control the step of the digital volume updates when the volume is ramping up. 00: Increment by 4 dB for each update 01: Increment by 2 dB for each update 10: Increment by 1 dB for each update 11: Increment by 0.5 dB for each update

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10.1.28 AUTO_MUTE_EN Register (Address = 0x47) [Reset = 0x00]

AUTO_MUTE_EN is shown in [Figure 10-28](#) and described in [Table 10-30](#).

Return to the [Summary Table](#).

Auto Mute Enable

Figure 10-28. AUTO_MUTE_EN Register

7	6	5	4	3	2	1	0
RESERVED							CH1 AUTO MUTE ENABLE
R/W-0x0							R/W-0x0

Table 10-30. AUTO_MUTE_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-1	RESERVED	R/W	0x0	
0	CH1 AUTO MUTE ENABLE	R/W	0x0	0: Disable Channel 1 auto mute 1: Enable Channel 1 auto mute

10.1.29 AUTO_MUTE_TIMING Register (Address = 0x48) [Reset = 0x00]

AUTO_MUTE_TIMING is shown in [Figure 10-29](#) and described in [Table 10-31](#).

Return to the [Summary Table](#).

Auto Mute Time

Figure 10-29. AUTO_MUTE_TIMING Register

7	6	5	4	3	2	1	0
RESERVED	CH1 AUTO MUTE TIMING				RESERVED		
R/W-0x0	R/W-0x0				R/W-0x0		

Table 10-31. AUTO_MUTE_TIMING Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6-4	CH1 AUTO MUTE TIMING	R/W	0x0	<p>Auto Mute Time for Channel 1</p> <p>These bits specify the length of consecutive zero samples at channel 1 before the channel can be auto muted. The times shown are for 96 kHz sampling rate and will scale with other rates. At 48kHz the timing durations will double. At 192kHz the timing durations will be halved.</p> <p>000: 11.5 ms 001: 53 ms 010: 106.5 ms 011: 266.5 ms 100: 0.535 sec 101: 1.065 sec 110: 2.665 sec 111: 5.33 sec</p>
3-0	RESERVED	R/W	0x0	

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10.1.30 ANALOG_GAIN Register (Address = 0x4A) [Reset = 0x00]ANALOG_GAIN is shown in [Figure 10-30](#) and described in [Table 10-32](#).Return to the [Summary Table](#).

Analog Gain Channel 1

Figure 10-30. ANALOG_GAIN Register

7	6	5	4	3	2	1	0
RESERVED		CH1 ANALOG GAIN		RESERVED			
R/W-0x0		R/W-0x0		R/W-0x0			

Table 10-32. ANALOG_GAIN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	RESERVED	R/W	0x0	
5-4	CH1 ANALOG GAIN	R/W	0x0	Analog Gain Control 00: 0 dB (21V) 01: -2.9dB (15V) 10: -8.9dB (7.5V) 11: -14.9dB (3.75V)
3-0	RESERVED	R/W	0x0	

10.1.31 ANALOG_GAIN_RAMP_CTRL Register (Address = 0x4E) [Reset = 0x00]

ANALOG_GAIN_RAMP_CTRL is shown in [Figure 10-31](#) and described in [Table 10-33](#).

Return to the [Summary Table](#).

Analog Gain Ramp Control

Figure 10-31. ANALOG_GAIN_RAMP_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				ANALOG GAIN RAMP STEP		ANALOG GAIN RAMP DOWN DISABLE	ANALOG GAIN RAMP UP DISABLE
R/W-0x0				R/W-0x0		R/W-0x0	R/W-0x0

Table 10-33. ANALOG_GAIN_RAMP_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3-2	ANALOG GAIN RAMP STEP	R/W	0x0	Applies to ramp up and ramp down 00: 15us/step 01: 60us/step 10: 200us/step 11: 400us/step
1	ANALOG GAIN RAMP DOWN DISABLE	R/W	0x0	0: Enable Analog Gain ramp down 1: Disable Analog Gain ramp down
0	ANALOG GAIN RAMP UP DISABLE	R/W	0x0	0: Enable Analog Gain ramp up 1: Disable Analog Gain ramp up

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10.1.32 RZ_CTRL Register (Address = 0x51) [Reset = 0x00]RZ_CTRL is shown in [Figure 10-32](#) and described in [Table 10-34](#).Return to the [Summary Table](#).

Zero Frequency Control

Figure 10-32. RZ_CTRL Register

7	6	5	4	3	2	1	0
RESERVED					ZERO FREQUENCY		
R/W-0x0					R/W-0x0		

Table 10-34. RZ_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-3	RESERVED	R/W	0x0	
2-0	ZERO FREQUENCY	R/W	0x0	Zero frequency control (zero resistor value) 000: 300kΩ (recommended for 2.048MHz FSW, speaker mode) 001: 600kΩ (recommended for all other FSW) 010: 750kΩ 011: 900kΩ (recommended for 384kHz FSW) 1xx: 1735kΩ (recommended for 2.048MHz FSW, lineout mode)

10.1.33 FSW_CTRL Register (Address = 0x52) [Reset = 0x03]

FSW_CTRL is shown in [Figure 10-33](#) and described in [Table 10-35](#).

Return to the [Summary Table](#).

Switching Frequency Control

Figure 10-33. FSW_CTRL Register

7	6	5	4	3	2	1	0
PULSE INJECTION	RESERVED				FSW SELECT		
R/W-0x0	R/W-0x0				R/W-0x3		

Table 10-35. FSW_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	PULSE INJECTION	R/W	0x0	Pulse Injection 0: Disable pulse injection 1: Enable pulse injection
6-3	RESERVED	R/W	0x0	
2-0	FSW SELECT	R/W	0x3	Class-D Switching Frequency 011: 2.048MHz 000: 384kHz 001: 480kHz 010: 1.024MHz 100: 432kHz 101: 528kHz 110: 576kHz 111: 624kHz

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10.1.34 CBC_CTRL Register (Address = 0x54) [Reset = 0x03]CBC_CTRL is shown in [Figure 10-34](#) and described in [Table 10-36](#).Return to the [Summary Table](#).

CBC Control

Figure 10-34. CBC_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				RESERVED	CBC HIGH FSW EN	CBC FAULT ENABLE	CBC WARN DISABLE
R/W-0x0				R/W-0x0	R/W-0x0	R/W-0x1	R/W-0x1

Table 10-36. CBC_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	Reserved
3	RESERVED	R/W	0x0	
2	CBC HIGH FSW EN	R/W	0x0	Enable CBC Warn and CBC Fault detection for high fsw (1024k and 2048k) when CBC WARN DISABLE and CBC FAULT DISABLE are set to 1. 0: Disabled 1: Enabled
1	CBC FAULT ENABLE	R/W	0x1	0: Disable CBC fault detection 1: Enable CBC fault detection
0	CBC WARN DISABLE	R/W	0x1	0: Disable CBC warning detection 1: Enable CBC warning detection

10.1.35 CURRENT_LIMIT_CTRL Register (Address = 0x55) [Reset = 0x00]

CURRENT_LIMIT_CTRL is shown in [Figure 10-35](#) and described in [Table 10-37](#).

Return to the [Summary Table](#).

Current Limit Control

Figure 10-35. CURRENT_LIMIT_CTRL Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED					CBC/OC LEVEL	
R/W-0x0	R/W-0x0					R/W-0x0	

Table 10-37. CURRENT_LIMIT_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6-2	RESERVED	R/W	0x0	
1-0	CBC/OC LEVEL	R/W	0x0	Select the CBC and OC Current Limit level 00: Level 4 01: Level 3 10: Level 2 11: Level 1

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10.1.36 OTW_LEVEL Register (Address = 0x56) [Reset = 0x00]OTW_LEVEL is shown in [Figure 10-36](#) and described in [Table 10-38](#).Return to the [Summary Table](#).

Overtemperature Warning Control

Figure 10-36. OTW_LEVEL Register

7	6	5	4	3	2	1	0
RESERVED					OVERTEMP WARN LEVEL		
R/W-0x0					R/W-0x0		

Table 10-38. OTW_LEVEL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-3	RESERVED	R/W	0x0	
2-0	OVERTEMP WARN LEVEL	R/W	0x0	Select OT Warning level1~7 report to register 000: NO OT Warning Level 001: OT Warning Level 1 (trigger when temperature > 95C) 010: OT Warning Level 2 (trigger when temperature > 110C) 011: OT Warning Level 3 (trigger when temperature > 125C) 100: OT Warning Level 4 (trigger when temperature > 135C) 101: OT Warning Level 5 (trigger when temperature > 145C) 110: OT Warning Level 6 (trigger when temperature > 155C) 111: OT Warning Level 7 (trigger when temperature > 165C)

10.1.37 SDOUT_DATA Register (Address = 0x5B) [Reset = 0x00]

SDOUT_DATA is shown in [Figure 10-37](#) and described in [Table 10-39](#).

Return to the [Summary Table](#).

SDOUT Data Selection

Figure 10-37. SDOUT_DATA Register

7	6	5	4	3	2	1	0
RESERVED		TEMP PVDD SDOUT EN	RESERVED	reg_isns_cal	RESERVED		
R/W-0x0		R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0		

Table 10-39. SDOUT_DATA Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	RESERVED	R/W	0x0	
5	TEMP PVDD SDOUT EN	R/W	0x0	Send temperature, Isense, and Vpredict data to SDOUT 0: No temperature data and PVDD data sent with Vpredict and Isense data 1: Send Temperature data and PVDD data with Vpredict and Isense data
4	RESERVED	R/W	0x0	
3	reg_isns_cal	R/W	0x0	Isense offset calibration enable 0: Disable Isense offset calibration 1: Enable Isense offset calibration
2-0	RESERVED	R/W	0x0	Reserved

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10.1.38 PWM_PHASE_CTRL Register (Address = 0x60) [Reset = 0x00]PWM_PHASE_CTRL is shown in [Figure 10-38](#) and described in [Table 10-40](#).Return to the [Summary Table](#).

PWM Phase Control

Figure 10-38. PWM_PHASE_CTRL Register

7	6	5	4	3	2	1	0
PWM PHASE MANUAL MODE ENABLE	RESERVED			RESERVED		PWM PHASE SYNC SELECT	PWM PHASE SYNC ENABLE
R/W-0x0	R/W-0x0			R/W-0x0		R/W-0x0	R/W-0x0

Table 10-40. PWM_PHASE_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	PWM PHASE MANUAL MODE ENABLE	R/W	0x0	0: Disable manual phase mode (default) 1: Enable manual phase mode (Configure in 0x69)
6-4	RESERVED	R/W	0x0	Reserved
3-2	RESERVED	R/W	0x0	
1	PWM PHASE SYNC SELECT	R/W	0x0	0: GPIO sync 1: SCLK sync
0	PWM PHASE SYNC ENABLE	R/W	0x0	0: Disable ramp phase sync 1: Enable ramp phase sync

10.1.39 SS_CTRL Register (Address = 0x61) [Reset = 0x00]

SS_CTRL is shown in [Figure 10-39](#) and described in [Table 10-41](#).

Return to the [Summary Table](#).

Spread Spectrum Control

Figure 10-39. SS_CTRL Register

7	6	5	4	3	2	1	0
GPO RAMP CLK DIV	RESERVED	RESERVED	RESERVED	RDM PERIOD TRIANGLE SS ENABLE	RANDOM SS ENABLE	TRIANGLE SS ENABLE	
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-41. SS_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	GPO RAMP CLK DIV	R/W	0x0	Selects GPIO output of ramp clock 0: div1 1: div2 2: div4 3: div8
5	RESERVED	R/W	0x0	
4	RESERVED	R/W	0x0	Reserved
3	RESERVED	R/W	0x0	
2	RDM PERIOD TRIANGLE SS ENABLE	R/W	0x0	0: Normal triangle spread spectrum 1: Triangle spread spectrum but the period of triangle spread spectrum is random
1	RANDOM SS ENABLE	R/W	0x0	0: Disable random spread spectrum 1: Enable random SS
0	TRIANGLE SS ENABLE	R/W	0x0	0: Disable triangle spread spectrum 1: Enable triangle SS

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10.1.40 SS_RANGE_CTRL Register (Address = 0x62) [Reset = 0x00]SS_RANGE_CTRL is shown in [Figure 10-40](#) and described in [Table 10-42](#).Return to the [Summary Table](#).

Spread Spectrum Range Control

Figure 10-40. SS_RANGE_CTRL Register

7	6	5	4	3	2	1	0
RESERVED	RANDOM SS RANGE			RDM PERIOD TRIANGLE SS CTRL.		TRIANGLE SS RANGE	
R/W-0x0	R/W-0x0			R/W-0x0		R/W-0x0	

Table 10-42. SS_RANGE_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6-4	RANDOM SS RANGE	R/W	0x0	<p>Random SS range control This setting is active when Random SS mode is enabled for 384kHz fsw</p> <p>000: SS range +0.31% 001: SS range $\pm 0.31\%$ 010: SS range $\pm 0.94\%$ 011: SS range $\pm 2.19\%$ 100: SS range $\pm 4.69\%$ 101: SS range $\pm 9.69\%$</p> <p>for 480kHz fsw</p> <p>000: SS range +0.39% 001: SS range $\pm 0.39\%$ 010: SS range $\pm 1.17\%$ 011: SS range $\pm 2.73\%$ 100: SS range $\pm 5.86\%$ 101: SS range $\pm 12.11\%$</p> <p>for 1024kHz fsw</p> <p>000: SS range +0.83% 001: SS range $\pm 0.83\%$ 010: SS range $\pm 2.5\%$ 011: SS range $\pm 5.83\%$ 100: SS range $\pm 12.5\%$ 101: SS range $\pm 25.83\%$</p> <p>for 2048kHz fsw</p> <p>000: SS range +1.67% 001: SS range $\pm 1.67\%$ 010: SS range $\pm 5\%$ 101: SS range $\pm 11.67\%$ 100: SS range $\pm 25\%$ 101: SS range $\pm 51.67\%$</p>
3-2	RDM PERIOD TRIANGLE SS CTRL.	R/W	0x0	<p>Random Period Triangle SS control This setting is active when Random Period Triangle SS mode is enabled</p> <p>00: Random triangle SS period from 1/FSS to 2/FSS 01: Random triangle SS period from 1/FSS to 4/FSS 10: Random triangle SS period from 1/FSS to 8/FSS 11: Random triangle SS period from 1/FSS to 15/FSS</p>

Table 10-42. SS_RANGE_CTRL Register Field Descriptions (continued)

Bit	Field	Type	Reset	Description
1-0	TRIANGLE SS RANGE	R/W	0x0	Triangle SS range control This setting is active when TRIANGLE SS is enabled For 384k FSW 00: 24kHz FSS with 15% range($\pm 7.5\%$) 01: 24kHz FSS with 25% range($\pm 12.5\%$) 10: 48kHz FSS with 15% range($\pm 7.5\%$) 11: 48kHz FSS with 25% range($\pm 12.5\%$) For 480k FSW 00: 30kHz Fss with 19% range($\pm 9.5\%$) 01: 30kHz Fss with 25% range($\pm 12.5\%$) 10: 60kHz Fss with 19% range($\pm 9.5\%$) 11: 60kHz Fss with 25% range($\pm 12.5\%$) For 1024k FSW 00: 85kHz Fss with 10% range($\pm 5\%$) 01: 85kHz Fss with 20% range($\pm 10\%$) 10: 128kHz Fss with 17% range($\pm 8.5\%$) 11: 128kHz Fss with 24% range($\pm 12\%$) For 2048k FSW 00: 128kHz Fss with 13% range($\pm 6.5\%$) 01: 128kHz Fss with 27% range($\pm 13.5\%$) 10: 170kHz Fss with 10% range($\pm 5\%$) 11: 170kHz Fss with 20% range($\pm 10\%$)

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10.1.41 RAMP_PHASE_CTRL_GPO Register (Address = 0x68) [Reset = 0x00]RAMP_PHASE_CTRL_GPO is shown in [Figure 10-41](#) and described in [Table 10-43](#).Return to the [Summary Table](#).

Switching Clock Phase Control for GPO

Figure 10-41. RAMP_PHASE_CTRL_GPO Register

7	6	5	4	3	2	1	0
GPO PHASE CONTROL							
R/W-0x0							

Table 10-43. RAMP_PHASE_CTRL_GPO Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	GPO PHASE CONTROL	R/W	0x0	Control phase for GPO Clock Sync. Requires bit 7 of 0x60 to be set to manual mode Determine phase offset: $360 \text{ deg} \times \text{reg_dephase_gpo} / 256$ 0x00: 0 deg 0x01: 1.4 deg ... 0x40: 90 deg ... 0xFF: 358.6 deg

10.1.42 PWM_PHASE_M_CTRL Register (Address = 0x69) [Reset = 0x00]

PWM_PHASE_M_CTRL is shown in [Figure 10-42](#) and described in [Table 10-44](#).

Return to the [Summary Table](#).

Switching Clock Phase Control 1

Figure 10-42. PWM_PHASE_M_CTRL Register

7	6	5	4	3	2	1	0
CH1 PWM PHASE MANUAL CTRL							
R/W-0x0							

Table 10-44. PWM_PHASE_M_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 PWM PHASE MANUAL CTRL	R/W	0x0	PWM PHASE MANUAL MODE EN in register 0x60 must be enabled. 1.4 degrees per step. 0x00: 0 deg 0x01: 1.4 deg ... 0x40: 90 deg ... 0xFF: 358.6 deg

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10.1.43 AUTO_MUTE_STATUS Register (Address = 0x71) [Reset = 0x00]

AUTO_MUTE_STATUS is shown in [Figure 10-43](#) and described in [Table 10-45](#).

Return to the [Summary Table](#).

Auto Mute Status

Figure 10-43. AUTO_MUTE_STATUS Register

7	6	5	4	3	2	1	0
RESERVED				CH1 AM STATUS	RESERVED		
R-0x0				R-0x0	R-0x0		

Table 10-45. AUTO_MUTE_STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R	0x0	
3	CH1 AM STATUS	R	0x0	This bit indicates the auto mute status for channel 1. 0: Not auto muted 1: Auto muted
2-0	RESERVED	R	0x0	

10.1.44 STATE_REPORT Register (Address = 0x72) [Reset = 0x00]

STATE_REPORT is shown in [Figure 10-44](#) and described in [Table 10-46](#).

Return to the [Summary Table](#).

Status Channel 1

Figure 10-44. STATE_REPORT Register

7	6	5	4	3	2	1	0
CH1 STATUS				RESERVED			
R-0x0				R-0x0			

Table 10-46. STATE_REPORT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	CH1 STATUS	R	0x0	000: DEEP SLEEP 001: LOAD DIAG 010: SLEEP 011: HI-Z 100: PLAY 101: FAULT 110: AUTOREC
3-0	RESERVED	R	0x0	

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10.1.45 PVDD_SENSE Register (Address = 0x74) [Reset = 0x00]

PVDD_SENSE is shown in [Figure 10-45](#) and described in [Table 10-47](#).

Return to the [Summary Table](#).

PVDD Voltage Sense

Figure 10-45. PVDD_SENSE Register

7	6	5	4	3	2	1	0
PVDD SENSE							
R-0x0							

Table 10-47. PVDD_SENSE Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	PVDD SENSE	R	0x0	<p>Sensed PVDD voltage = Bit value x 0.19</p> <p>0000 0000: 0V</p> <p>0000 0001: 0.19V</p> <p>...</p> <p>0100 1101: 14.63V</p> <p>...</p> <p>1111 1111: 48.45V</p>

10.1.46 TEMP_SENSOR Register (Address = 0x75) [Reset = 0x00]

TEMP_SENSOR is shown in [Figure 10-46](#) and described in [Table 10-48](#).

Return to the [Summary Table](#).

Temperature Readout

Figure 10-46. TEMP_SENSOR Register

7	6	5	4	3	2	1	0
TEMP SENSOR							
R-0x0							

Table 10-48. TEMP_SENSOR Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	TEMP SENSOR	R	0x0	Temp in Kelvin K = Bit value x 2.19 Temp in Celsius = Temp in Kelvin - 273.15

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10.1.47 FS_MON Register (Address = 0x76) [Reset = 0x00]FS_MON is shown in [Figure 10-47](#) and described in [Table 10-49](#).Return to the [Summary Table](#).

FS Monitor

Figure 10-47. FS_MON Register

7	6	5	4	3	2	1	0
RESERVED		SCLK RATIO MSB		DETECTED SAMPLE RATE			
R-0x0		R-0x0		R-0x0			

Table 10-49. FS_MON Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	RESERVED	R	0x0	
5-4	SCLK RATIO MSB	R	0x0	MSB for SCLK Monitor. Described in register SCLK MONITOR register (0x77).
3-0	DETECTED SAMPLE RATE	R	0x0	0000: FS Error 0100: 16KHz 0110: 32KHz 1001: 48KHz 1011: 96KHz 1101: 192KHz Others Reserved

10.1.48 SCLK_MON Register (Address = 0x77) [Reset = 0x00]

SCLK_MON is shown in [Figure 10-48](#) and described in [Table 10-50](#).

Return to the [Summary Table](#).

SCLK Monitor

Figure 10-48. SCLK_MON Register

7	6	5	4	3	2	1	0
SCLK RATIO LSB							
R-0x0							

Table 10-50. SCLK_MON Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	SCLK RATIO LSB	R	0x0	Used with SCLK RATIO MSB in register 0x76, for a total of 10 bits. SCLK ratio range between 32Fs to 512Fs. 00 0010 0000: 32Fs 10 0000 0000: 512Fs

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10.1.49 POWER_FAULT_STATUS Register (Address = 0x80) [Reset = 0x00]POWER_FAULT_STATUS is shown in [Figure 10-49](#) and described in [Table 10-51](#).Return to the [Summary Table](#).

Power Fault Status

Figure 10-49. POWER_FAULT_STATUS Register

7	6	5	4	3	2	1	0
GLOBAL WARNING STATUS	GLOBAL FAULT STATUS	RESERVED	DVDD UV STATUS	PVDD OV STATUS	RESERVED	PVDD UV STATUS	RESERVED
R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0

Table 10-51. POWER_FAULT_STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
7	GLOBAL WARNING STATUS	R	0x0	Unlatched 0: No warning 1: If any warning active in device, regardless of warning signal configuration
6	GLOBAL FAULT STATUS	R	0x0	Unlatched 0: No fault 1: If any fault active in device, regardless of fault signal configuration
5	RESERVED	R	0x0	Reserved
4	DVDD UV STATUS	R	0x0	Unlatched 0: DVDD supply voltage is above UV threshold 1: DVDD supply voltage is below UV threshold
3	PVDD OV STATUS	R	0x0	Unlatched 0: PVDD supply voltage is below OV threshold 1: PVDD supply voltage is above OV threshold
2	RESERVED	R	0x0	
1	PVDD UV STATUS	R	0x0	Unlatched 0: PVDD supply voltage is above UV threshold 1: PVDD supply voltage is below UV threshold
0	RESERVED	R	0x0	

10.1.50 OT_FAULT Register (Address = 0x81) [Reset = 0x00]

OT_FAULT is shown in [Figure 10-50](#) and described in [Table 10-52](#).

Return to the [Summary Table](#).

Temperature (OTSD) and Fault Status

Figure 10-50. OT_FAULT Register

7	6	5	4	3	2	1	0
GLOBAL WARNING	GLOBAL FAULT	RESERVED	OTSD STATUS	RESERVED			
R-0x0	R-0x0	R-0x0	R-0x0	R-0x0			

Table 10-52. OT_FAULT Register Field Descriptions

Bit	Field	Type	Reset	Description
7	GLOBAL WARNING	R	0x0	0: No warning 1: Any warning triggered
6	GLOBAL FAULT	R	0x0	0: No fault 1: Any fault triggered
5	RESERVED	R	0x0	
4	OTSD STATUS	R	0x0	Unlatched 0: Die temperature is below OTSD threshold 1: Die temperature is above OTSD threshold
3-0	RESERVED	R	0x0	

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10.1.51 OTW_STATUS Register (Address = 0x82) [Reset = 0x00]OTW_STATUS is shown in [Figure 10-51](#) and described in [Table 10-53](#).Return to the [Summary Table](#).

Temperature (OTW) Warning Status

Figure 10-51. OTW_STATUS Register

7	6	5	4	3	2	1	0
RESERVED			OTW STATUS	RESERVED			
R-0x0			R-0x0	R-0x0			

Table 10-53. OTW_STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
7-5	RESERVED	R	0x0	
4	OTW STATUS	R	0x0	Unlatched 0: Die temperature is below OTW threshold 1: Die temperature is above OTW threshold
3-0	RESERVED	R	0x0	

10.1.52 CLIP_WARN_STATUS Register (Address = 0x83) [Reset = 0x00]

CLIP_WARN_STATUS is shown in [Figure 10-52](#) and described in [Table 10-54](#).

Return to the [Summary Table](#).

Channel Clip Detect Status

Figure 10-52. CLIP_WARN_STATUS Register

7	6	5	4	3	2	1	0
RESERVED				CH1 CLIP STATUS	RESERVED		
R-0x0				R-0x0	R-0x0		

Table 10-54. CLIP_WARN_STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R	0x0	
3	CH1 CLIP STATUS	R	0x0	0: Channel 1 clipping is not present or below clip detect threshold 1: Channel 1 clipping is above clip detect threshold
2-0	RESERVED	R	0x0	

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10.1.53 CBC_WARNING_STATUS Register (Address = 0x85) [Reset = 0x00]CBC_WARNING_STATUS is shown in [Figure 10-53](#) and described in [Table 10-55](#).Return to the [Summary Table](#).

CBC Warning Report

Figure 10-53. CBC_WARNING_STATUS Register

7	6	5	4	3	2	1	0
CH1 CBC WARN STATUS	RESERVED						
R-0x0	R-0x0						

Table 10-55. CBC_WARNING_STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 CBC WARN STATUS	R	0x0	0: Channel 1 CBC warning is not present 1: Channel 1 CBC warning is present
6-0	RESERVED	R	0x0	

10.1.54 POWER_FAULT_LATCHED Register (Address = 0x86) [Reset = 0x00]

POWER_FAULT_LATCHED is shown in [Figure 10-54](#) and described in [Table 10-56](#).

Return to the [Summary Table](#).

Power Fault Latched

Figure 10-54. POWER_FAULT_LATCHED Register

7	6	5	4	3	2	1	0
DVDD POR STORED	RESERVED	RESERVED	DVDD UV STORED	PVDD OV STORED	RESERVED	PVDD UV STORED	RESERVED
R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0	R-0x0

Table 10-56. POWER_FAULT_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7	DVDD POR STORED	R	0x0	Latched 0: No DVDD power on reset event stored 1: DVDD power on reset event detected and stored
6	RESERVED	R	0x0	
5	RESERVED	R	0x0	Reserved
4	DVDD UV STORED	R	0x0	Latched 0: No DVDD under voltage event stored 1: DVDD under voltage event detected and stored
3	PVDD OV STORED	R	0x0	Latched 0: No PVDD over voltage event stored 1: PVDD over voltage event detected and stored
2	RESERVED	R	0x0	
1	PVDD UV STORED	R	0x0	Latched 0: No PVDD under voltage event stored 1: PVDD under voltage event detected and stored
0	RESERVED	R	0x0	

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10.1.55 OTSD_LATCHED Register (Address = 0x87) [Reset = 0x00]OTSD_LATCHED is shown in [Figure 10-55](#) and described in [Table 10-57](#).Return to the [Summary Table](#).

Temperature (OTSD) Fault Latched

Figure 10-55. OTSD_LATCHED Register

7	6	5	4	3	2	1	0
RESERVED			OTSD STORED	RESERVED			
R-0x0			R-0x0	R-0x0			

Table 10-57. OTSD_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7-5	RESERVED	R	0x0	
4	OTSD STORED	R	0x0	Latched 0: No over temperature shutdown event stored 1: Over temperature shutdown event detected and stored
3-0	RESERVED	R	0x0	

10.1.56 OTW_LATCHED Register (Address = 0x88) [Reset = 0x00]

OTW_LATCHED is shown in [Figure 10-56](#) and described in [Table 10-58](#).

Return to the [Summary Table](#).

Temperature (OTW) Warning Latched

Figure 10-56. OTW_LATCHED Register

7	6	5	4	3	2	1	0
RESERVED			OTW STORED	RESERVED			
R-0x0			R-0x0	R-0x0			

Table 10-58. OTW_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7-5	RESERVED	R	0x0	
4	OTW STORED	R	0x0	Latched 0: No over temperature warning event stored 1: Global over temperature warning event detected and stored
3-0	RESERVED	R	0x0	

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10.1.57 CLIP_WARN_LATCHED Register (Address = 0x89) [Reset = 0x00]CLIP_WARN_LATCHED is shown in [Figure 10-57](#) and described in [Table 10-59](#).Return to the [Summary Table](#).

Channel Clip Detect Warning Memory

Figure 10-57. CLIP_WARN_LATCHED Register

7	6	5	4	3	2	1	0
RESERVED				CH1 CLIP STORED	RESERVED		
R-0x0				R-0x0	R-0x0		

Table 10-59. CLIP_WARN_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R	0x0	
3	CH1 CLIP STORED	R	0x0	Latched 0: No channel 1 clipping event stored 1: Channel 1 clipping event detected and stored
2-0	RESERVED	R	0x0	

10.1.58 CLK_FAULT_LATCHED Register (Address = 0x8A) [Reset = 0x00]

CLK_FAULT_LATCHED is shown in [Figure 10-58](#) and described in [Table 10-60](#).

Return to the [Summary Table](#).

Clock Error Latched

Figure 10-58. CLK_FAULT_LATCHED Register

7	6	5	4	3	2	1	0
RESERVED						RESERVED	CLOCK FAULT STORED
R-0x0						R-0x0	R-0x0

Table 10-60. CLK_FAULT_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7-2	RESERVED	R	0x0	
1	RESERVED	R	0x0	Reserved
0	CLOCK FAULT STORED	R	0x0	0: No Clock Error event stored 1: Clock Error event stored

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10.1.59 RTLDG_OL_SL_FAULT_LATCHED Register (Address = 0x8B) [Reset = 0x00]

RTLDG_OL_SL_FAULT_LATCHED is shown in [Figure 10-59](#) and described in [Table 10-61](#).

Return to the [Summary Table](#).

Real-Time Load Diagnostic OL/SL Latched

Figure 10-59. RTLDG_OL_SL_FAULT_LATCHED Register

7	6	5	4	3	2	1	0
CH1 RTLDG SL STORED	RESERVED			CH1 RTLDG OL STORED	RESERVED		
R-0x0	R-0x0			R-0x0	R-0x0		

Table 10-61. RTLDG_OL_SL_FAULT_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 RTLDG SL STORED	R	0x0	Latched 0: No shorted load condition got detected on Channel 1 during Real-Time Load Diagnostics 1: A shorted load condition got detected on Channel 1 during Real-Time Load Diagnostics
6-4	RESERVED	R	0x0	
3	CH1 RTLDG OL STORED	R	0x0	Latched 0: No open load condition got detected on Channel 1 during Real-Time Load Diagnostics 1: An open load condition got detected on Channel 1 during Real-Time Load Diagnostics
2-0	RESERVED	R	0x0	

10.1.60 RTLDG_S2G_S2P_FAULT_LATCHED Register (Address = 0x8C) [Reset = 0x00]

RTLDG_S2G_S2P_FAULT_LATCHED is shown in [Figure 10-60](#) and described in [Table 10-62](#).

Return to the [Summary Table](#).

Real-Time Load Diagnostic S2G/S2P Latched

Figure 10-60. RTLDG_S2G_S2P_FAULT_LATCHED Register

7	6	5	4	3	2	1	0
CH1 RTLDG S2P STORED	RESERVED			CH1 RTLDG S2G STORED	RESERVED		
R-0x0	R-0x0			R-0x0	R-0x0		

Table 10-62. RTLDG_S2G_S2P_FAULT_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 RTLDG S2P STORED	R	0x0	Latched 0: No short-to-power condition got detected on Channel 1 during Real-Time Load Diagnostics 1: A short-to-power condition got detected on Channel 1 during Real-Time Load Diagnostics
6-4	RESERVED	R	0x0	
3	CH1 RTLDG S2G STORED	R	0x0	Latched 0: No short-to-ground condition got detected on Channel 1 during Real-Time Load Diagnostics 1: A short-to-ground condition got detected on Channel 1 during Real-Time Load Diagnostics
2-0	RESERVED	R	0x0	

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10.1.61 CBC_FAULT_WARN_LATCHED Register (Address = 0x8D) [Reset = 0x00]CBC_FAULT_WARN_LATCHED is shown in [Figure 10-61](#) and described in [Table 10-63](#).Return to the [Summary Table](#).

Channel Load Current Fault Latched

Figure 10-61. CBC_FAULT_WARN_LATCHED Register

7	6	5	4	3	2	1	0
CH1 CBC WARN STORED	RESERVED			CH1 CBC FAULT STORED	RESERVED		
R-0x0	R-0x0			R-0x0	R-0x0		

Table 10-63. CBC_FAULT_WARN_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 CBC WARN STORED	R	0x0	Latched Register clears to 0x0 upon reading 0: No channel 1 load current warning event stored 1: Channel 1 load current warning event detected and stored
6-4	RESERVED	R	0x0	
3	CH1 CBC FAULT STORED	R	0x0	Register clears to 0x0 upon reading For channel restart, load current fault needs to be cleared by writing to register 0x30 0: No channel 1 load current fault event stored 1: Channel 1 load current fault event detected and stored
2-0	RESERVED	R	0x0	

10.1.62 OC_DC_FAULT_LATCHED Register (Address = 0x8E) [Reset = 0x00]

OC_DC_FAULT_LATCHED is shown in [Figure 10-62](#) and described in [Table 10-64](#).

Return to the [Summary Table](#).

Channel Over Current and DC Detection Fault Latched

Figure 10-62. OC_DC_FAULT_LATCHED Register

7	6	5	4	3	2	1	0
CH1 OC FAULT STORED	RESERVED			CH1 DC FAULT STORED	RESERVED		
R-0x0	R-0x0			R-0x0	R-0x0		

Table 10-64. OC_DC_FAULT_LATCHED Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 OC FAULT STORED	R	0x0	Latched 0: No channel 1 over current fault event stored 1: Channel 1 over current fault event detected and stored
6-4	RESERVED	R	0x0	
3	CH1 DC FAULT STORED	R	0x0	Latched 0: No channel 1 DC fault event stored 1: Channel 1 DC fault event detected and stored
2-0	RESERVED	R	0x0	

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10.1.63 OTSD_RECOVERY_EN Register (Address = 0x8F) [Reset = 0x00]OTSD_RECOVERY_EN is shown in [Figure 10-63](#) and described in [Table 10-65](#).Return to the [Summary Table](#).

Overtemperature Shutdown Auto-recovery Enable

Figure 10-63. OTSD_RECOVERY_EN Register

7	6	5	4	3	2	1	0
RESERVED						OTSD AUTO REC	RESERVED
R/W-0x0						R/W-0x0	R/W-0x0

Table 10-65. OTSD_RECOVERY_EN Register Field Descriptions

Bit	Field	Type	Reset	Description
7-2	RESERVED	R/W	0x0	
1	OTSD AUTO REC	R/W	0x0	0: Disable Overtemperature Shutdown Auto-recovery 1: Enable Overtemperature Shutdown Auto-recovery
0	RESERVED	R/W	0x0	Reserved

10.1.64 REPORT_ROUTING_2 Register (Address = 0x90) [Reset = 0xA2]

REPORT_ROUTING_2 is shown in [Figure 10-64](#) and described in [Table 10-66](#).

Return to the [Summary Table](#).

Enable Faults to GPIO

Figure 10-64. REPORT_ROUTING_2 Register

7	6	5	4	3	2	1	0
CBC LATCH FAULT GPIO	RESERVED	OTSD LATCH FAULT GPIO	POWER LATCH FAULT GPIO	DC LDG FAULT GPIO	RESERVED	OTSD FAULT GPIO	POWER FAULT GPIO
R/W-0x1	R/W-0x0	R/W-0x1	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x1	R/W-0x0

Table 10-66. REPORT_ROUTING_2 Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CBC LATCH FAULT GPIO	R/W	0x1	0: Latching Overcurrent Limiting events are not routed to FAULT 1: Latching Overcurrent Limiting events are routed to FAULT
6	RESERVED	R/W	0x0	
5	OTSD LATCH FAULT GPIO	R/W	0x1	0: Latching Overtemperature Shutdown events are not routed to FAULT 1: Latching Overtemperature Shutdown events are routed to FAULT
4	POWER LATCH FAULT GPIO	R/W	0x0	0: Latching Power Fault events are not routed to FAULT 1: Latching Power Fault events are routed to FAULT
3	DC LDG FAULT GPIO	R/W	0x0	0: Non-Latched DC Load Diagnostic events are not routed to FAULT 1: Non-Latched DC Load Diagnostics events are routed to FAULT
2	RESERVED	R/W	0x0	
1	OTSD FAULT GPIO	R/W	0x1	0: Non-Latched Overtemperature Shutdown events are not routed to FAULT 1: Non-Latched Overtemperature Shutdown events are routed to FAULT
0	POWER FAULT GPIO	R/W	0x0	0: Non-Latching Power Fault events are not routed to FAULT 1: Non-Latching Power Fault events are routed to FAULT

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10.1.65 REPORT_ROUTING_3 Register (Address = 0x91) [Reset = 0x00]REPORT_ROUTING_3 is shown in [Figure 10-65](#) and described in [Table 10-67](#).Return to the [Summary Table](#).

Enable Warnings to GPIO

Figure 10-65. REPORT_ROUTING_3 Register

7	6	5	4	3	2	1	0
CBC LATCH WARN GPIO	RESERVED	OTSD LATCH WARN GPIO	POWER LATCH WARN GPIO	DC LDG WARN GPIO	RESERVED	OTSD WARN GPIO	POWER WARN GPIO
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-67. REPORT_ROUTING_3 Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CBC LATCH WARN GPIO	R/W	0x0	0: Latching Overcurrent Limiting events are not routed to <u>WARN</u> 1: Latching Overcurrent Limiting events are routed to <u>WARN</u>
6	RESERVED	R/W	0x0	
5	OTSD LATCH WARN GPIO	R/W	0x0	0: Latching Overtemperature Shutdown events are not routed to <u>WARN</u> 1: Latching Overtemperature Shutdown events are routed to <u>WARN</u>
4	POWER LATCH WARN GPIO	R/W	0x0	0: Latching Power Fault events are not routed to <u>WARN</u> 1: Latching Power Fault events are routed to <u>WARN</u>
3	DC LDG WARN GPIO	R/W	0x0	0: Non-Latched DC Load Diagnostic events are not routed to <u>WARN</u> 1: Non-Latched DC Load Diagnostics events are routed to <u>WARN</u>
2	RESERVED	R/W	0x0	
1	OTSD WARN GPIO	R/W	0x0	0: Non-Latched Overtemperature Shutdown events are not routed to <u>WARN</u> 1: Non-Latched Overtemperature Shutdown events are routed to <u>WARN</u>
0	POWER WARN GPIO	R/W	0x0	0: Non-Latching Power Fault events are not routed to <u>WARN</u> 1: Non-Latching Power Fault events are routed to <u>WARN</u>

10.1.66 REPORT_ROUTING_4 Register (Address = 0x92) [Reset = 0x06]

REPORT_ROUTING_4 is shown in [Figure 10-66](#) and described in [Table 10-68](#).

Return to the [Summary Table](#).

Enable Faults and Warnings Reported to GPIO

Figure 10-66. REPORT_ROUTING_4 Register

7	6	5	4	3	2	1	0
RESERVED	CLIP LATCH WARN GPIO	OTW LATCH WARN GPIO	OTW WARN GPIO	PROT SD FAULT GPIO	OC LATCH FAULT GPIO	DC LATCH FAULT GPIO	FAULT WARN GPIO
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x1	R/W-0x1	R/W-0x0

Table 10-68. REPORT_ROUTING_4 Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6	CLIP LATCH WARN GPIO	R/W	0x0	0: Latching Clip Detect events are not routed to <u>WARN</u> 1: Latching Clip Detect events are routed to <u>WARN</u>
5	OTW LATCH WARN GPIO	R/W	0x0	0: Latching Overtemperature Warning events are not routed to <u>WARN</u> 1: Latching Overtemperature Warning events are routed to <u>WARN</u>
4	OTW WARN GPIO	R/W	0x0	0: Non-latched Overtemperature Warning events are not routed to <u>WARN</u> 1: Non-latched Overtemperature Warning events are routed to <u>WARN</u>
3	PROT SD FAULT GPIO	R/W	0x0	0: If any channel enters the FAULT state it is not reported to <u>FAULT</u> 1: If any channel enters the FAULT state it is reported to <u>FAULT</u>
2	OC LATCH FAULT GPIO	R/W	0x1	0: Latching Overcurrent shutdown events are not routed to <u>FAULT</u> 1: Latching Overcurrent shutdown events are routed to <u>FAULT</u>
1	DC LATCH FAULT GPIO	R/W	0x1	0: Latching DC Detect events are not routed to <u>FAULT</u> 1: Latching DC Detect events are routed to <u>FAULT</u>
0	FAULT WARN GPIO	R/W	0x0	0: <u>WARN</u> pin signals are not routed to the <u>FAULT</u> pin 1: <u>WARN</u> pin signals are routed to the <u>FAULT</u> pin

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10.1.67 CLIP_DETECT_CTRL Register (Address = 0x93) [Reset = 0x00]CLIP_DETECT_CTRL is shown in [Figure 10-67](#) and described in [Table 10-69](#).Return to the [Summary Table](#).

Clip Detect Control

Figure 10-67. CLIP_DETECT_CTRL Register

7	6	5	4	3	2	1	0
RESERVED	CLIP DETECT ENABLE	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-69. CLIP_DETECT_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6	CLIP DETECT ENABLE	R/W	0x0	0: Disable Clip detect 1: Enable Clip detect
5-4	RESERVED	R/W	0x0	Reserved
3-0	RESERVED	R/W	0x0	

10.1.68 REPORT_ROUTING_5 Register (Address = 0x94) [Reset = 0x00]

REPORT_ROUTING_5 is shown in [Figure 10-68](#) and described in [Table 10-70](#).

Return to the [Summary Table](#).

Enable Faults and Warnings Reported to GPIO

Figure 10-68. REPORT_ROUTING_5 Register

7	6	5	4	3	2	1	0
CLK FAULT GPIO	CLK LATCH FAULT GPIO	CBC WARN FAULT GPIO	RTLDG LATCH FAULT GPIO	RESERVED		CLIP WARN GPIO	RTLDG LATCH WARN GPIO
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0		R/W-0x0	R/W-0x0

Table 10-70. REPORT_ROUTING_5 Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CLK FAULT GPIO	R/W	0x0	0: Non-Latched Clock error events are not routed to FAULT and WARN 1: Non-Latched Clock error events are routed to FAULT and WARN
6	CLK LATCH FAULT GPIO	R/W	0x0	0: Latched Clock error events are not routed to FAULT and WARN 1: Latched Clock error events are routed to FAULT and WARN
5	CBC WARN FAULT GPIO	R/W	0x0	0: Unlatched CBC warning events are not routed to WARN 1: Unlatched CBC warning events are routed to WARN
4	RTLDG LATCH FAULT GPIO	R/W	0x0	0: Latched Real-time load diagnostic events are not routed to FAULT 1: Latched Real-time load diagnostic events are routed to FAULT
3-2	RESERVED	R/W	0x0	
1	CLIP WARN GPIO	R/W	0x0	0: Non-latched Clip Detect events are not routed to WARN 1: Non-latched Clip Detect events are routed to WARN
0	RTLDG LATCH WARN GPIO	R/W	0x0	0: Latched Real-time load diagnostic events are not routed to WARN 1: Latched Real-time load diagnostic events are routed to WARN

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10.1.69 GPIO1_OUTPUT_SELECT Register (Address = 0x95) [Reset = 0x00]GPIO1_OUTPUT_SELECT is shown in [Figure 10-69](#) and described in [Table 10-71](#).Return to the [Summary Table](#).

Select Signals to GPIOs

Figure 10-69. GPIO1_OUTPUT_SELECT Register

7	6	5	4	3	2	1	0
RESERVED		RESERVED	GPIO1 OUTPUT				
R/W-0x0		R/W-0x0	R/W-0x0				

Table 10-71. GPIO1_OUTPUT_SELECT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	RESERVED	R/W	0x0	
5	RESERVED	R/W	0x0	Reserved
4-0	GPIO1 OUTPUT	R/W	0x0	GPIO1 pin output function 0x00: LOW 0x06: Auto Mute Channel 1 0x09: SDOUT1 0x0A: $\overline{\text{WARN}}$ 0x0B: $\overline{\text{FAULT}}$ 0x0E: Clock sync to secondary devices(e.g.DCDC) 0x0F: Clock Error All other values are RESERVED

10.1.70 GPIO2_OUTPUT_SELECT Register (Address = 0x96) [Reset = 0x0B]

GPIO2_OUTPUT_SELECT is shown in [Figure 10-70](#) and described in [Table 10-72](#).

Return to the [Summary Table](#).

Select Signals to GPIOs

Figure 10-70. GPIO2_OUTPUT_SELECT Register

7	6	5	4	3	2	1	0
RESERVED		RESERVED	GPIO2 OUTPUT				
R/W-0x0		R/W-0x0	R/W-0xB				

Table 10-72. GPIO2_OUTPUT_SELECT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	RESERVED	R/W	0x0	
5	RESERVED	R/W	0x0	Reserved
4-0	GPIO2 OUTPUT	R/W	0xB	GPIO2 pin output function 0x00: LOW 0x06: Auto Mute Channel 1 0x09: SDOUT1 0x0A: WARN 0x0B: FAULT 0x0E: Clock sync to secondary devices(e.g.DCDC) 0x0F: Clock Error All other values are RESERVED

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10.1.71 GPIO_INPUT_SLEEP_HIZ Register (Address = 0x9B) [Reset = 0x00]

GPIO_INPUT_SLEEP_HIZ is shown in [Figure 10-71](#) and described in [Table 10-73](#).

Return to the [Summary Table](#).

Select Signals from GPIOs

Figure 10-71. GPIO_INPUT_SLEEP_HIZ Register

7	6	5	4	3	2	1	0
RESERVED	GPIO INPUT FOR DEEP SLEEP			RESERVED	GPIO INPUT FOR HI Z		
R/W-0x0	R/W-0x0			R/W-0x0	R/W-0x0		

Table 10-73. GPIO_INPUT_SLEEP_HIZ Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6-4	GPIO INPUT FOR DEEP SLEEP	R/W	0x0	GPIO Source for DEEP SLEEP state Configures the GPIO pin to set the device into DEEP SLEEP state 000: N/A 001: GPIO1 010: GPIO2 others: Reserved
3	RESERVED	R/W	0x0	
2-0	GPIO INPUT FOR HI Z	R/W	0x0	GPIO Source for Hi-Z state Configures the GPIO pin to set the device channels into Hi-Z state 000: N/A 001: GPIO1 010: GPIO2 others: Reserved

10.1.72 GPIO_INPUT_PLAY_SLEEP Register (Address = 0x9C) [Reset = 0x00]

GPIO_INPUT_PLAY_SLEEP is shown in [Figure 10-72](#) and described in [Table 10-74](#).

Return to the [Summary Table](#).

Select Signals from GPIOs

Figure 10-72. GPIO_INPUT_PLAY_SLEEP Register

7	6	5	4	3	2	1	0
RESERVED	GPIO INPUT PLAY			RESERVED	GPIO INPUT SLEEP		
R/W-0x0	R/W-0x0			R/W-0x0	R/W-0x0		

Table 10-74. GPIO_INPUT_PLAY_SLEEP Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6-4	GPIO INPUT PLAY	R/W	0x0	GPIO Source for PLAY state Configures the GPIO pin to set the device channels into PLAY state 000: N/A 001: GPIO1 010: GPIO2 others: Reserved
3	RESERVED	R/W	0x0	
2-0	GPIO INPUT SLEEP	R/W	0x0	GPIO Source for SLEEP state Configures the GPIO pin to set the device into SLEEP state 000: N/A 001: GPIO1 010: GPIO2 others: Reserved

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10.1.73 GPIO_INPUT_MUTE Register (Address = 0x9D) [Reset = 0x00]GPIO_INPUT_MUTE is shown in [Figure 10-73](#) and described in [Table 10-75](#).Return to the [Summary Table](#).

Select Signals from GPIOs

Figure 10-73. GPIO_INPUT_MUTE Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED			RESERVED	GPIO INPUT MUTE		
R/W-0x0	R/W-0x0			R/W-0x0	R/W-0x0		

Table 10-75. GPIO_INPUT_MUTE Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6-4	RESERVED	R/W	0x0	Reserved
3	RESERVED	R/W	0x0	
2-0	GPIO INPUT MUTE	R/W	0x0	GPIO Source for $\overline{\text{MUTE}}$ Configures the GPIO pin to control MUTE for all channels 000: N/A 001: GPIO1 010: GPIO2 others: Reserved

10.1.74 GPIO_INPUT_SYNC Register (Address = 0x9E) [Reset = 0x00]

GPIO_INPUT_SYNC is shown in [Figure 10-74](#) and described in [Table 10-76](#).

Return to the [Summary Table](#).

Select Signals from GPIOs

Figure 10-74. GPIO_INPUT_SYNC Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED			RESERVED	GPIO INPUT SYNC		
R/W-0x0	R/W-0x0			R/W-0x0	R/W-0x0		

Table 10-76. GPIO_INPUT_SYNC Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	Reserved
6-4	RESERVED	R/W	0x0	Reserved
3	RESERVED	R/W	0x0	
2-0	GPIO INPUT SYNC	R/W	0x0	GPIO Source for Phase Sync Configures the GPIO pin become the input to sync phase with another device in target configuration 000: N/A 001: GPIO1 010: GPIO2 others: Reserved

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10.1.75 GPIO_CTRL Register (Address = 0xA0) [Reset = 0x40]GPIO_CTRL is shown in [Figure 10-75](#) and described in [Table 10-77](#).Return to the [Summary Table](#).

General GPIO Control

Figure 10-75. GPIO_CTRL Register

7	6	5	4	3	2	1	0
GPIO1 IO SELECT	GPIO2 IO SELECT	RESERVED		GPO1 MODE	GPO2 MODE	RESERVED	
R/W-0x0	R/W-0x1	R/W-0x0		R/W-0x0	R/W-0x0	R/W-0x0	

Table 10-77. GPIO_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	GPIO1 IO SELECT	R/W	0x0	0: Set GPIO1 as input 1: Set GPIO1 as output
6	GPIO2 IO SELECT	R/W	0x1	0: Set GPIO2 as input 1: Set GPIO2 as output
5-4	RESERVED	R/W	0x0	
3	GPO1 MODE	R/W	0x0	Set GPIO1 as open drain. This bit only applies to GPO functions with Output buffer mode and has no effect on functions that use Open Drain mode by default 0: Output Buffer mode 1: Open drain mode
2	GPO2 MODE	R/W	0x0	Set GPIO2 as open drain. This bit only applies to GPO functions with Output buffer mode and has no effect on functions that use Open Drain mode by default 0: Output Buffer mode 1: Open drain mode
1-0	RESERVED	R/W	0x0	

10.1.76 GPIO_INVERT Register (Address = 0xA1) [Reset = 0x00]

GPIO_INVERT is shown in [Figure 10-76](#) and described in [Table 10-78](#).

Return to the [Summary Table](#).

Invert GPIO Signals

Figure 10-76. GPIO_INVERT Register

7	6	5	4	3	2	1	0
GPO1 INV	GPO2 INV	RESERVED					GPO PU DISABLE
R/W-0x0	R/W-0x0	R/W-0x0					R/W-0x0

Table 10-78. GPIO_INVERT Register Field Descriptions

Bit	Field	Type	Reset	Description
7	GPO1 INV	R/W	0x0	0: GPIO1 Output signal is non-inverted 1: GPIO1 Output signal is inverted
6	GPO2 INV	R/W	0x0	0: GPIO2 Output signal is non-inverted 1: GPIO2 Output signal is inverted
5-1	RESERVED	R/W	0x0	
0	GPO PU DISABLE	R/W	0x0	0: Enable pull-up of GP outputs in open drain 1: Disable pull-up of GP outputs in open drain

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10.1.77 DC_LDГ_CTRL Register (Address = 0xB0) [Reset = 0x00]DC_LDГ_CTRL is shown in [Figure 10-77](#) and described in [Table 10-79](#).Return to the [Summary Table](#).

DC Load Diagnostics Control

Figure 10-77. DC_LDГ_CTRL Register

7	6	5	4	3	2	1	0
LDG ABORT	LDG BUFFER WAIT TIME	RESERVED		LDG WAIT BYPASS	LDG SLOL DISABLE	LDG BYPASS	
R/W-0x0	R/W-0x0	R/W-0x0		R/W-0x0	R/W-0x0	R/W-0x0	

Table 10-79. DC_LDГ_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	LDG ABORT	R/W	0x0	0: Normal operation 1: Abort DC load diagnostic
6-5	LDG BUFFER WAIT TIME	R/W	0x0	00: Buffer wait time 1ms 01: Buffer wait time 2ms 10: Buffer wait time 5ms 11: Buffer wait time 10ms
4-3	RESERVED	R/W	0x0	Reserved
2	LDG WAIT BYPASS	R/W	0x0	0: Enable the waiting loop at the end of shorted / open load detection 1: Bypass the waiting loop at the end of shorted / open load detection
1	LDG SLOL DISABLE	R/W	0x0	0: Shorted load and open load detection are enabled 1: Shorted load, open load and line out out detection are disabled
0	LDG BYPASS	R/W	0x0	0: Automatic DC diagnostic after a channel fault occurs in Hi-Z or PLAY state 1: DC diagnostic will not run automatically after a channel fault occurs

10.1.78 DC_LDG_LO_CTRL Register (Address = 0xB1) [Reset = 0x00]

DC_LDG_LO_CTRL is shown in [Figure 10-78](#) and described in [Table 10-80](#).

Return to the [Summary Table](#).

DC Load Diagnostic Line-out Control

Figure 10-78. DC_LDG_LO_CTRL Register

7	6	5	4	3	2	1	0
RESERVED	RESERVED	RESERVED	CH1 LO LDG ENABLE	RESERVED			
R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0	R/W-0x0			

Table 10-80. DC_LDG_LO_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7	RESERVED	R/W	0x0	
6	RESERVED	R/W	0x0	Reserved
5-4	RESERVED	R/W	0x0	Reserved
3	CH1 LO LDG ENABLE	R/W	0x0	0: Disable DC Load Diagnostics to check for line-out load on Channel 1 1: Enable DC Load Diagnostics to check for line-out load on Channel 1
2-0	RESERVED	R/W	0x0	

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10.1.79 DC_LDГ_TIME_CTRL Register (Address = 0xB2) [Reset = 0x00]DC_LDГ_TIME_CTRL is shown in [Figure 10-79](#) and described in [Table 10-81](#).Return to the [Summary Table](#).

DC Load Diagnostic Timing Control

Figure 10-79. DC_LDГ_TIME_CTRL Register

7	6	5	4	3	2	1	0
LDG RAMP SL OL		LDG SETTLING SL OL		LDG RAMP S2PG		LDG SETTLING S2PG	
R/W-0x0		R/W-0x0		R/W-0x0		R/W-0x0	

Table 10-81. DC_LDГ_TIME_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-6	LDG RAMP SL OL	R/W	0x0	Ramp time, shorted load and open load diagnostics 00: 10 ms 01: 5 ms 10: 20 ms 11: 15 ms
5-4	LDG SETTLING SL OL	R/W	0x0	Settling time, shorted load and open load diagnostics 00: 15 ms 01: 30 ms 10: 10 ms 11: 20 ms
3-2	LDG RAMP S2PG	R/W	0x0	Ramp time, short to power and short to ground diagnostics 00: 5 ms 01: 2.5 ms 10: 10 ms 11: 15 ms
1-0	LDG SETTLING S2PG	R/W	0x0	Settling time, short to power and short to ground diagnostics 00: 10ms 01: 5 ms 10: 20 ms 11: 30 ms

10.1.80 DC_LDГ_SL_CTRL Register (Address = 0xB3) [Reset = 0x11]

DC_LDГ_SL_CTRL is shown in [Figure 10-80](#) and described in [Table 10-82](#).

Return to the [Summary Table](#).

DC Load Diagnostic Shorted-load Threshold

Figure 10-80. DC_LDГ_SL_CTRL Register

7	6	5	4	3	2	1	0
CH1 DC LDG SL				RESERVED			
R/W-0x1				R/W-0x1			

Table 10-82. DC_LDГ_SL_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	CH1 DC LDG SL	R/W	0x1	DC load diagnostic shorted-load threshold Channel 1 0000 : 0.5Ω 0001 : 1Ω 0010 : 1.5Ω ... 1001 : 5Ω
3-0	RESERVED	R/W	0x1	

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10.1.81 AC_LDГ_CTRL Register (Address = 0xB5) [Reset = 0x10]AC_LDГ_CTRL is shown in [Figure 10-81](#) and described in [Table 10-83](#).Return to the [Summary Table](#).

AC Load Diagnostic Control

Figure 10-81. AC_LDГ_CTRL Register

7	6	5	4	3	2	1	0
RESERVED			AC DIAG GAIN	CH1 AC DIAG START	RESERVED		
R/W-0x0			R/W-0x1	R/W-0x0	R/W-0x0		

Table 10-83. AC_LDГ_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-5	RESERVED	R/W	0x0	
4	AC DIAG GAIN	R/W	0x1	Used together with 0xB7 to select tweeter detection threshold. 0: Gain 1 1: Gain 8
3	CH1 AC DIAG START	R/W	0x0	0: Normal operation 1: Start AC diagnostic on channel 1 once channel is in Hi-Z mode
2-0	RESERVED	R/W	0x0	

10.1.82 TWEETER_DETECT_CTRL Register (Address = 0xB6) [Reset = 0x08]

TWEETER_DETECT_CTRL is shown in [Figure 10-82](#) and described in [Table 10-84](#).

Return to the [Summary Table](#).

Tweeter Detection Control

Figure 10-82. TWEETER_DETECT_CTRL Register

7	6	5	4	3	2	1	0
RESERVED				RESERVED	RESERVED	TWEETWER DETECT CALC TYPE	TWEETER DETECT DISABLE
R/W-0x0				R/W-0x1	R/W-0x0	R/W-0x0	R/W-0x0

Table 10-84. TWEETER_DETECT_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R/W	0x0	
3	RESERVED	R/W	0x1	Reserved
2	RESERVED	R/W	0x0	Reserved
1	TWEETWER DETECT CALC TYPE	R/W	0x0	0: AC pass/fail judgement type 2 Calculate magnitude of impedance as $\text{Re}(Z)+0.5*\text{Im}(Z)$ 1: AC pass/fail judgement type 1 Calculate magnitude of impedance as $\text{Re}(Z)$
0	TWEETER DETECT DISABLE	R/W	0x0	Calculate magnitude of impedance Check whether calculated result is lower than tweeter detection threshold value If yes, set tweeter detection bit. 0: Enable Tweeter detection judgement 1: Disable Tweeter detection calculation

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10.1.83 TWEETER_DETECT_THRESH Register (Address = 0xB7) [Reset = 0x00]TWEETER_DETECT_THRESH is shown in [Figure 10-83](#) and described in [Table 10-85](#).Return to the [Summary Table](#).

Tweeter Detection Threshold

Figure 10-83. TWEETER_DETECT_THRESH Register

7	6	5	4	3	2	1	0
TWEETER DETECT THRESHOLD							
R/W-0x0							

Table 10-85. TWEETER_DETECT_THRESH Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	TWEETER DETECT THRESHOLD	R/W	0x0	Set the reference value for AC load diagnostics pass/fail judgement. If AC DIAG GAIN in AC_LDГ_CTRL(0xB5) = 0: Bit value x 0.8 Ω /code If AC DIAG GAIN in AC_LDГ_CTRL(0xB5) = 1: Bit value x 0.1 Ω /code

10.1.84 AC_LDQ_FREQ_CTRL Register (Address = 0xB8) [Reset = 0xC8]

AC_LDQ_FREQ_CTRL is shown in [Figure 10-84](#) and described in [Table 10-86](#).

Return to the [Summary Table](#).

AC Load Diagnostic Frequency Control

Figure 10-84. AC_LDQ_FREQ_CTRL Register

7	6	5	4	3	2	1	0
AC LDG STIMULUS FREQUENCY							
R/W-0xC8							

Table 10-86. AC_LDQ_FREQ_CTRL Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	AC LDG STIMULUS FREQUENCY	R/W	0xC8	Frequency = 93.75Hz * bit value 0000 0000: Reserved 0000 0001: 93.75Hz 0000 0010: 187.5Hz 0000 0011: 281.25Hz 1100 1000: 18.75kHz 1111 1111: 23.91kHz

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10.1.85 DC_LDG_REPORT Register (Address = 0xC0) [Reset = 0x00]DC_LDG_REPORT is shown in [Figure 10-85](#) and described in [Table 10-87](#).Return to the [Summary Table](#).

DC Load Diagnostic Report

Figure 10-85. DC_LDG_REPORT Register

7	6	5	4	3	2	1	0
CH1 S2G	CH1 S2P	CH1 OL	CH1 SL	RESERVED			
R-0x0	R-0x0	R-0x0	R-0x0	R-0x0			

Table 10-87. DC_LDG_REPORT Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 S2G	R	0x0	0: No short-to-GND detected on Channel 1 1: Short-to-GND detected on Channel 1
6	CH1 S2P	R	0x0	0: No short-to-power detected on Channel 1 1: Short-to-power detected on Channel 1
5	CH1 OL	R	0x0	0: No open load detected on Channel 1 1: Open load detected on Channel 1
4	CH1 SL	R	0x0	0: No shorted load detected on Channel 1 1: Shorted load detected on Channel 1
3-0	RESERVED	R	0x0	

10.1.86 DC_LDG_RESULT Register (Address = 0xC2) [Reset = 0x00]

DC_LDG_RESULT is shown in [Figure 10-86](#) and described in [Table 10-88](#).

Return to the [Summary Table](#).

DC Load Diagnostic Result Report

Figure 10-86. DC_LDG_RESULT Register

7	6	5	4	3	2	1	0
CH1 LO LDG RESULT	RESERVED			CH1 DC LDG RESULT	RESERVED		
R-0x0	R-0x0			R-0x0	R-0x0		

Table 10-88. DC_LDG_RESULT Register Field Descriptions

Bit	Field	Type	Reset	Description
7	CH1 LO LDG RESULT	R	0x0	0: Lineout load not detected on Channel 1 1: Lineout load detected on Channel 1
6-4	RESERVED	R	0x0	
3	CH1 DC LDG RESULT	R	0x0	0: DC Load Diagnostic did not complete without faults on channel 1 1: DC Load Diagnostic completed without faults on channel 1
2-0	RESERVED	R	0x0	

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10.1.87 AC_LDГ_REPORT_CH1_R Register (Address = 0xC3) [Reset = 0x00]AC_LDГ_REPORT_CH1_R is shown in [Figure 10-87](#) and described in [Table 10-89](#).Return to the [Summary Table](#).

AC Load Diagnostic Report Real Channel 1

Figure 10-87. AC_LDГ_REPORT_CH1_R Register

7	6	5	4	3	2	1	0
CH1 AC IMP R							
R-0x0							

Table 10-89. AC_LDГ_REPORT_CH1_R Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 AC IMP R	R	0x0	Register value corresponds to real part of complex impedance seen at Channel 1 output MSB determines the leading sign (0: positive, 1: negative) 0.8Ω/code if AC DIAG GAIN in 0xB5 = 0 0.1Ω/code if AC DIAG GAIN in 0xB5 = 1

10.1.88 AC_LDГ_REPORT_CH1_I Register (Address = 0xC4) [Reset = 0x00]

AC_LDГ_REPORT_CH1_I is shown in [Figure 10-88](#) and described in [Table 10-90](#).

Return to the [Summary Table](#).

AC Load Diagnostic Report Imaginary Channel 1

Figure 10-88. AC_LDГ_REPORT_CH1_I Register

7	6	5	4	3	2	1	0
CH1 AC IMP I							
R-0x0							

Table 10-90. AC_LDГ_REPORT_CH1_I Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 AC IMP I	R	0x0	Register value corresponds to imaginary part of complex impedance seen at Channel 1 output MSB determines the leading sign (0: positive, 1: negative) 0.8Ω/code if AC DIAG GAIN in 0xB5 = 0 0.1Ω/code if AC DIAG GAIN in 0xB5 = 1

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10.1.89 DC_LDГ_DCR_MSB Register (Address = 0xC5) [Reset = 0x00]

DC_LDГ_DCR_MSB is shown in [Figure 10-89](#) and described in [Table 10-91](#).

Return to the [Summary Table](#).

DC Diagnostic DC Resistance Measurement MSB

Figure 10-89. DC_LDГ_DCR_MSB Register

7	6	5	4	3	2	1	0
RESERVED						CH1 DC RESISTANCE MSB	
R-0x0						R-0x0	

Table 10-91. DC_LDГ_DCR_MSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-2	RESERVED	R	0x0	
1-0	CH1 DC RESISTANCE MSB	R	0x0	MSB for DC Diagnostics resistance measurement, refer to DC_LDГ_DCR_LSB (0xC6)

10.1.90 DC_LDG_DCR_LSB Register (Address = 0xC6) [Reset = 0x00]

DC_LDG_DCR_LSB is shown in [Figure 10-90](#) and described in [Table 10-92](#).

Return to the [Summary Table](#).

DC Diagnostic DC Resistance Measurement LSB

Figure 10-90. DC_LDG_DCR_LSB Register

7	6	5	4	3	2	1	0
CH1 DC RESISTANCE LSB							
R-0x0							

Table 10-92. DC_LDG_DCR_LSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 DC RESISTANCE LSB	R	0x0	Channel 1 DC Load diagnostics resistance measurement. Combine with MSB in 0xC5. 0.1Ω/code.

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10.1.91 TWEETER_REPORT Register (Address = 0xCB) [Reset = 0x00]TWEETER_REPORT is shown in [Figure 10-91](#) and described in [Table 10-93](#).Return to the [Summary Table](#).

Tweeter Detection Report

Figure 10-91. TWEETER_REPORT Register

7	6	5	4	3	2	1	0
RESERVED				CH1 TW DET	RESERVED		
R-0x0				R-0x0	R-0x0		

Table 10-93. TWEETER_REPORT Register Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RESERVED	R	0x0	
3	CH1 TW DET	R	0x0	0: No tweeter detected on Channel 1 1: Tweeter detected on Channel 1
2-0	RESERVED	R	0x0	

10.1.92 CH1_RTLDG_IMP_MSB Register (Address = 0xD1) [Reset = 0x00]

CH1_RTLDG_IMP_MSB is shown in [Figure 10-92](#) and described in [Table 10-94](#).

Return to the [Summary Table](#).

Real-time Load Diagnostic Channel 1 Impedance MSB

Figure 10-92. CH1_RTLDG_IMP_MSB Register

7	6	5	4	3	2	1	0
CH1 RTLDG IMPEDANCE MSB							
R-0x0							

Table 10-94. CH1_RTLDG_IMP_MSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 RTLDG IMPEDANCE MSB	R	0x0	Combine with LSB in register 0xD2 for RTLDG impedance

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10.1.93 CH1_RTLDG_IMP_LSB Register (Address = 0xD2) [Reset = 0x00]CH1_RTLDG_IMP_LSB is shown in [Figure 10-93](#) and described in [Table 10-95](#).Return to the [Summary Table](#).

Real-time Load Diagnostic Channel 1 Impedance LSB

Figure 10-93. CH1_RTLDG_IMP_LSB Register

7	6	5	4	3	2	1	0
CH1 RTLDG IMPEDANCE LSB							
R-0x0							

Table 10-95. CH1_RTLDG_IMP_LSB Register Field Descriptions

Bit	Field	Type	Reset	Description
7-0	CH1 RTLDG IMPEDANCE LSB	R	0x0	Combined with MSB in 0xD1 for RTLDG impedance Impedance reading is combined MSB and LSB in decimal, divided by 285

11 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

11.1 Application Information

The TAS6511-Q1 is a mono-channel digital input Class-D audio-amplifier design with integrated real time Current Feedback and DSP for use in automotive head units, VESS, eCall, and external amplifier modules. The TAS6511-Q1 incorporates the necessary functionality to perform in demanding automotive OEM applications.

11.1.1 AM Radio Avoidance

AM-radio frequency interference is avoided by setting the switching frequency of the device above the AM band. When setting the switching frequency below the AM band, change the switching frequency to avoid the second and third harmonic of the switching interfering with the AM band.

11.1.2 Reconstruction Filter Design

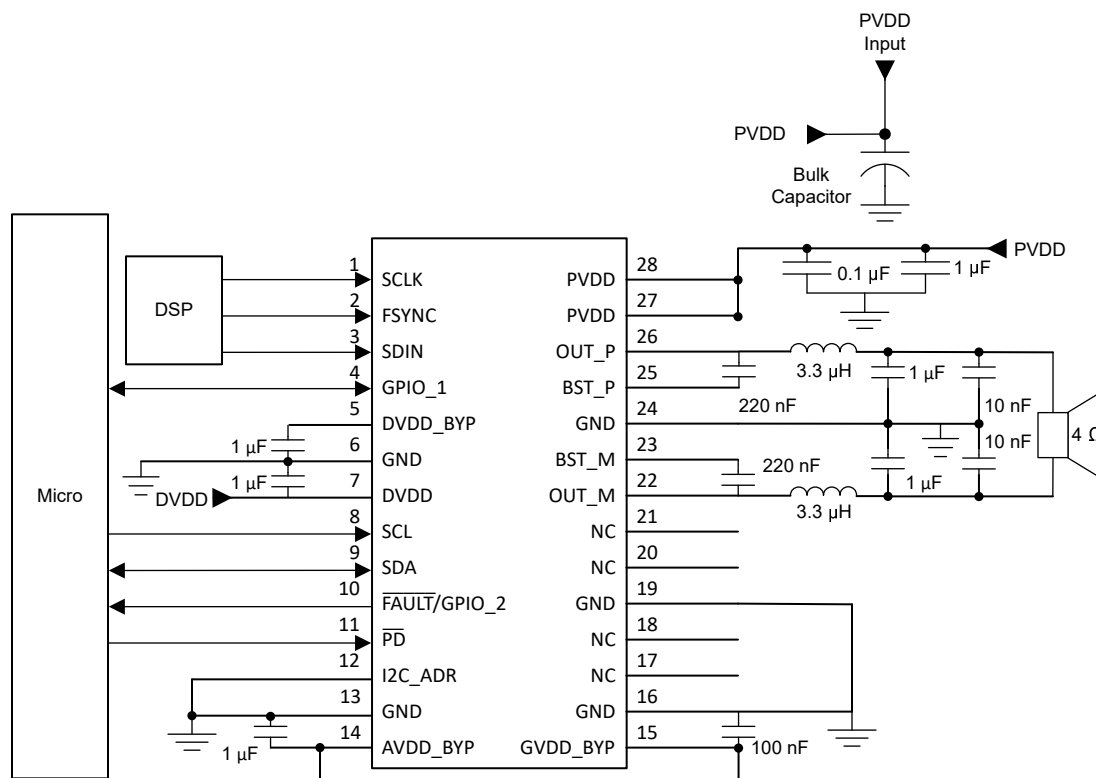
The amplifier outputs are driven by high-current LDMOS transistors in an H-bridge configuration. These transistors are either fully off or fully on. The result is a square-wave output signal with a duty cycle that is proportional to the amplitude of the audio signal. An LC demodulation filter is used to recover the audio signal. The filter attenuates the high-frequency components of the output signals that are out of the audio band. The design of the demodulation filter significantly affects the audio performance of the power amplifier. Therefore, to meet the system THD+N requirements, the selection of the inductors used in the output filter should be carefully considered.

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11.2 Typical Application**11.2.1 BTL Application**

Figure 11-1 shows the schematic for a typical single channel design.

**Figure 11-1. Typical Application Schematic****11.2.1.1 Design Requirements**

The TAS6511-Q1 requires two power supplies compliant with the recommended operation range. The device is designed to work with either a vehicle battery or regulated power supply such as from a backup battery.

11.2.1.1.1 Communication

All communications are through I²C protocol. A system controller set as the I²C primary can communicate with the device through the SDA and SCL pins. The device cannot generate an I²C clock or initiate a transaction. The device requires a primary host. The maximum clock speed accepted by the device is 400kHz. If multiple TAS6511-Q1 devices are on the same I²C bus, the I²C address must be different for each device. Up to eight TAS6511-Q1 devices can be on the same I²C bus.

11.2.1.2 Detailed Design Procedure

All communications are through I²C protocol. A system controller set as the I²C primary can communicate with the device through the SDA and SCL pins. The device cannot generate an I²C clock or initiate a transaction. The device requires a primary host. The maximum clock speed accepted by the device is 400kHz. If multiple TAS6511-Q1 devices are on the same I²C bus, the I²C address must be different for each device. Up to eight TAS6511-Q1 devices can be on the same I²C bus.

11.2.1.2.1 Hardware Design

11.2.1.2.1.1 Digital Audio Input

The TAS6511-Q1 audio amplifier supports four different digital input formats which are: I²S, Left Justified, and TDM/DSP mode. Depending on the format, the device can support 16, 20, 24, and 32 bit data. The supported frequencies are 16 kHz, 32 kHz, 48 kHz, 96 kHz, and 192 kHz. See the [Serial Audio Port](#) section for more details.

11.2.1.2.1.2 Power Supply Decoupling

The power supply decoupling has multiple functions. The large electrolytic capacitor is used to reduce the PVDD voltage ripple due to the audio frequencies. The 1 μ F MLCC on each group of PVDD pins is to reduce the PVDD voltage ripple at the PWM switching frequency and the 100 nF is for EMI reduction.

The large electrolytic capacitor value is dependent on the regulation capabilities of the boost converter used. If a battery is used with long wires, a larger value may be needed to reduce the voltage ripple in the audio band to meet the output power requirements.

11.2.1.2.1.3 Bootstrap

The bootstrap capacitors provide the gate-drive voltage of the upper N-channel FET. These capacitors must be sized appropriately for the system specification. A special condition can occur where the bootstrap sags if the capacitor is not sized accordingly. The special condition is just below clipping where the PWM is slightly less than 100% duty cycle with sustained low-frequency signals. Changing the bootstrap capacitor value to a larger value for driving subwoofers that require frequencies below 30Hz can be necessary.

11.2.1.2.1.4 Reconstruction LC Filters

The values of the inductor and the capacitor on the LC filter is determined by the PWM frequency and the required audio bandwidth of the amplifier. The PWM can vary from 384 kHz to 2.048 MHz. There are two groups of PWM frequencies to determine the LC Filter. The lower frequencies from 384 kHz to 624 kHz, and the higher frequencies, 1.024 MHz and 2.048 MHz. The lower frequency cutoff should be less than 40 kHz, where the higher frequency cutoff can be as high as 100 kHz.

The application note [LC Filter Design](#) and the [Class-D LC Filter Designer](#) will provide the tools necessary to design the LC filter.

11.3 Power Supply Recommendations

The TAS6511-Q1 requires two power supplies. The PVDD supply is the high-current supply in the recommended supply range. The DVDD supply is the 1.8Vdc or 3.3Vdc logic supply and must be maintained in the tolerance as shown in the [Recommended Operating Conditions](#).

11.4 Layout

11.4.1 Layout Guidelines

The TAS6511-Q1 EVM layout optimizes for thermal dissipation and EMC performance. The TAS6511-Q1 device has a thermal pad down, and good thermal conduction and dissipation require adequate copper area. Layout also affects EMC performance. See [Section 11.2](#) for a typical application schematic and [Section 11.4.3](#) for an example layout.

11.4.1.1 EMI Considerations

Automotive-level EMI performance depends on both careful integrated circuit design and good system-level design. Controlling sources of electromagnetic interference (EMI) was a major consideration in all aspects of the design. The design has minimal parasitic inductances because of the short leads on the package which reduces the EMI that results from current passing from the die to the system PCB. The design also incorporates circuitry that optimizes output transitions that cause EMI.

11.4.1.1.1 General Guidelines

- The ground connections for the capacitors in the LC filter have a direct path back to the device and also the ground return. This direct path allows for improved common mode EMI rejection. This is on the same layer of the pcb as the TAS6511-Q1.
- Traces that carry large currents incorporate multiple vias to reduce the series impedance of these traces.

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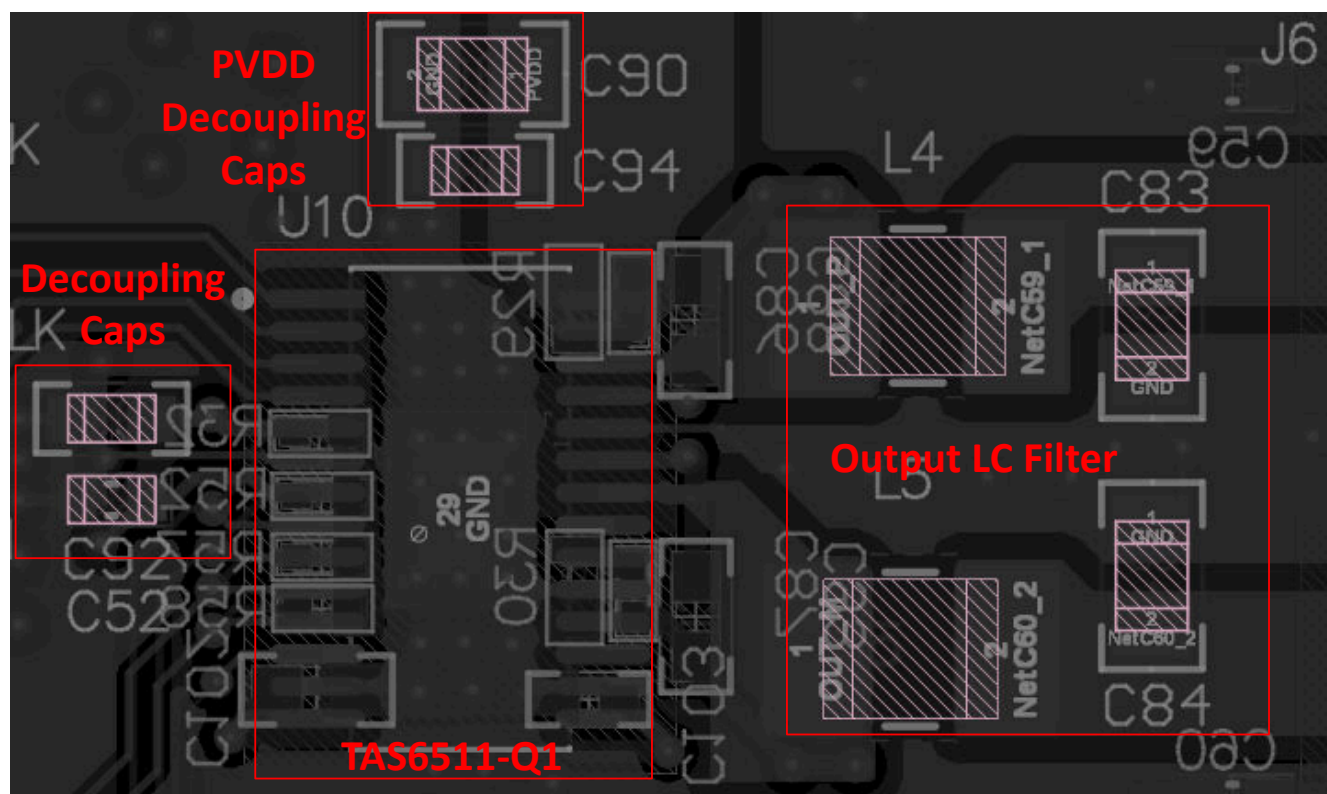
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- The decoupling capacitors on PVDD, is very close to the device with the ground return close to the ground pins.
- A ground plane, on the same side as the device pins helps reduce EMI by providing a very-low loop impedance for the high-frequency switching current. This plane has many vias between the ground planes on other layers.

11.4.2 Thermal Considerations

The thermally enhanced package has an exposed pad down thermal pad. The output power of any amplifier is determined by the thermal performance of the amplifier as well as limitations placed on it by the system, such as the ambient operating temperature. The PCB absorbs heat from the TAS6511-Q1 and transfers it to the air. With proper thermal management this process can reach equilibrium and heat can be continually transferred from the device. The thermal resistance is comprised of the following components:

- $R_{\theta JC}$ of the TAS6511-Q1
- Thermal resistance of the thermal interface material
- Thermal resistance between PCB

11.4.3 Layout Example

12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop designs are listed below.

12.1 Device Support

12.2 Documentation Support

12.2.1 Related Documentation

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.5 Trademarks

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12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (December 2024) to Revision B (April 2025)	Page
• Updated 14.4V, 4Q, 10% THD+N output power to 30W.....	1
• Deleted Supply-voltage ramp rate - PVDD Load Dump in Absolute Maximum Ratings.....	5
• Deleted outdated note #3 under Thermal Information.....	6
• Added additional Output power specifications.....	7
• Changed links to reflect section names instead of section numbers throughout the document.....	21
• Updated Vpredict description.....	31
• Added Mechanical, Packaging, and Orderable Information section.....	170

Changes from Revision * (December 2023) to Revision A (December 2024)	Page
• Updated device status to production data.....	1

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14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

14.1 Package Option Addendum

Packaging Information

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish ⁽⁶⁾	MSL Peak Temp ⁽³⁾	Op Temp (°C)	Device Marking ^{(4) (5)}
TAS6511QPWRQ1	ACTIVE	HTSSOP	PWP	28	2000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 125C	TAS6511

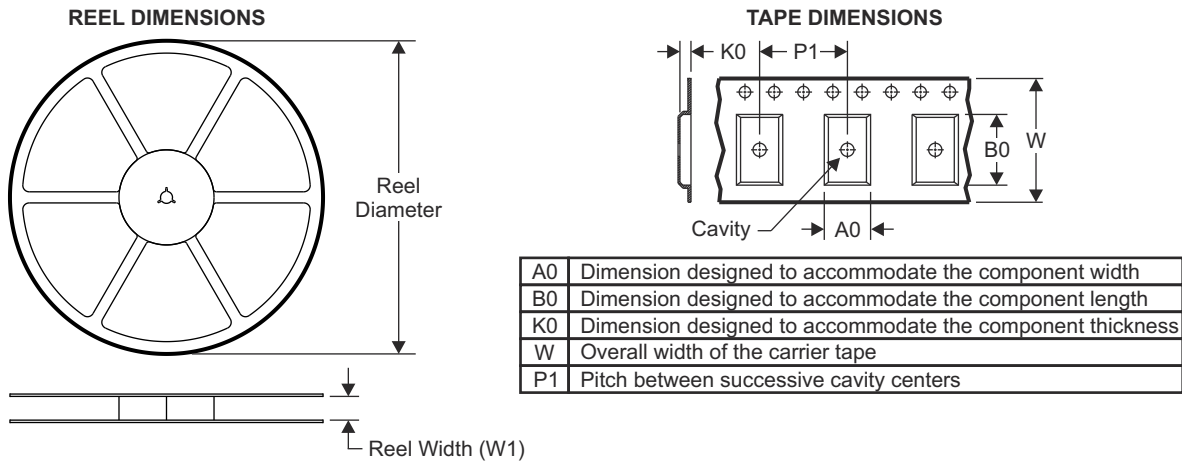
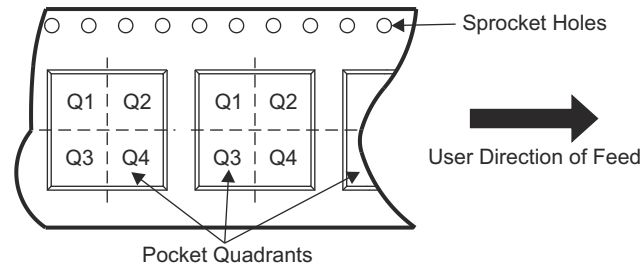
- (1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PRE_PROD Unannounced device, not in production, not available for mass market, nor on the web, samples not available.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
- (2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material).
- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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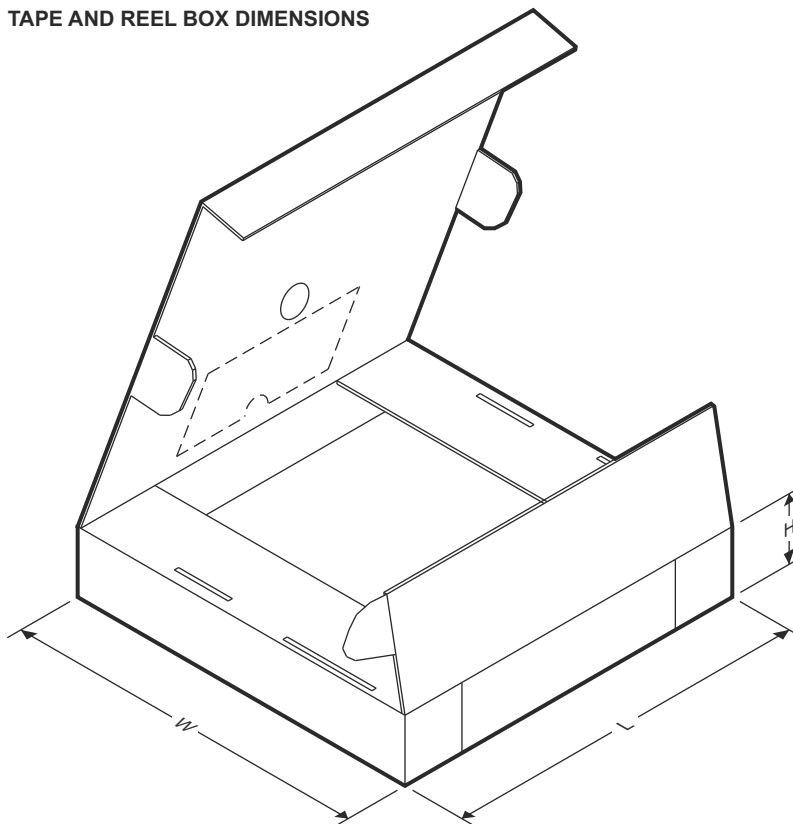
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

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14.2 Tape and Reel Information**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

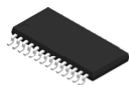
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TAS6511QPWRQ1	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TAS6511QPWPRQ1	HTSSOP	PWP	28	2000	356.0	356.0	35.0

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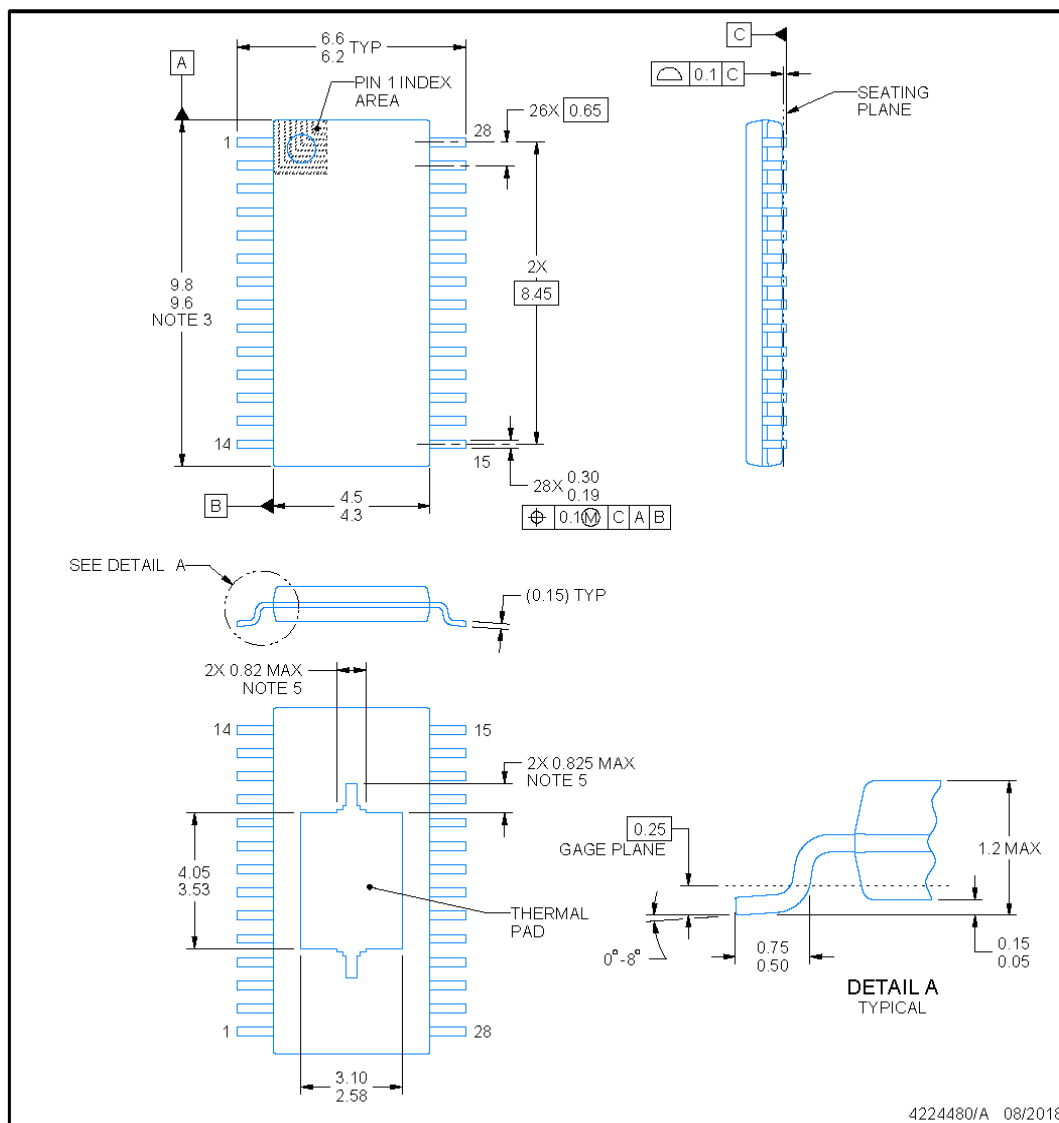
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PWP0028M

PACKAGE OUTLINE

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

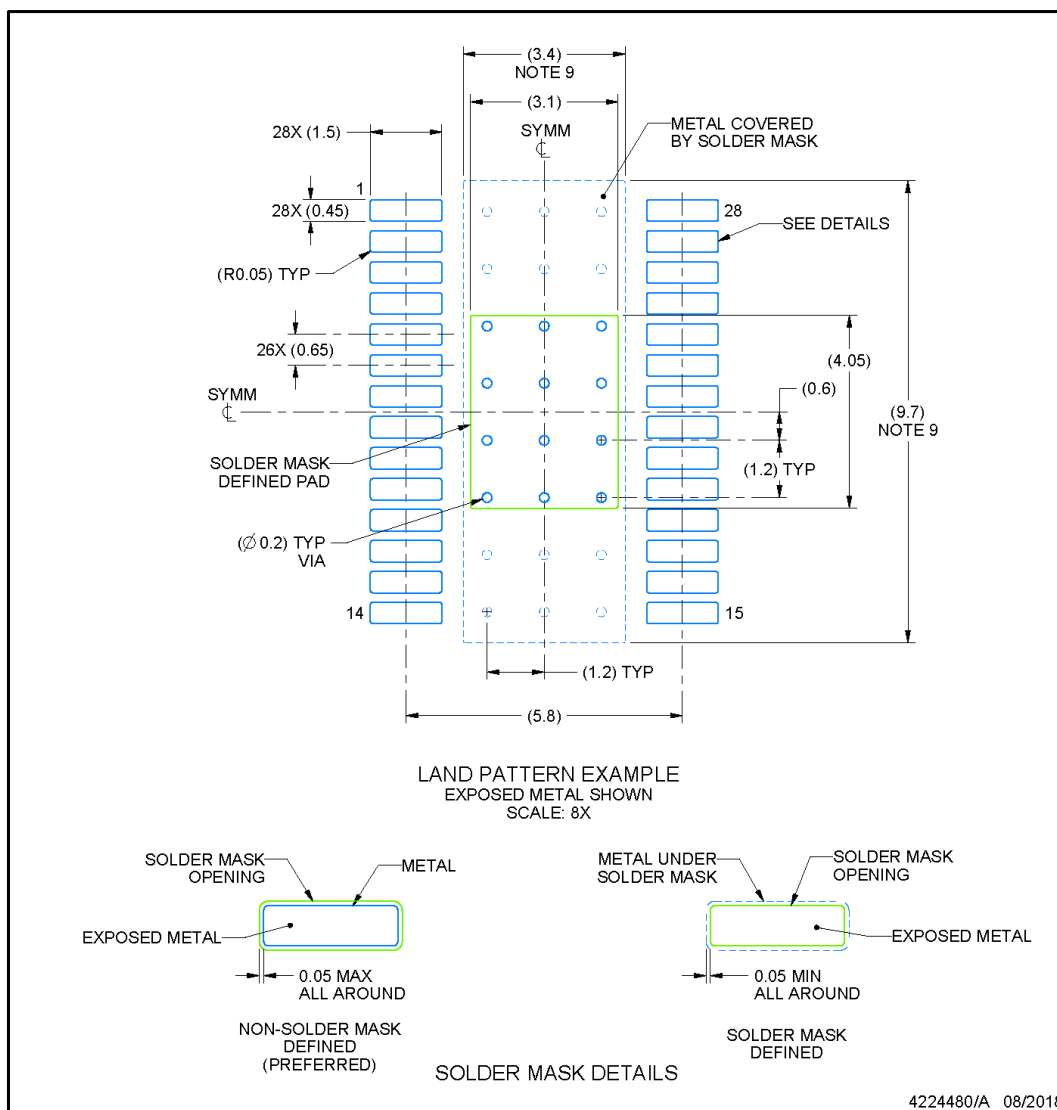
**NOTES:**

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may differ or may not be present.

EXAMPLE BOARD LAYOUT**PWP0028M****PowerPAD™ TSSOP - 1.2 mm max height**

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

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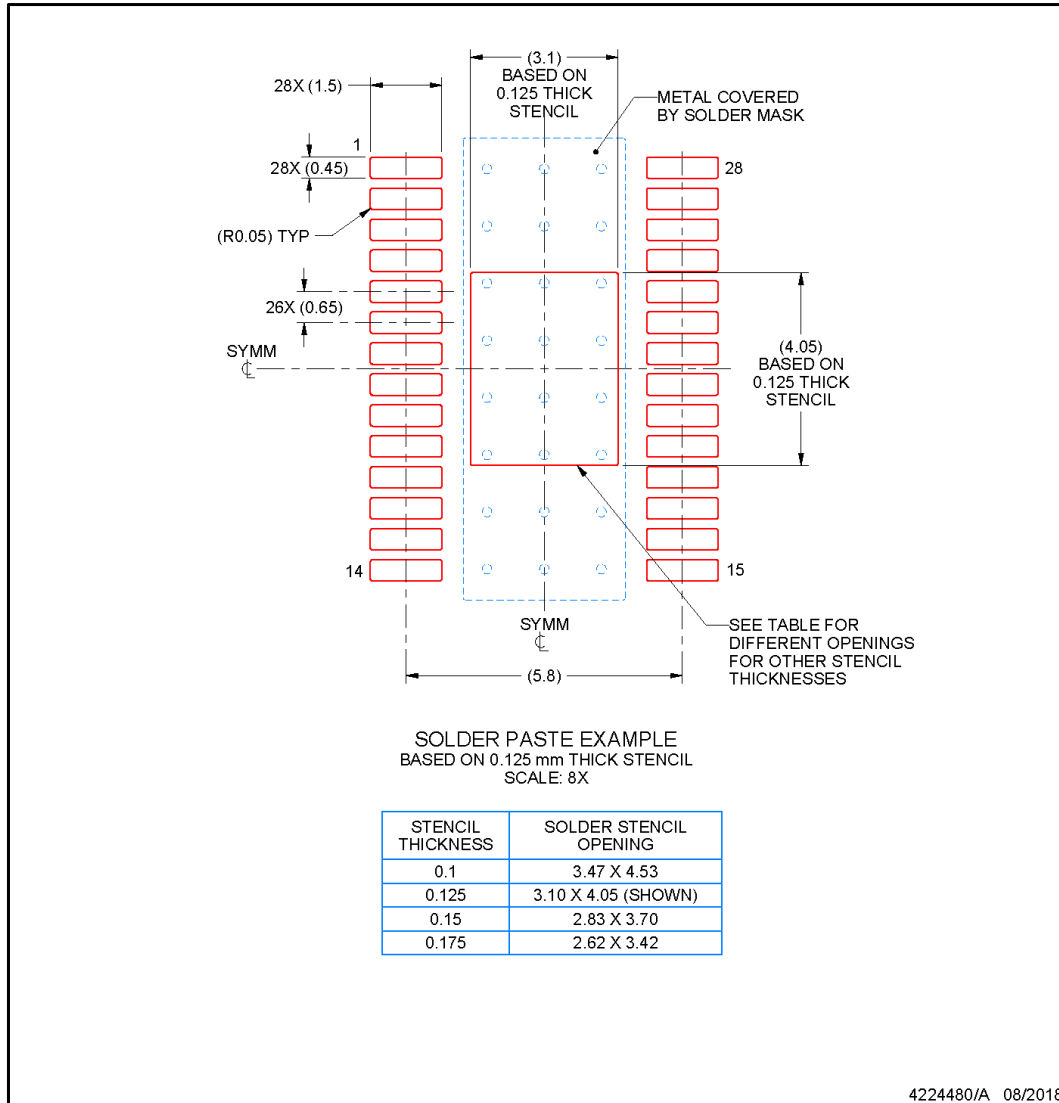
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EXAMPLE STENCIL DESIGN

PWP0028M

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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